Chapter 4

Spin Valves

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2018年10月26日

Review of Last Class

1. Magnetoresistance and ordinary MR

2. Anisotropic MR **3. Tunneling AMR**

4. Colossal MR **5. Giant MR**

6. Tunneling MR **7. Spin Hall MR**

8. Nonlocal MR **9. Hanle MR**

Outline

1. Spin valves and spin injection

2. Spin valves based on Metal and Superconductor

3. Spin valves based on Semiconductor and Quantum materials

This Class

1. Spin valves and spin injection

Outline

1. Vertical Spin valves

2. From Vertical to Lateral Spin valves

3. Spin injection

Outline

1. Vertical Spin valves

Spin valve

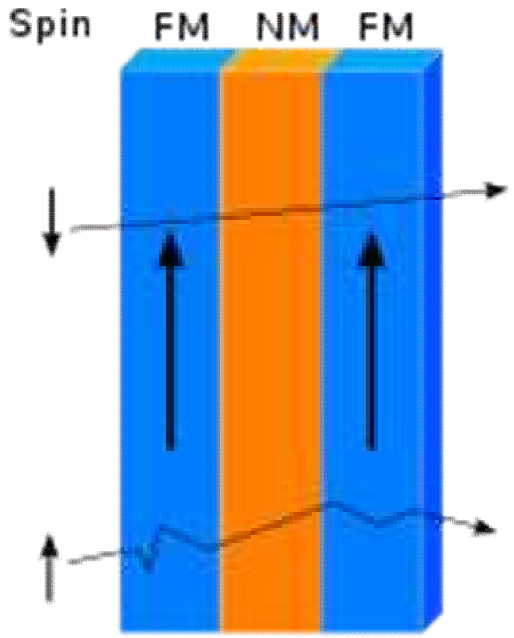
Valve

Spin valve

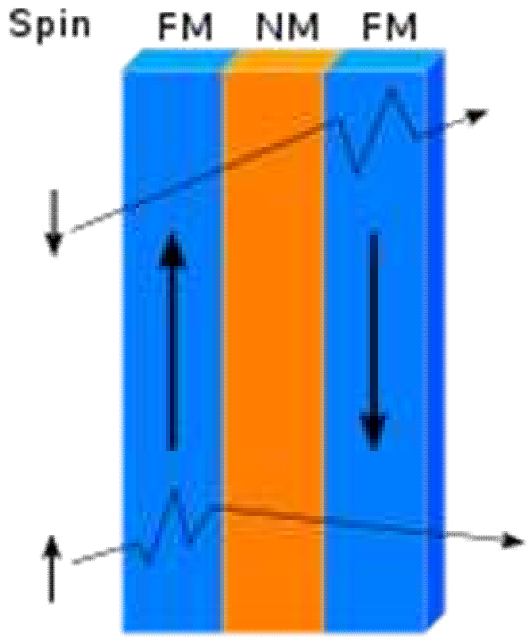
Valves

Cold Water Hot Water

Spin valve

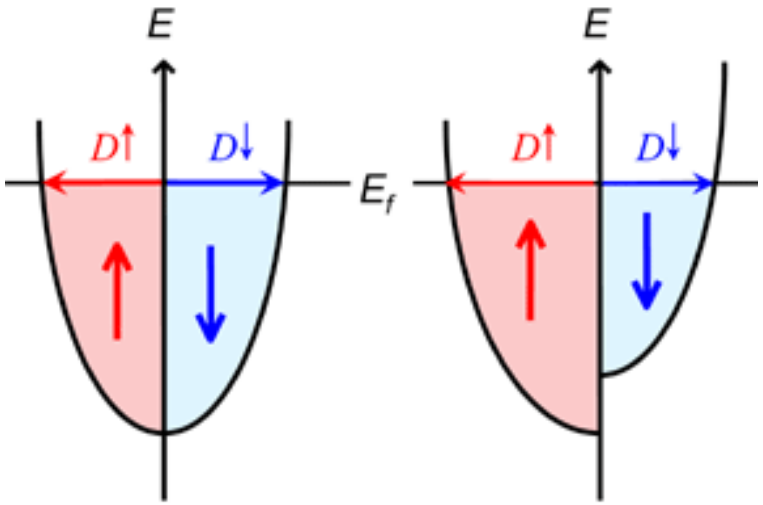


Low Resistance State



High Resistance State

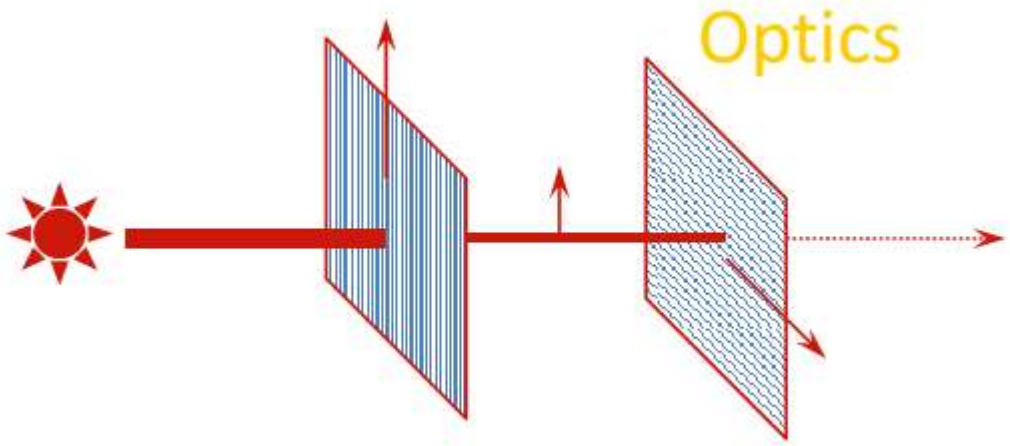
Spin valve



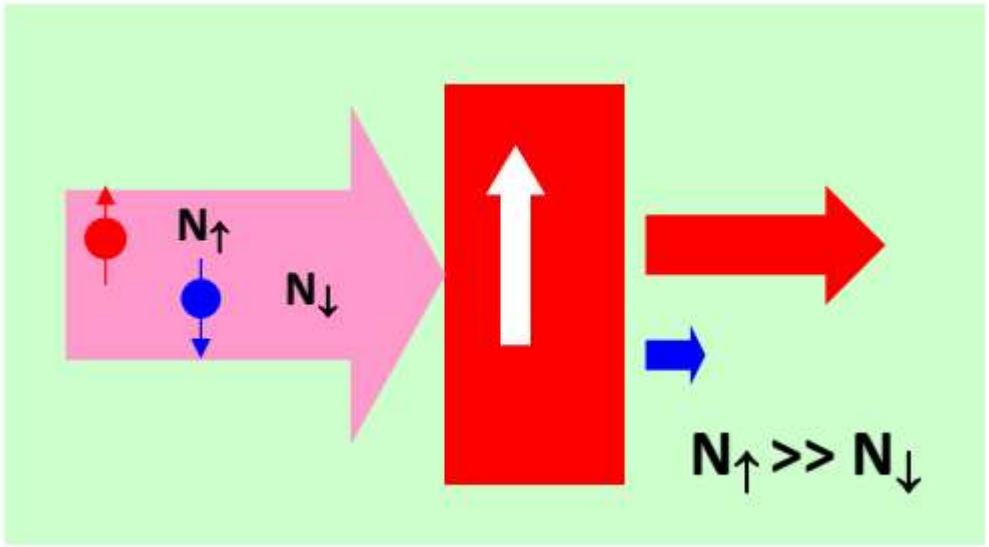
Nonmagnetic Ferromangetic

$$P = \frac{D_\uparrow - D_\downarrow}{D_\uparrow + D_\downarrow}$$

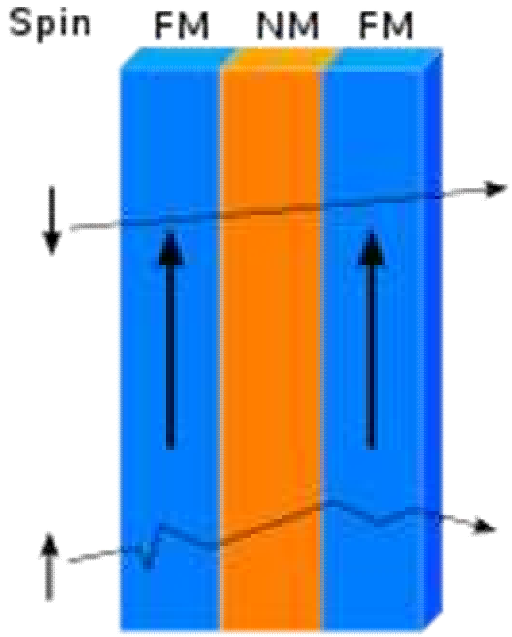
Julie Model

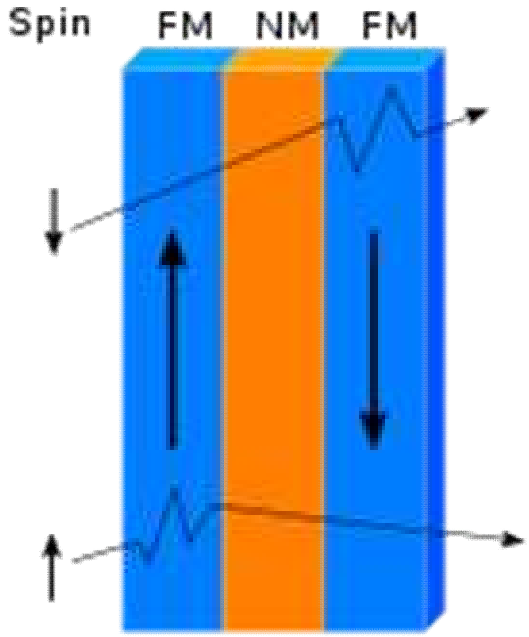


FM



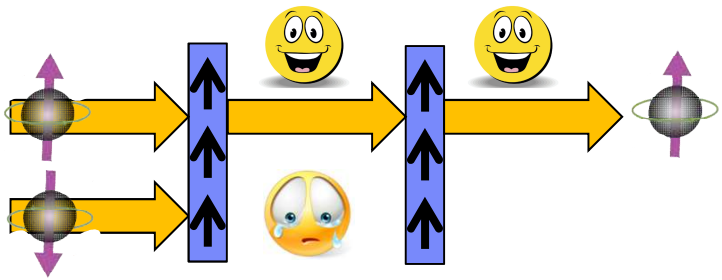
Julie Model

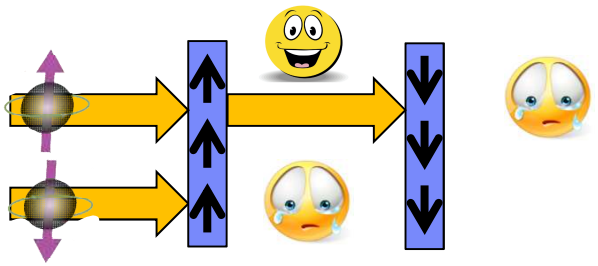




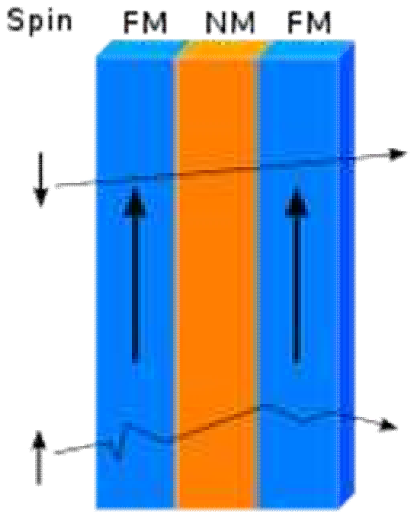
Parallel

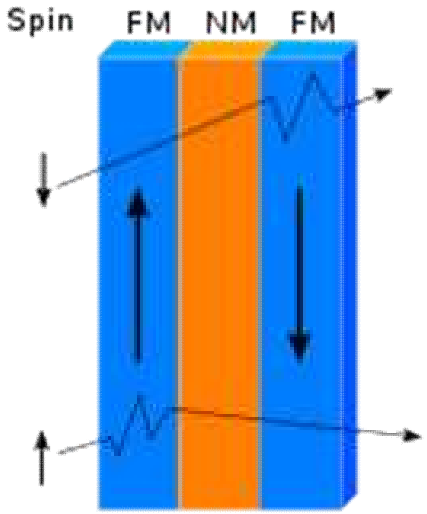
Anti-Parallel

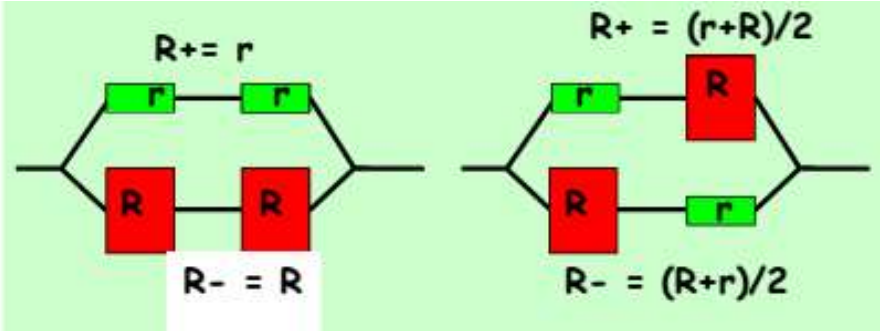




Julie Model







$$R_P = \frac{Rr}{R+r} \approx r < R_{AP} = \frac{R+r}{4}$$

When Julie model fails

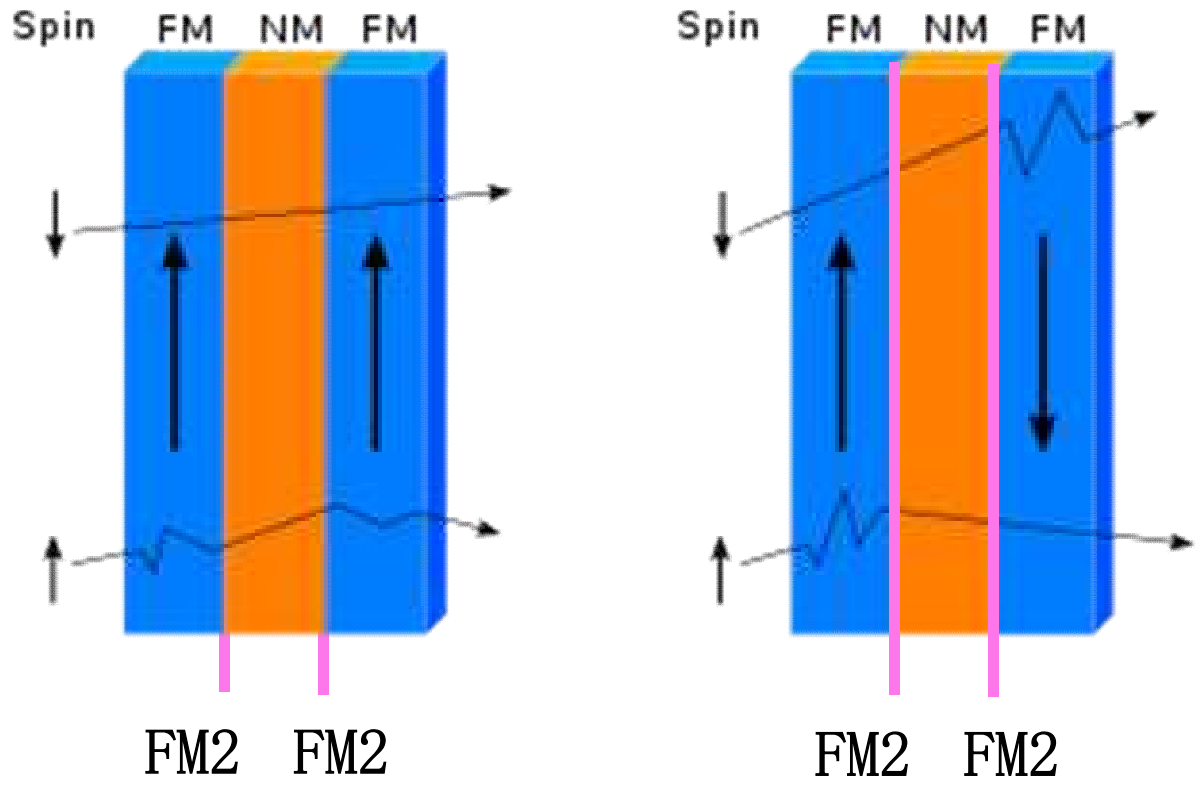
Two examples:

1) Insertion of thin FM layer

2) MgO tunnel barrier

When Julie model fails

1) Insertion of thin FM layer



Question: What happens?

When Julie model fails

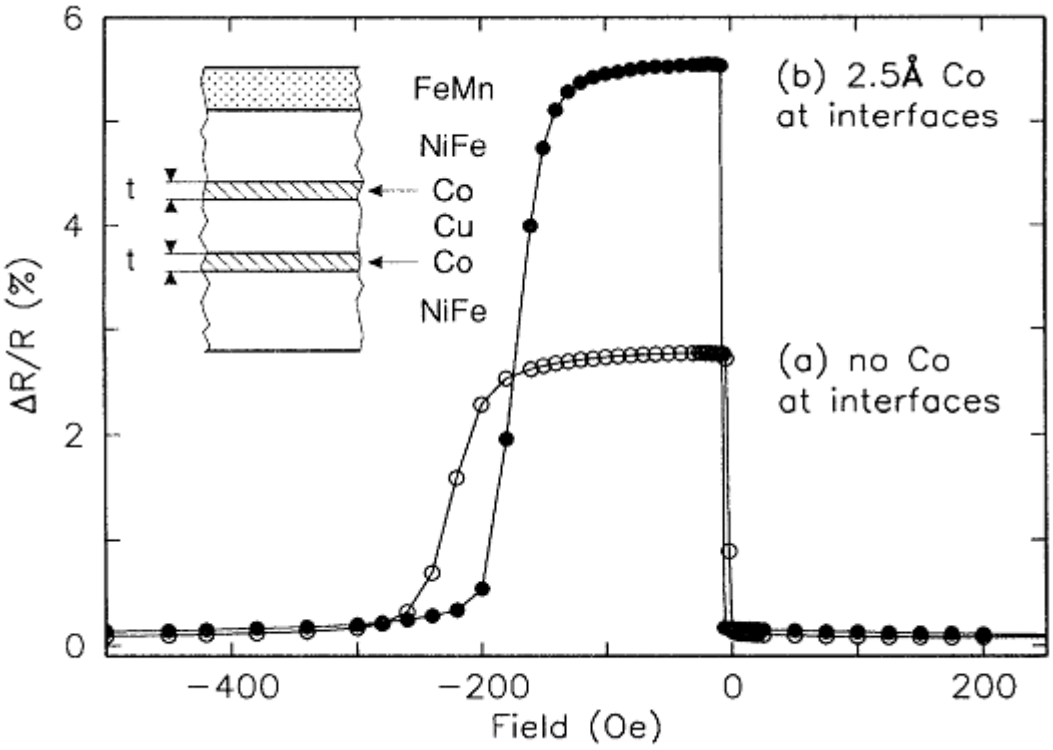
1) Insertion of thin FM layer

Julie model: two spin current model, then the interface should not matter. The MR depends on the spin polarization of the FMs.

However, this is not the experimental observation.

When Julie model fails

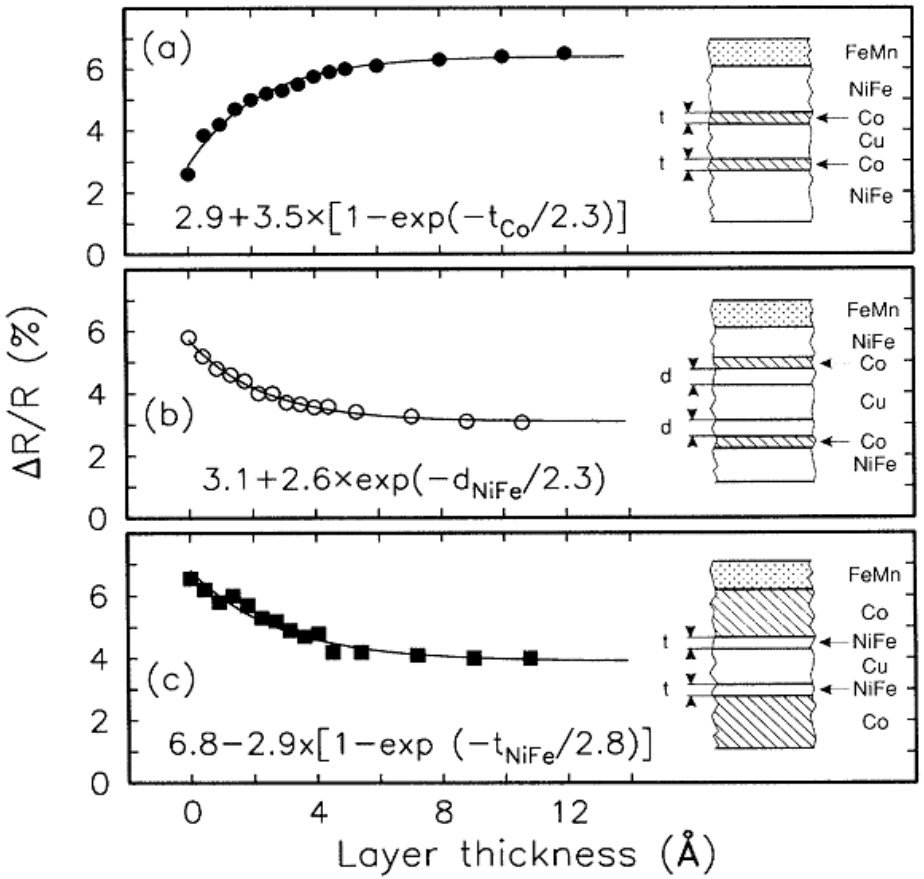
1) Insertion of thin FM layer



Parkin, PRL (1993)

When Julie model fails

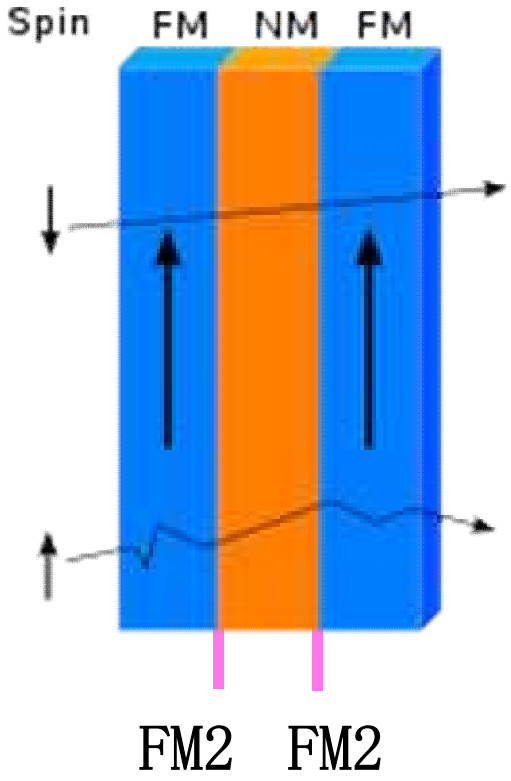
1) Insertion of thin FM layer



Parkin, PRL (1993)

When Julie model fails

1) Insertion of thin FM layer



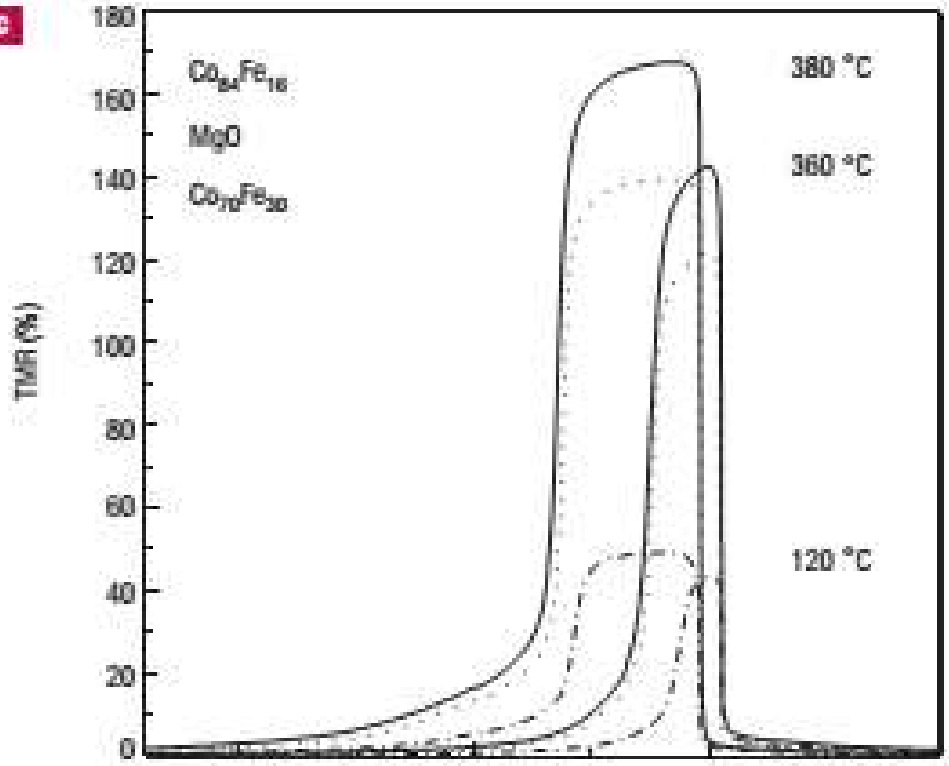
Origin of Enhanced MR of Magnetic Multilayers:

Spin-Dependent Scattering from Magnetic Interface States

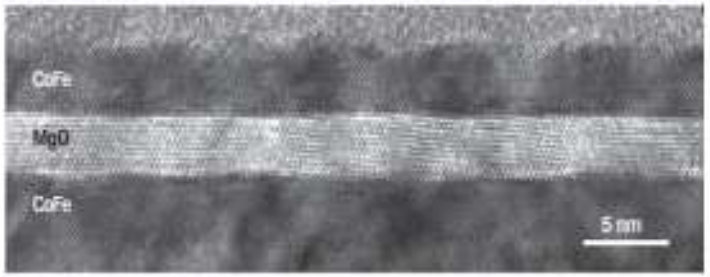
Parkin, PRL (1993)

When Julie model fails

2) MgO tunnel barrier



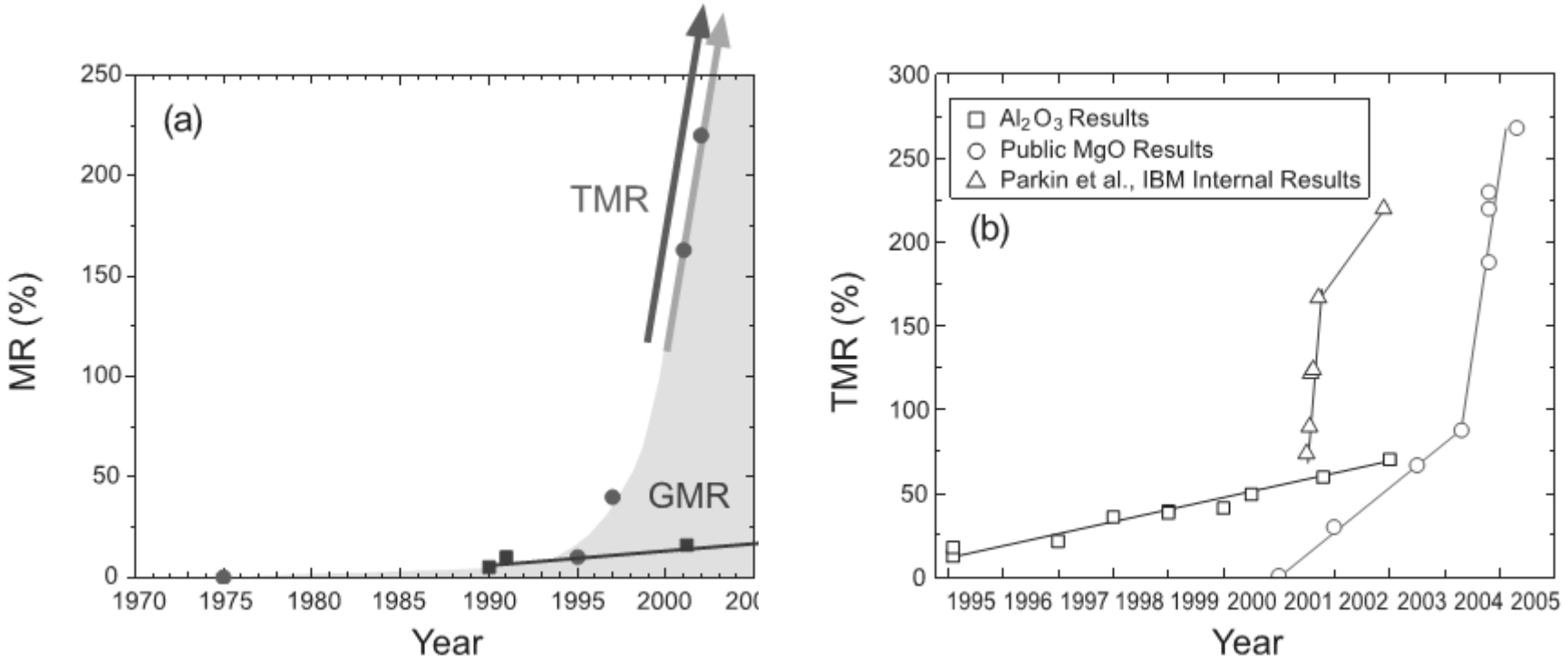
Epitaxial MgO



Parkin, et al, Nature Mater (2004)
Yuasa, et al, Nature Mater (2004)

When Julie model fails

2) MgO tunnel barrier

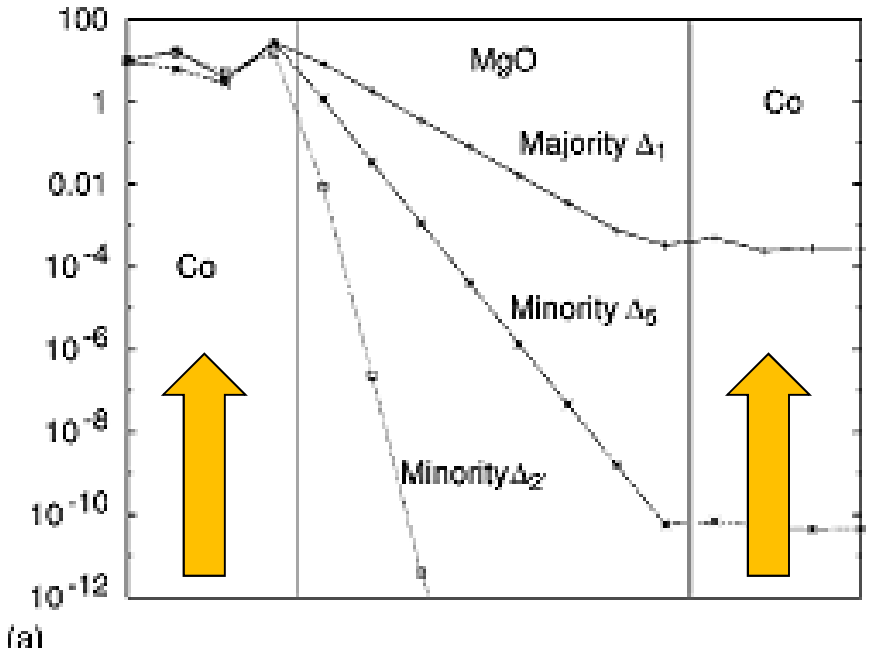


Maekawa, Book Concepts in Spin electronics (2006)

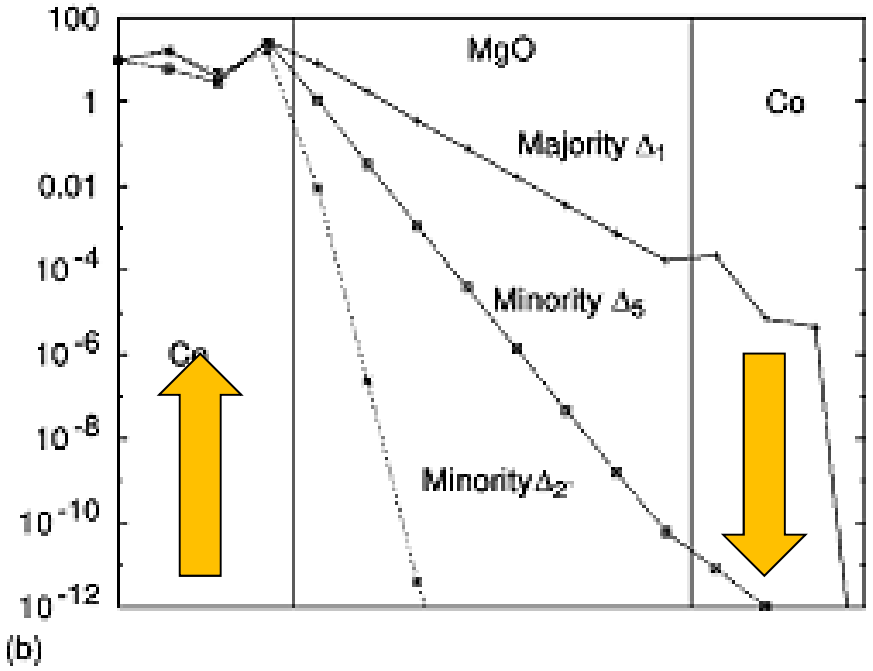
When Julie model fails

MgO barrier for tunneling: MR >100%

Parallel



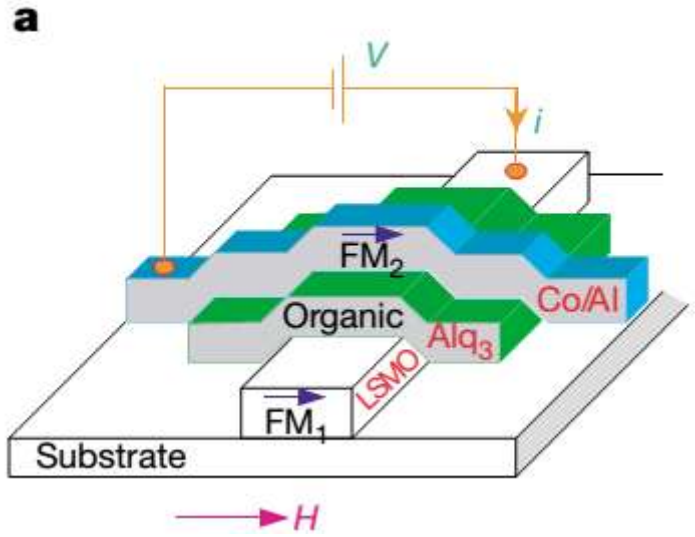
Anti-Parallel

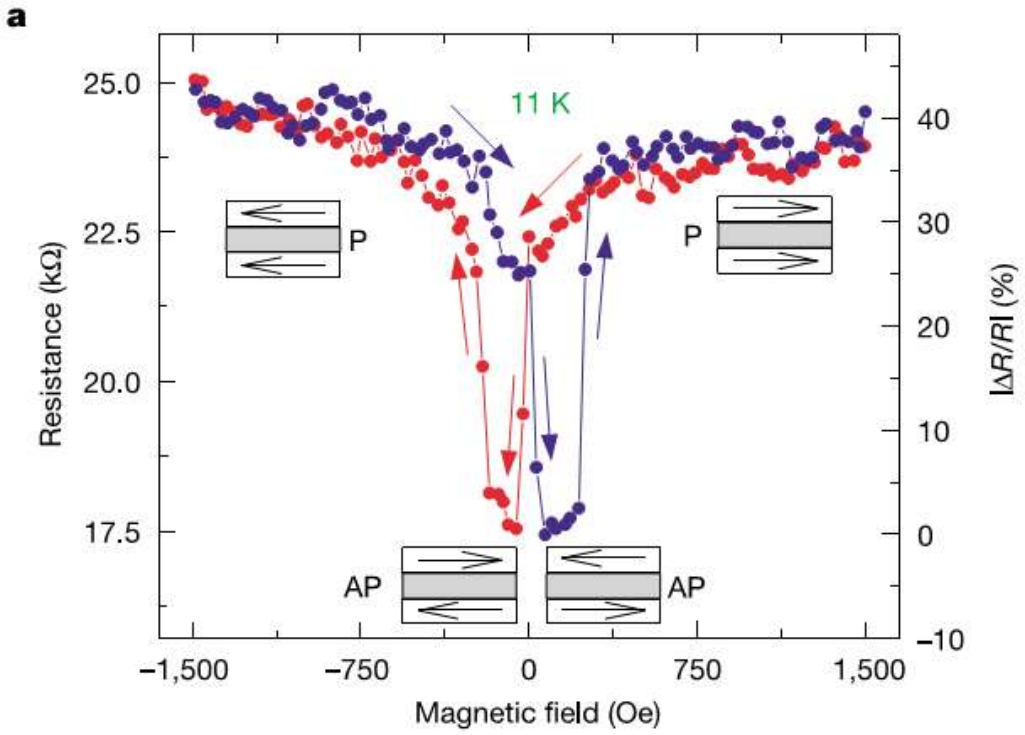


Δ_1, symmetry, slow decaying
Tunneling of Co majority spin (SP)

Zhang & Butler, et al, PRB (2004)

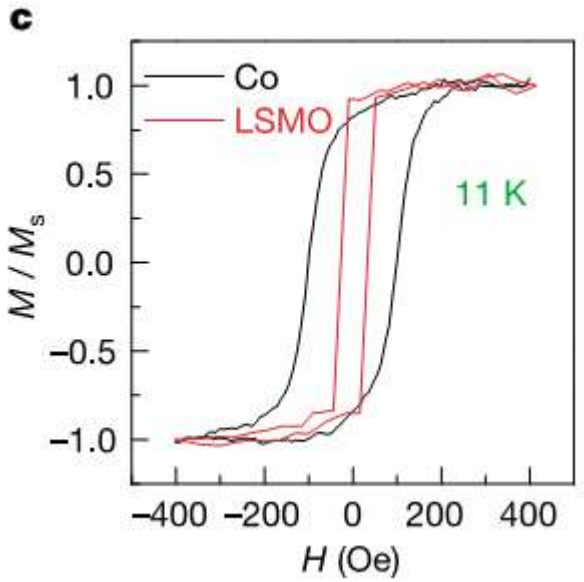
Organic Materials

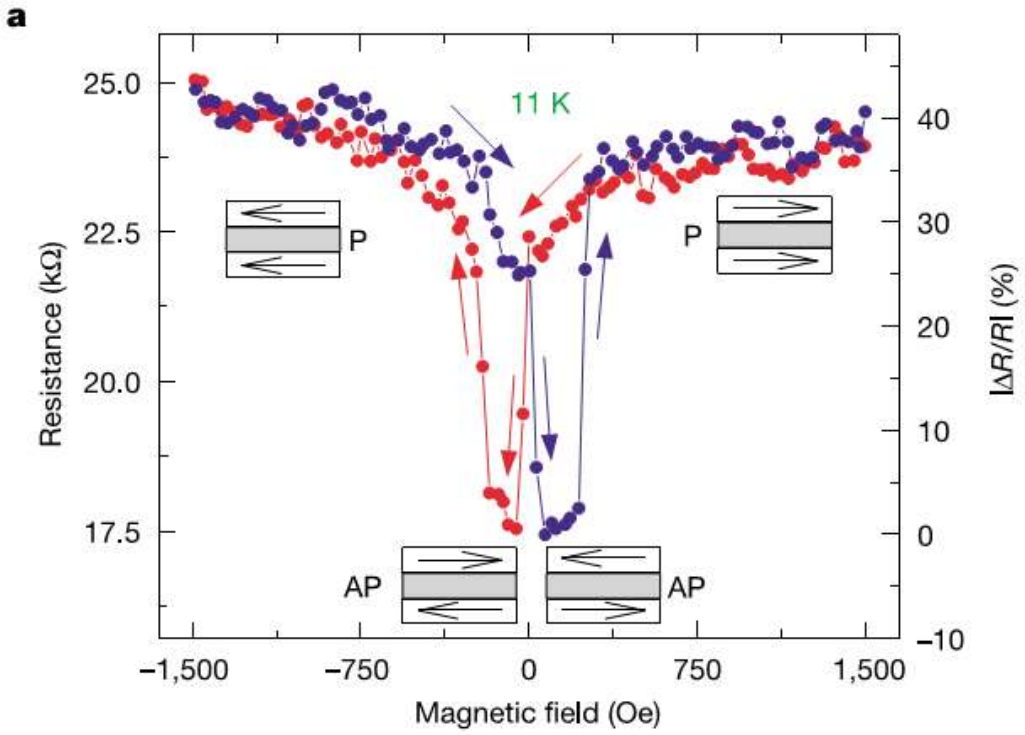




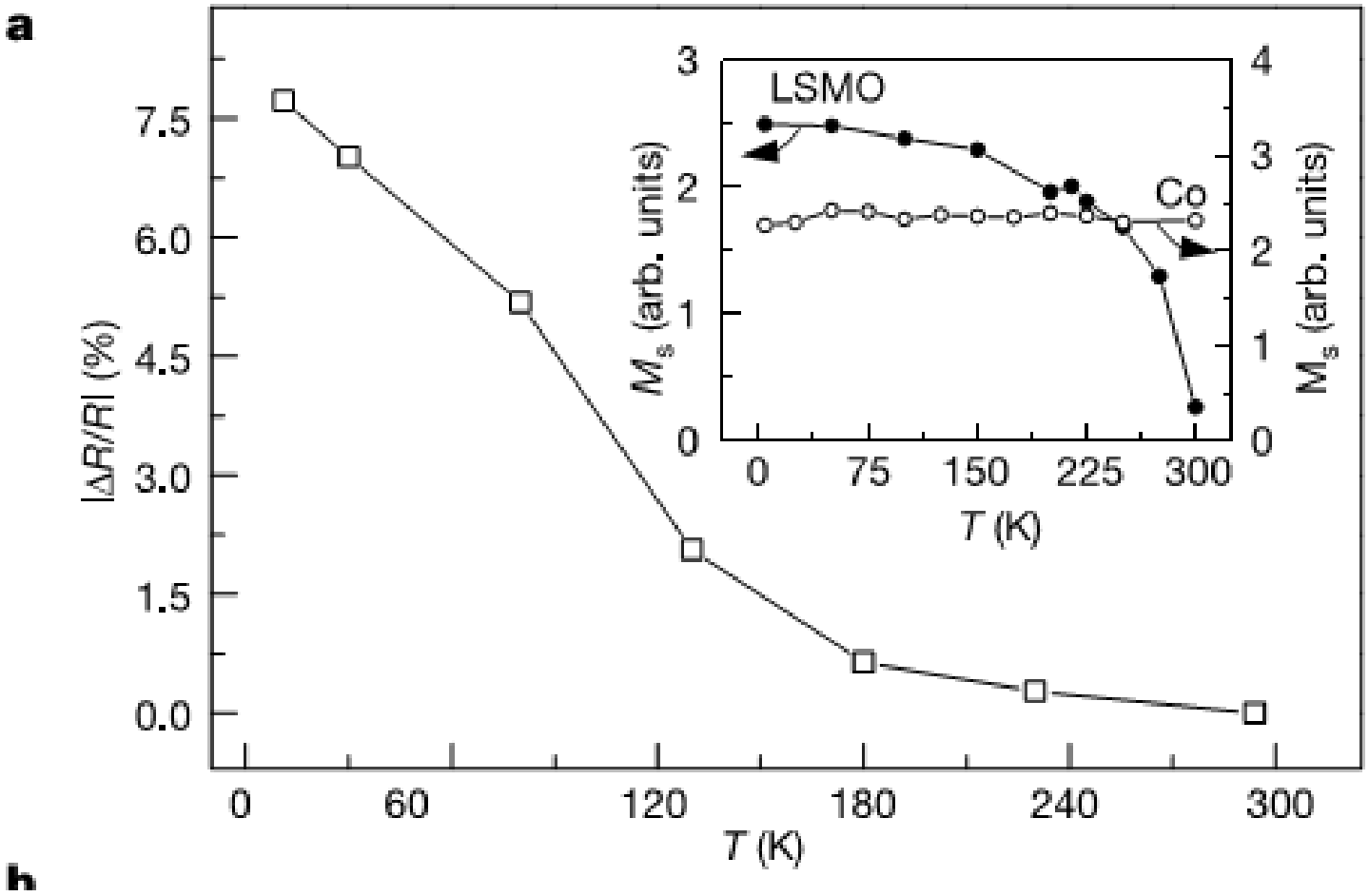
Xiong, et al, Nature (2004)

Organic Materials

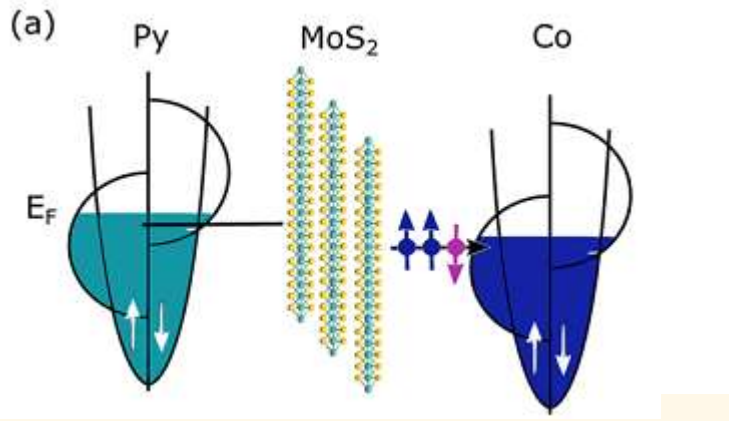


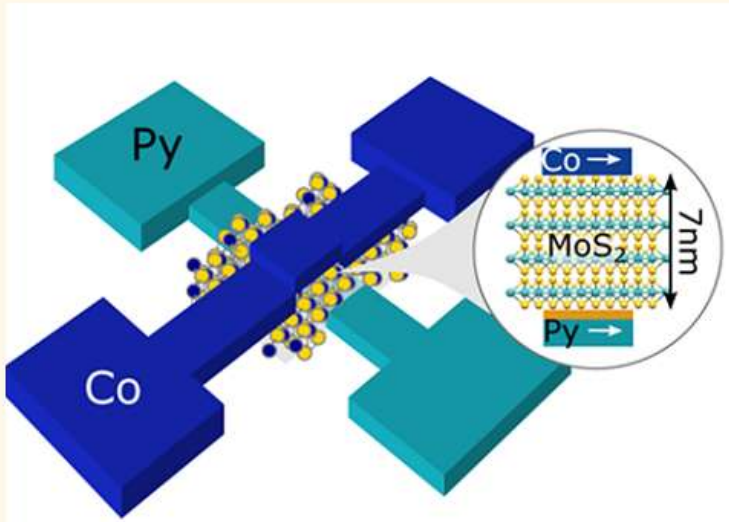


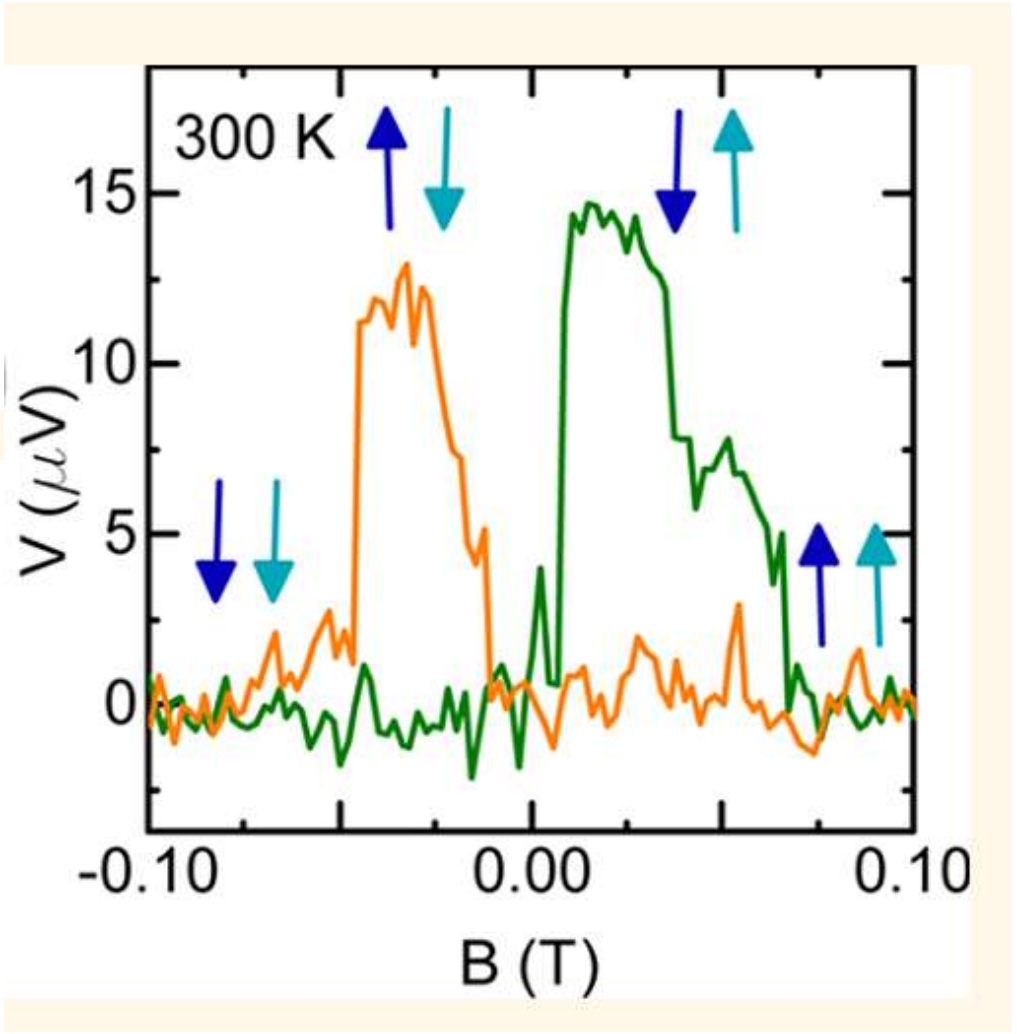
Organic Materials



2D Materials



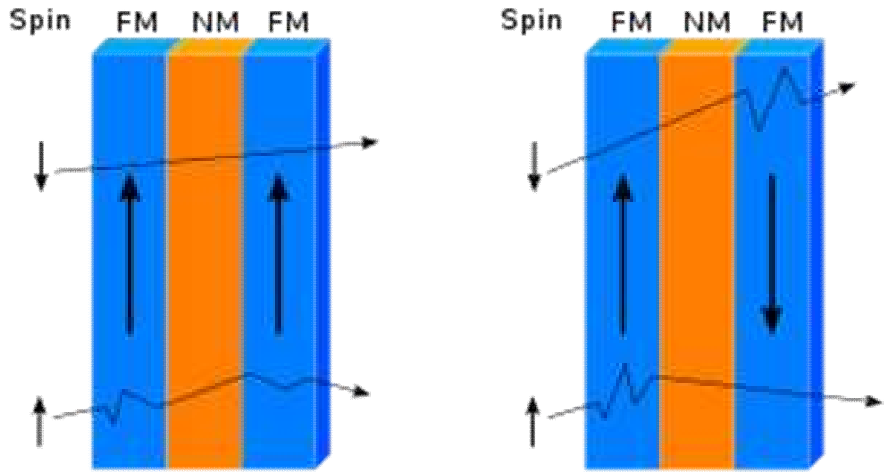


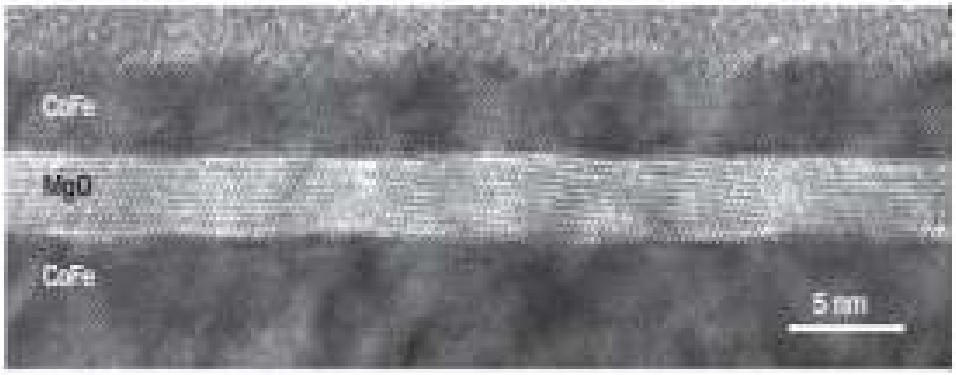


Dankert, et al, ACS Nano (2017)
Wang, et al, Nano Lett. (2015)

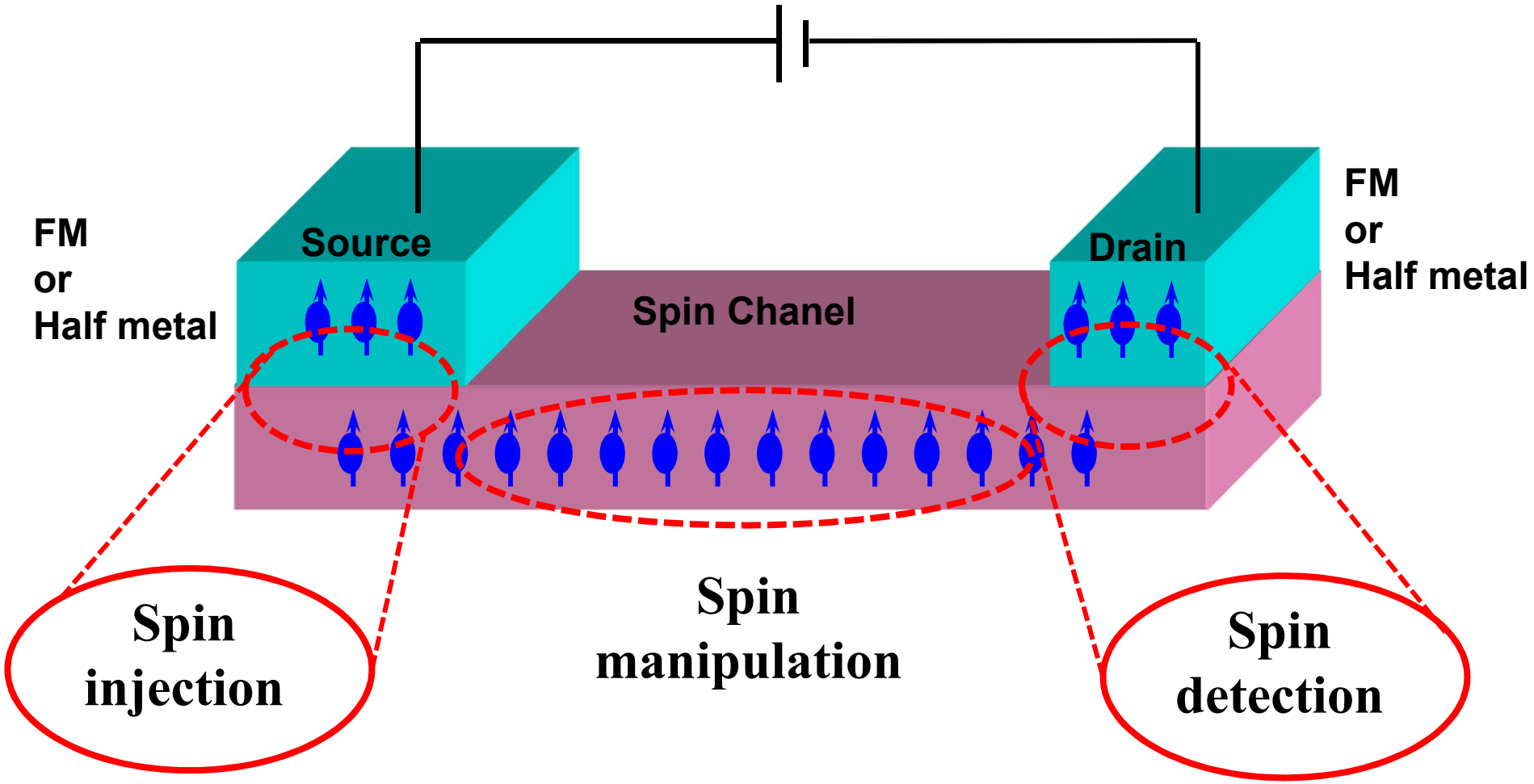
2. Why Lateral Spin Valves

Lateral Spin valves



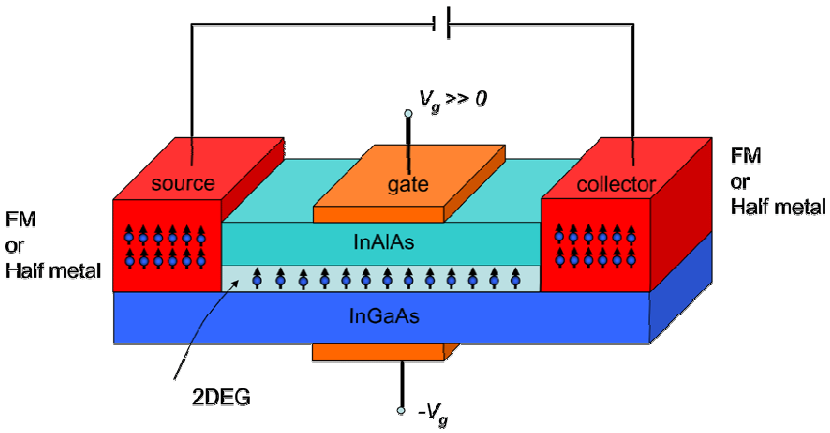


Lateral Spin valves



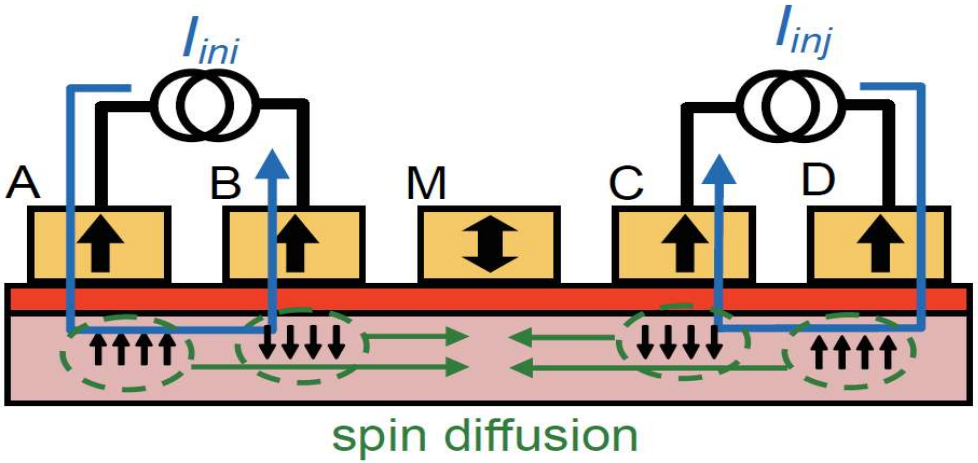
Lateral Spin valves

Spin transistor



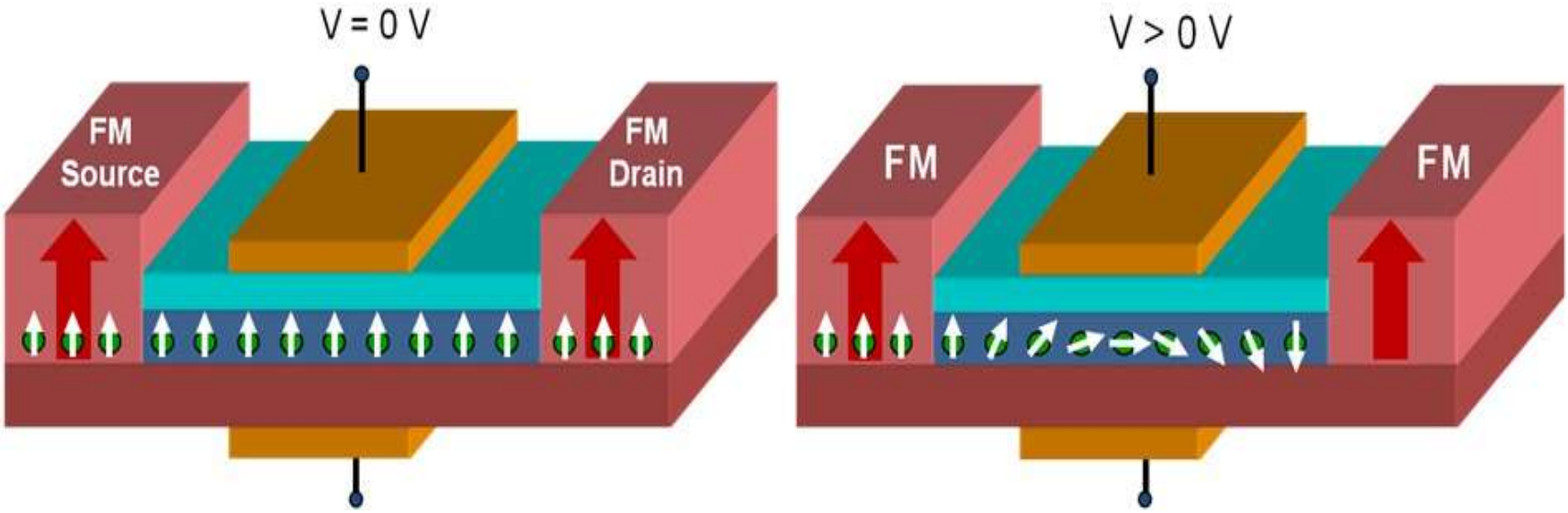
Datta & Das, APL (1990)

Spin logic and computing



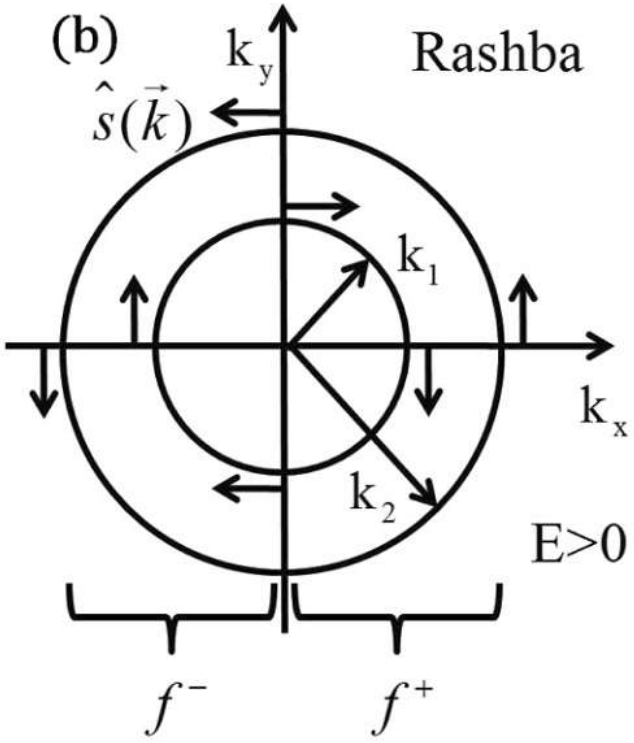
Dery, et al, Nature (2007)
Behin-Aein, et al, Nat. Nano (2010).
Dery, et al, IEEE Trans. Elec. Dev. (2012)

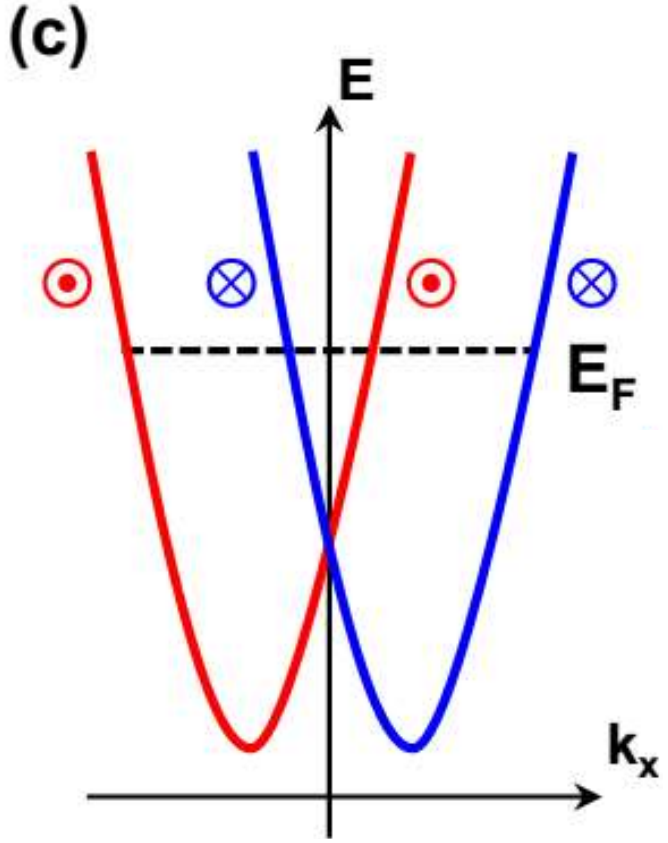
Spin transistor



Electronic analog of the electro - optic modulator - Scitation
scitation.aip.org/content/aip/journal/apl/56/7/10.../1.102730 ▾ 翻译此页
作者：S Datta - 1990 - 被引用次数：4147 - 相关文章
1990年2月12日 - 10.1063/1.102730. Supriyo Datta[1] and Biswajit Das[1] ... Abstract; Full Text; References (12); Cited By (2579); Data & Media; Metrics; Related ...

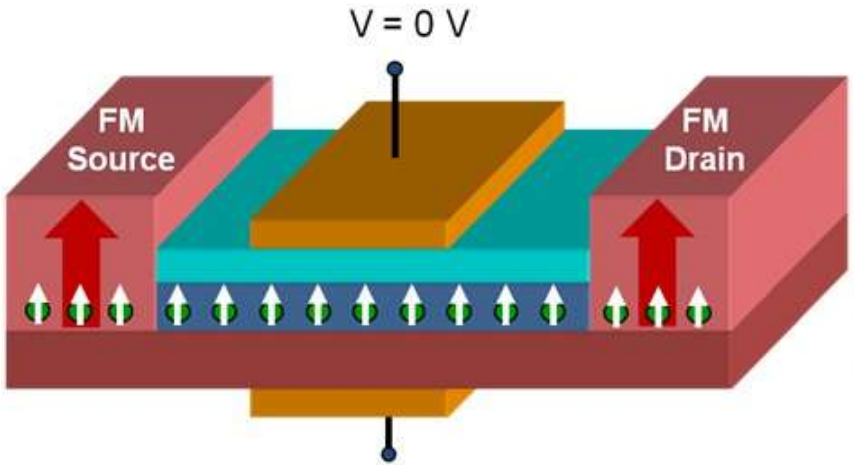
Rashba field





$$H_{\text{Rashba}} = \frac{\hbar^2}{2m}\left(k_x^2 + k_y^2\right) I_2 + \alpha(\sigma_x k_y - \sigma_y k_x),$$

Spin FET



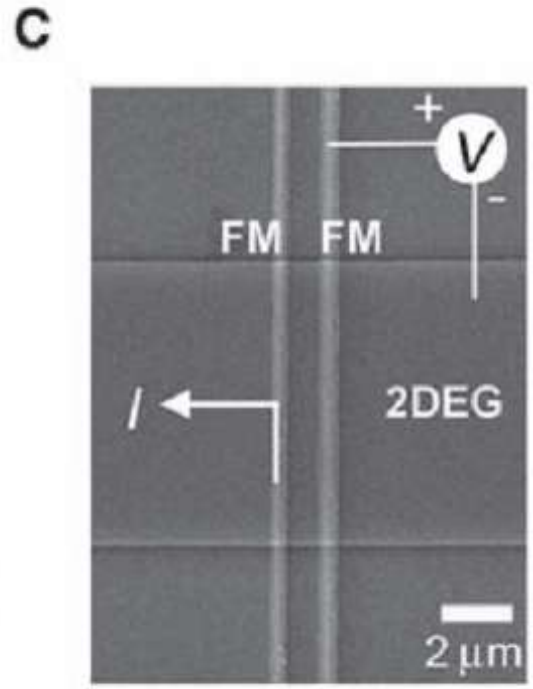
1) Long spin diffusion length

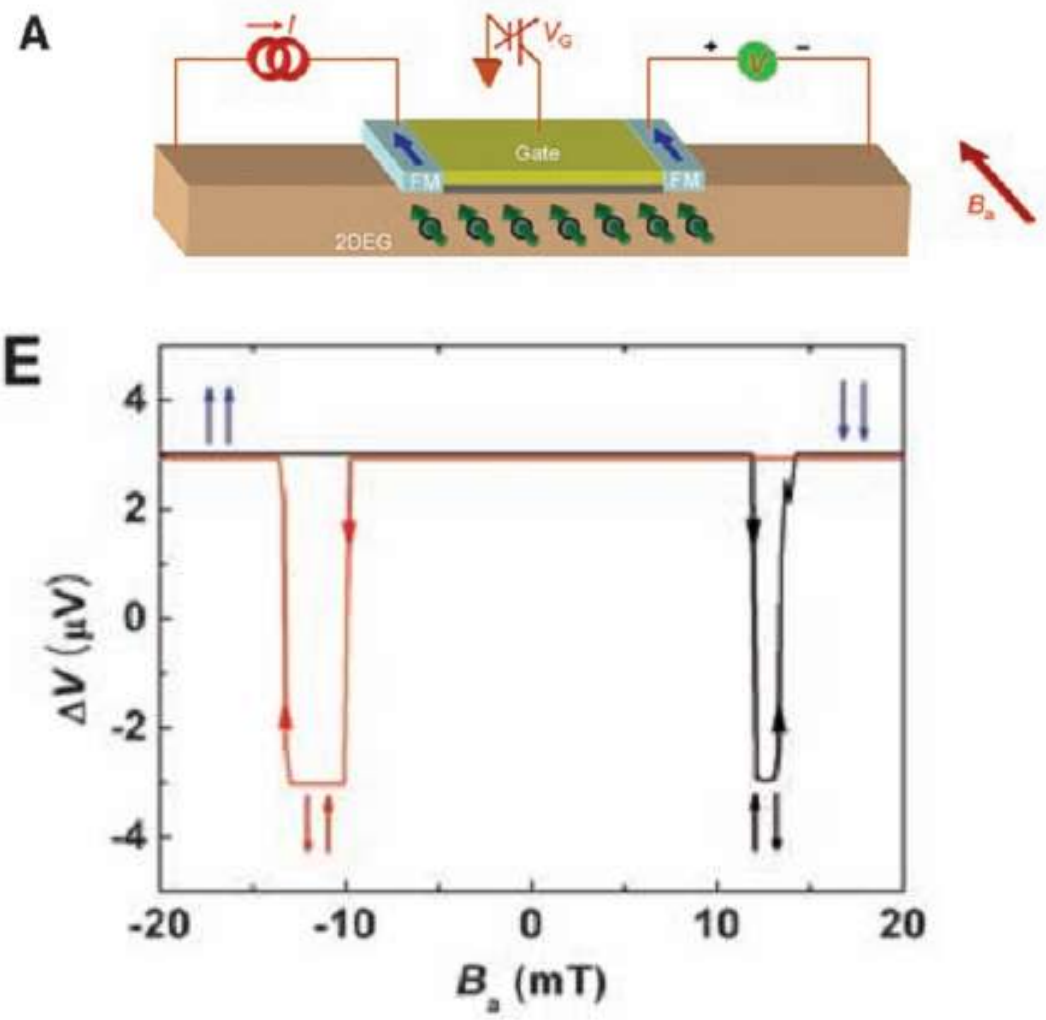
2) Large Rashba parameter → Rashba field

Datta & Das, APL (1990)

Spin FET

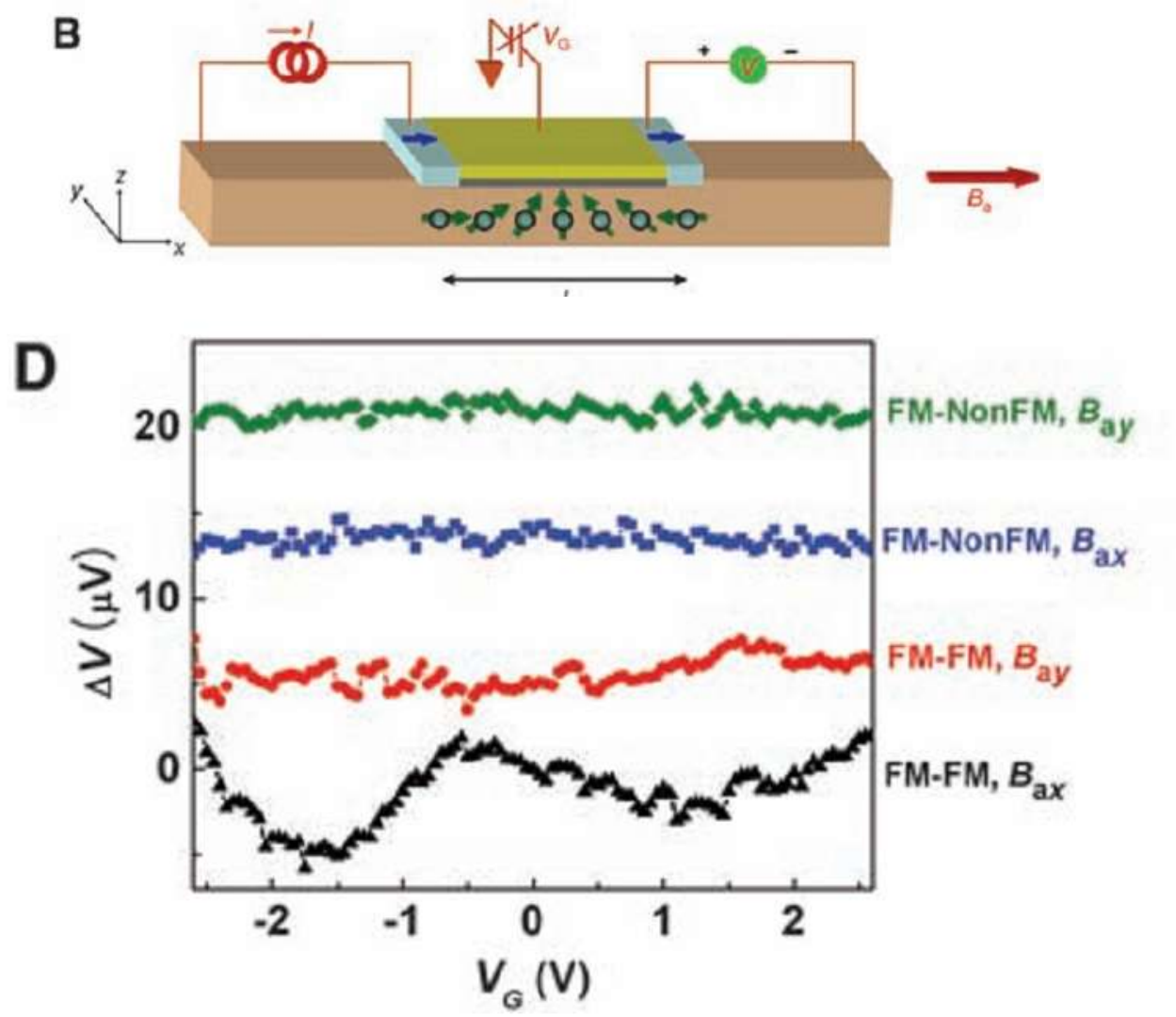
InAs channel



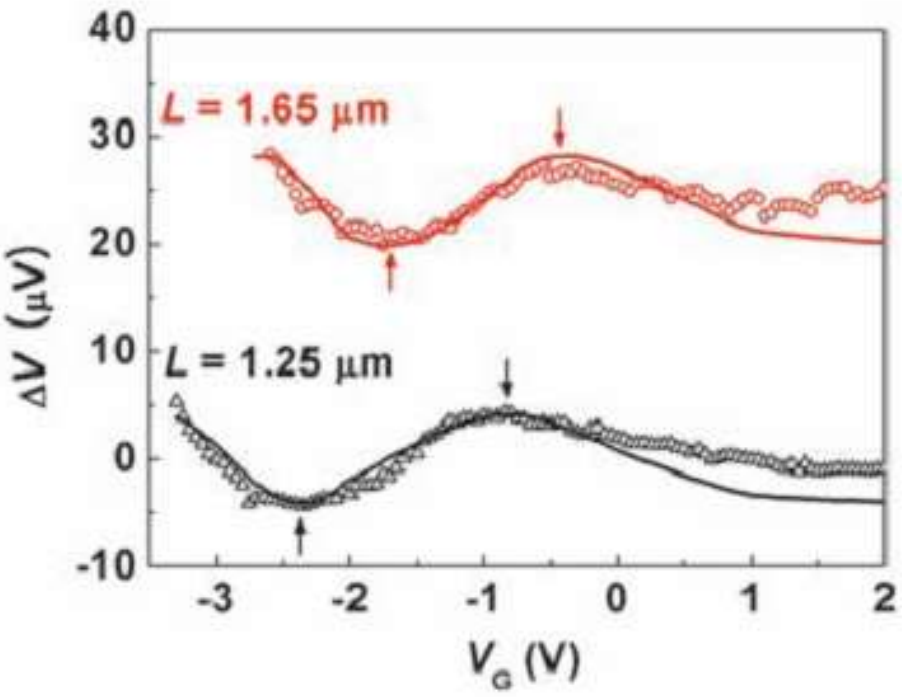


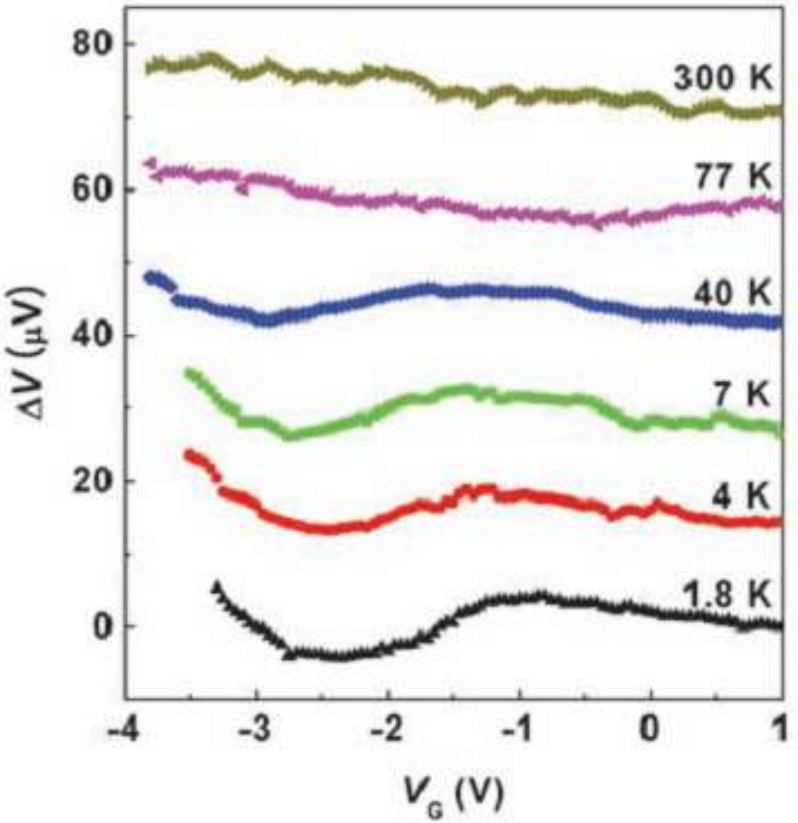
Koo, et al, Science (2009)

Spin FET

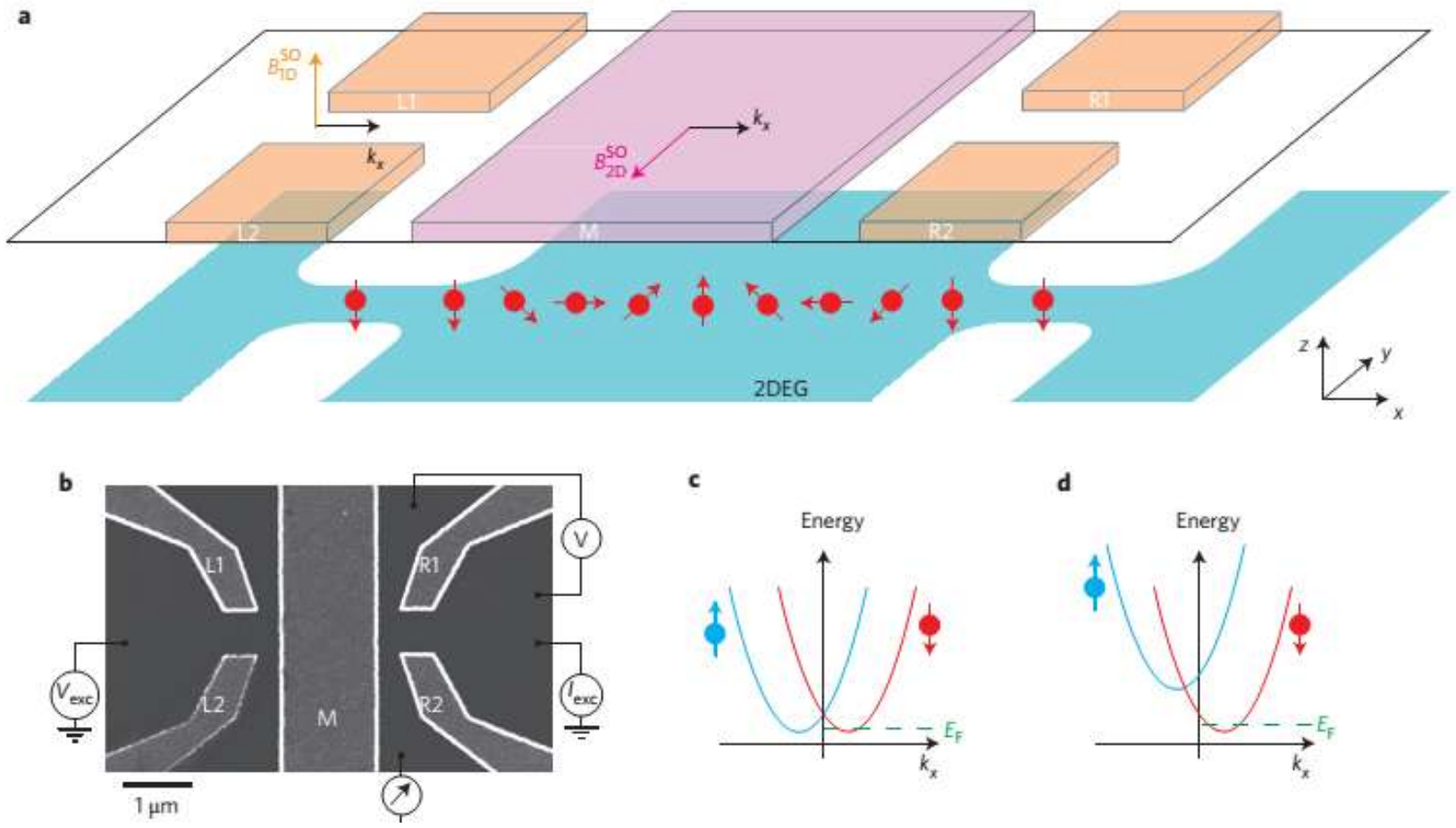

B
I
V_G
V
+
−
y
z
x
B_a
D
20
10
0
ΔV (μV)
FM-NonFM, B_{ay}
FM-NonFM, B_{ax}
FM-FM, B_{ay}
FM-FM, B_{ax}
-2
-1
0
1
2
V_G (V)

Spin FET



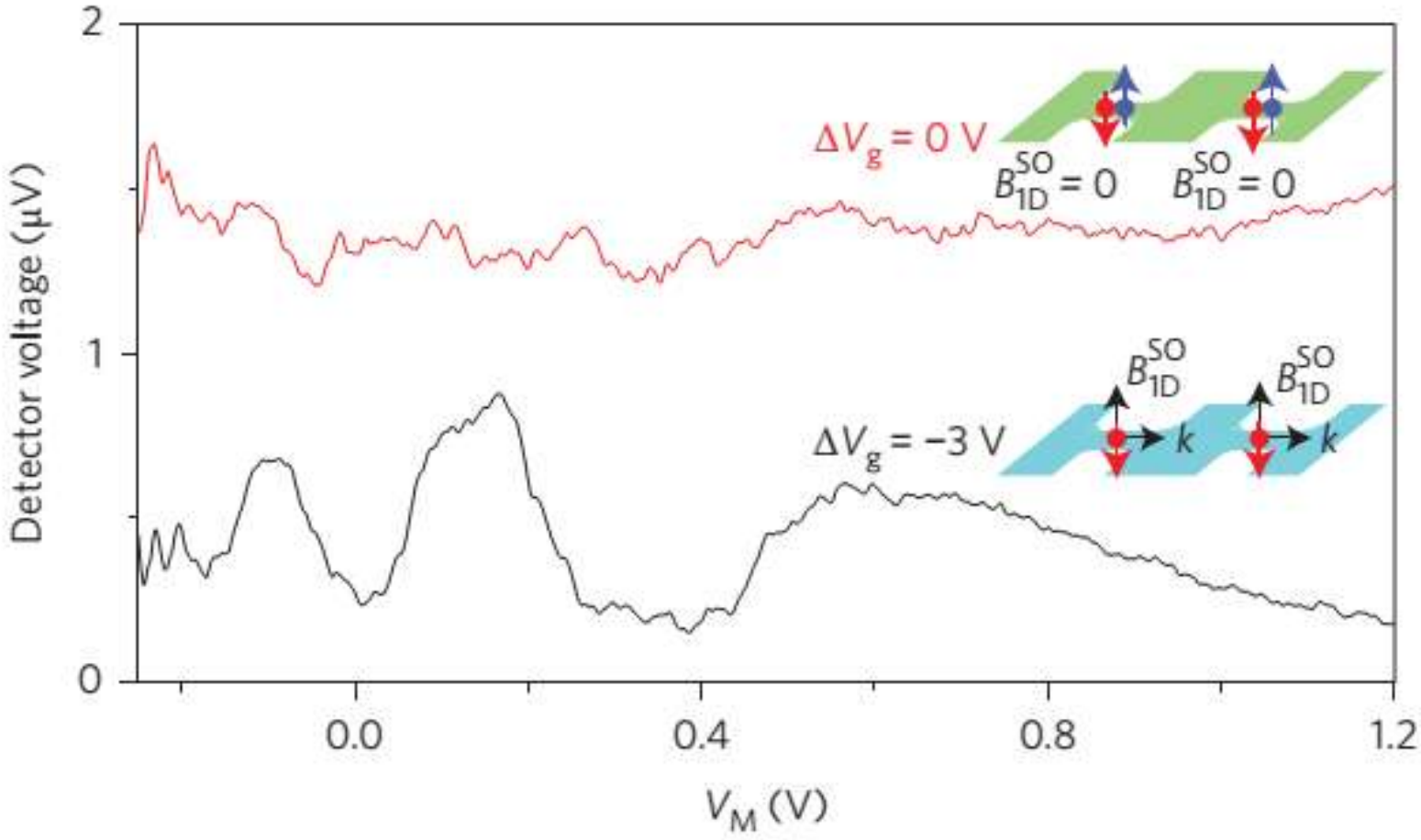


Spin FET

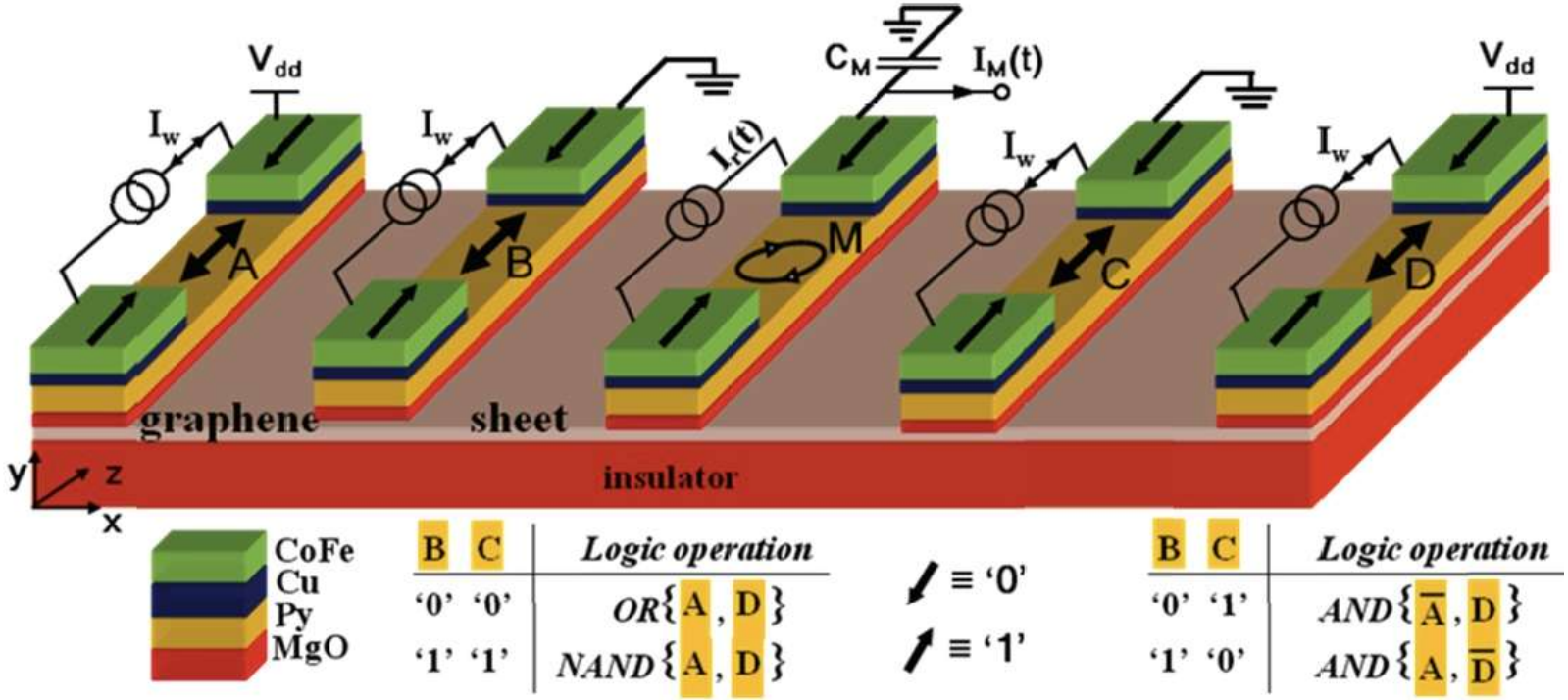


Chuang, et al, Nature Nanotech (2014)

Spin FET


2
1
0
Detector voltage (μV)
0.0
0.4
0.8
1.2
V_M (V)
$\Delta V_g = 0$ V
$B_{1D}^{SO} = 0$
$B_{1D}^{SO} = 0$
$\Delta V_g = -3$ V
B_{1D}^{SO}
B_{1D}^{SO}
k
k

Spin Logic



B	C	*Logic operation*
'0'	'0'	$OR\{A, D\}$
'1'	'1'	$NAND\{A, D\}$

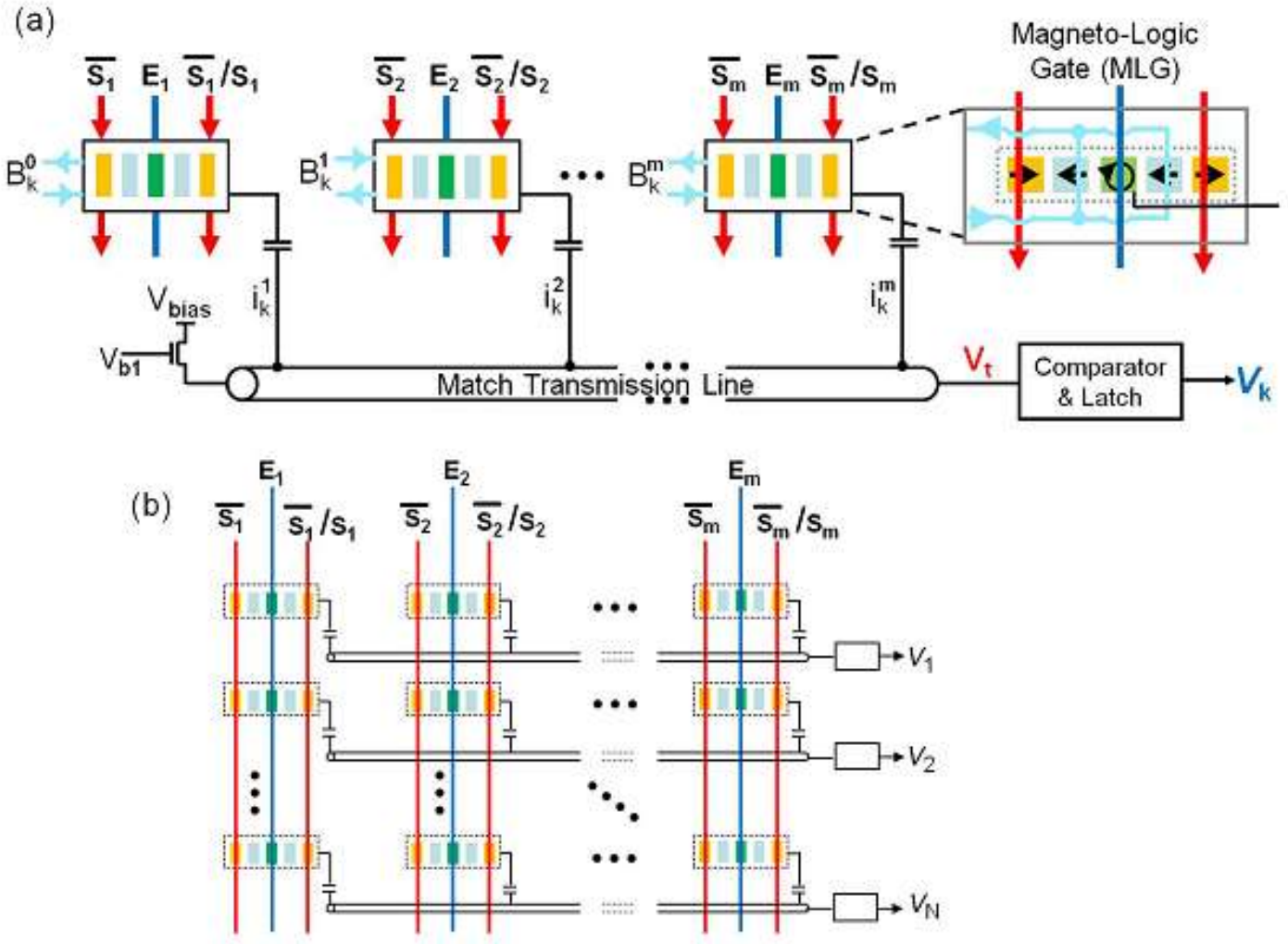
↙ ≡ '0'

↗ ≡ '1'

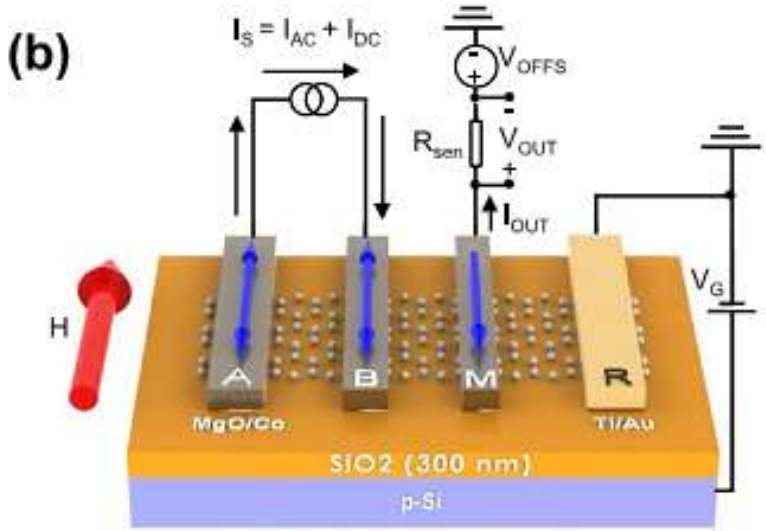
B	C	*Logic operation*
'0'	'1'	$AND\{\overline{A}, D\}$
'1'	'0'	$AND\{A, \overline{D}\}$

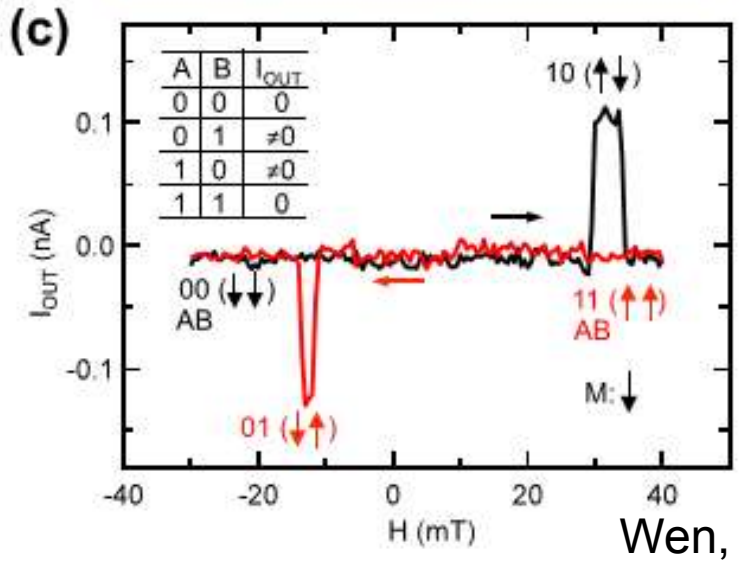
Dery, et al, Nature (2007)
Dery, et al, IEEE Trans. Elec. Dev. (2012)

Spin Logic


(a)
Magneto-Logic Gate (MLG)
Match Transmission Line
Comparator & Latch
(b)

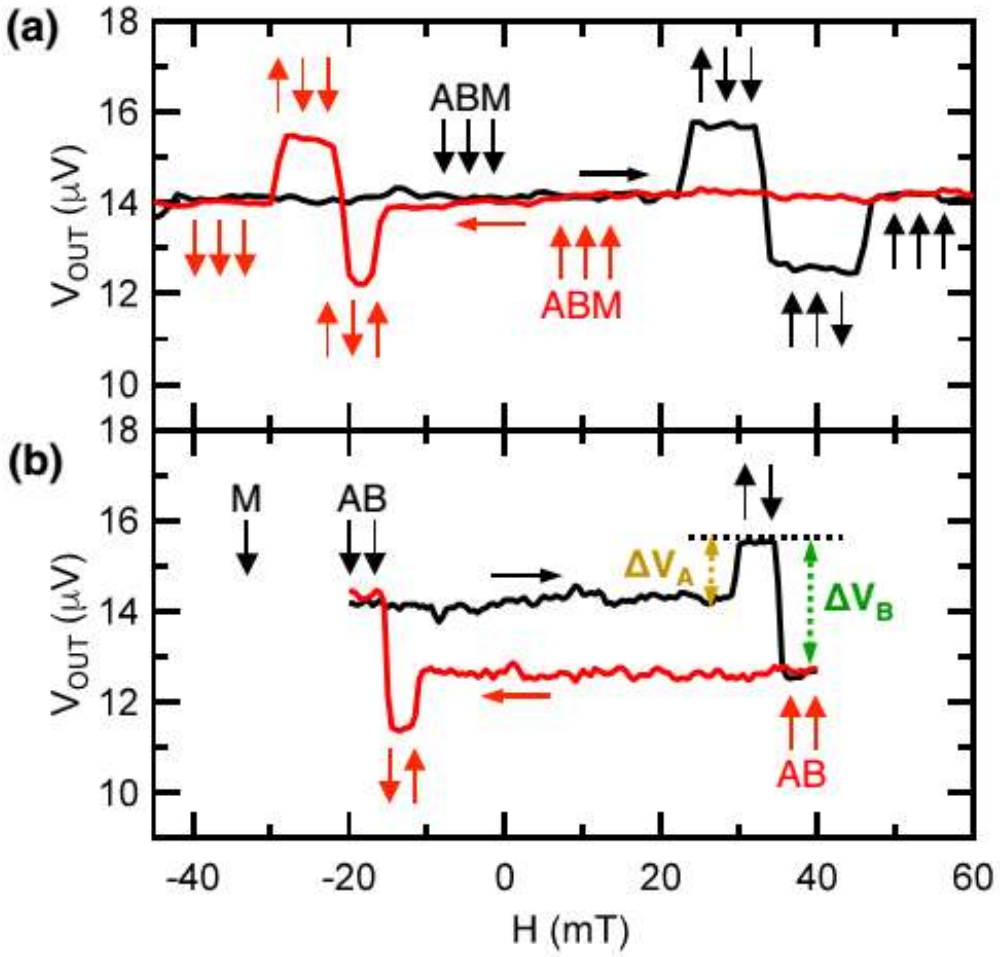
Spin Logic



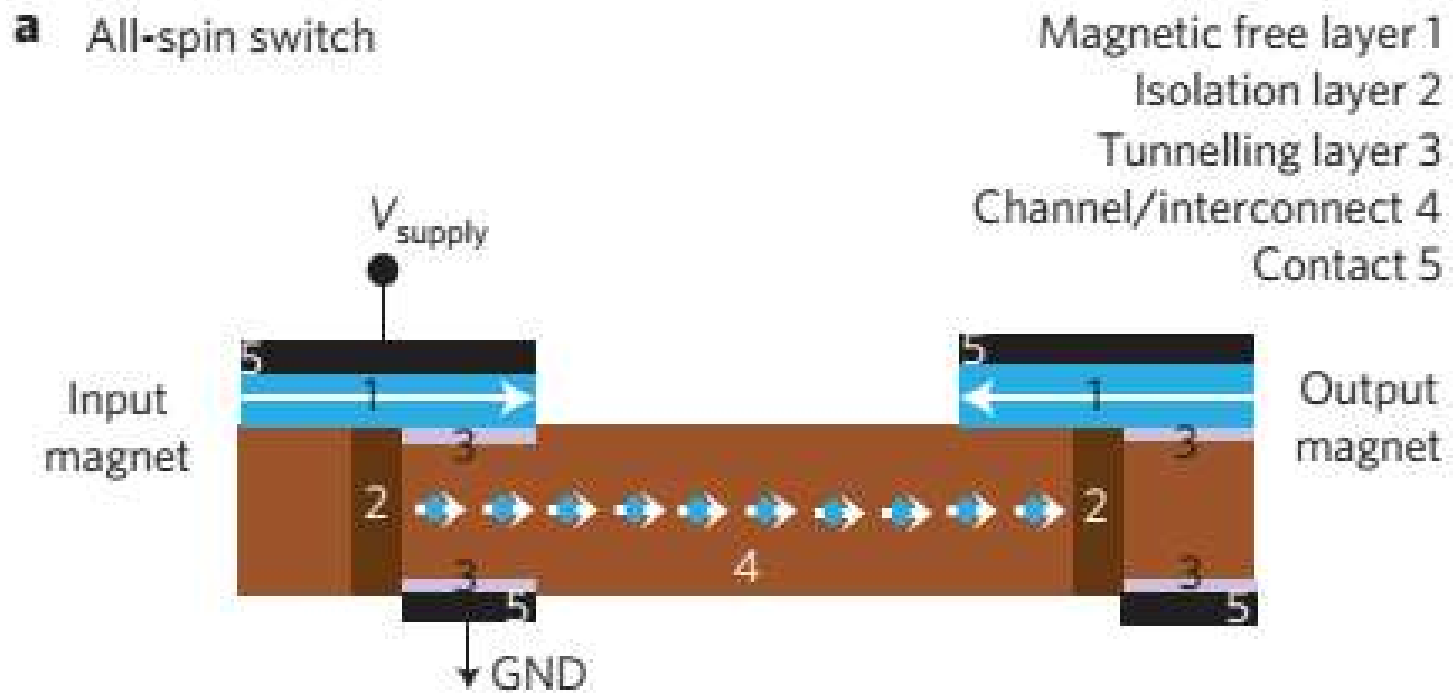


Wen, et al, PR Applied (2016)

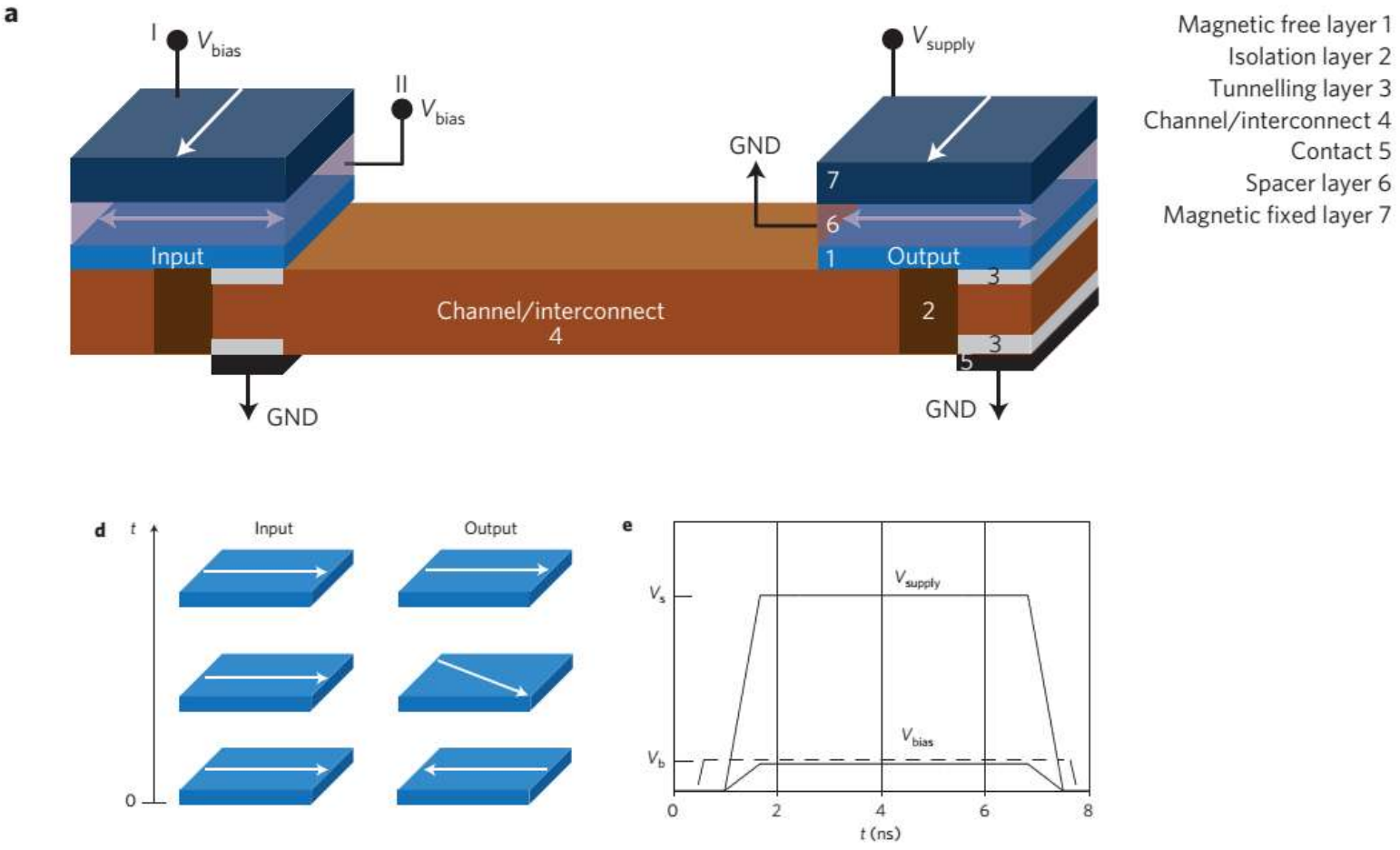
Spin Logic


(a)
(b)
ABM
ABM
M
AB
AB
ΔV_A
ΔV_B
V_{OUT} (μV)
H (mT)
18
16
14
12
10
-40
-20
0
20
40
60

Spin Logic

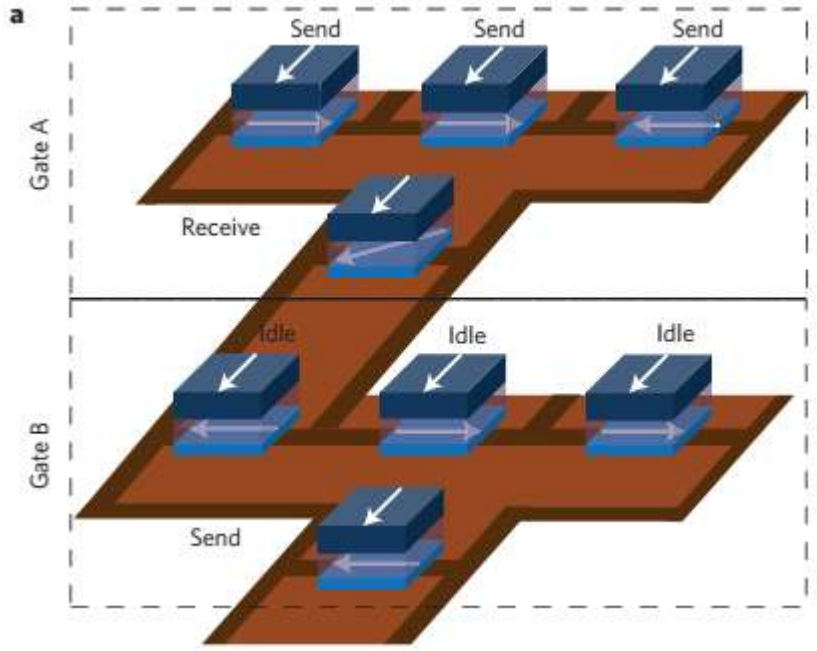

a All-spin switch
Magnetic free layer 1
Isolation layer 2
Tunnelling layer 3
Channel/interconnect 4
Contact 5
V_{supply}
Input magnet
Output magnet
GND

Spin Logic

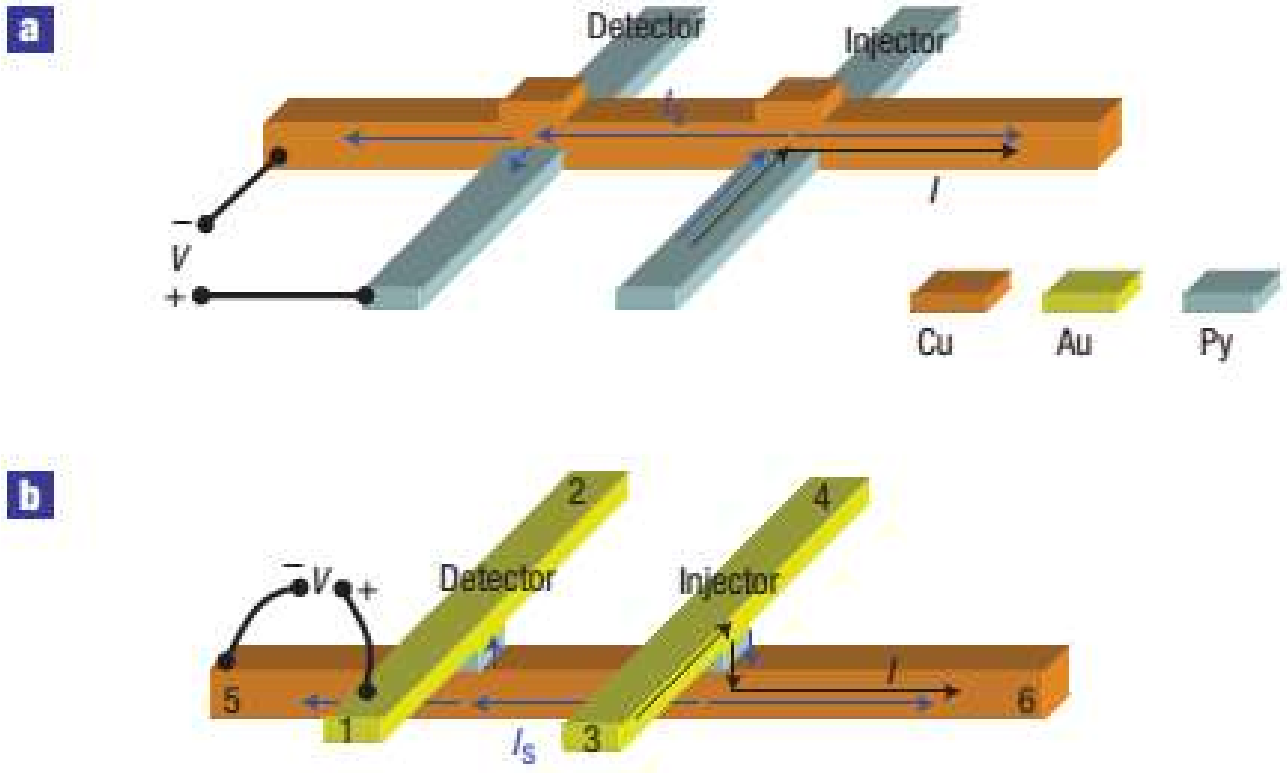


Behin-Aein, et al. Nature Nanotech. (2010)

Spin Logic

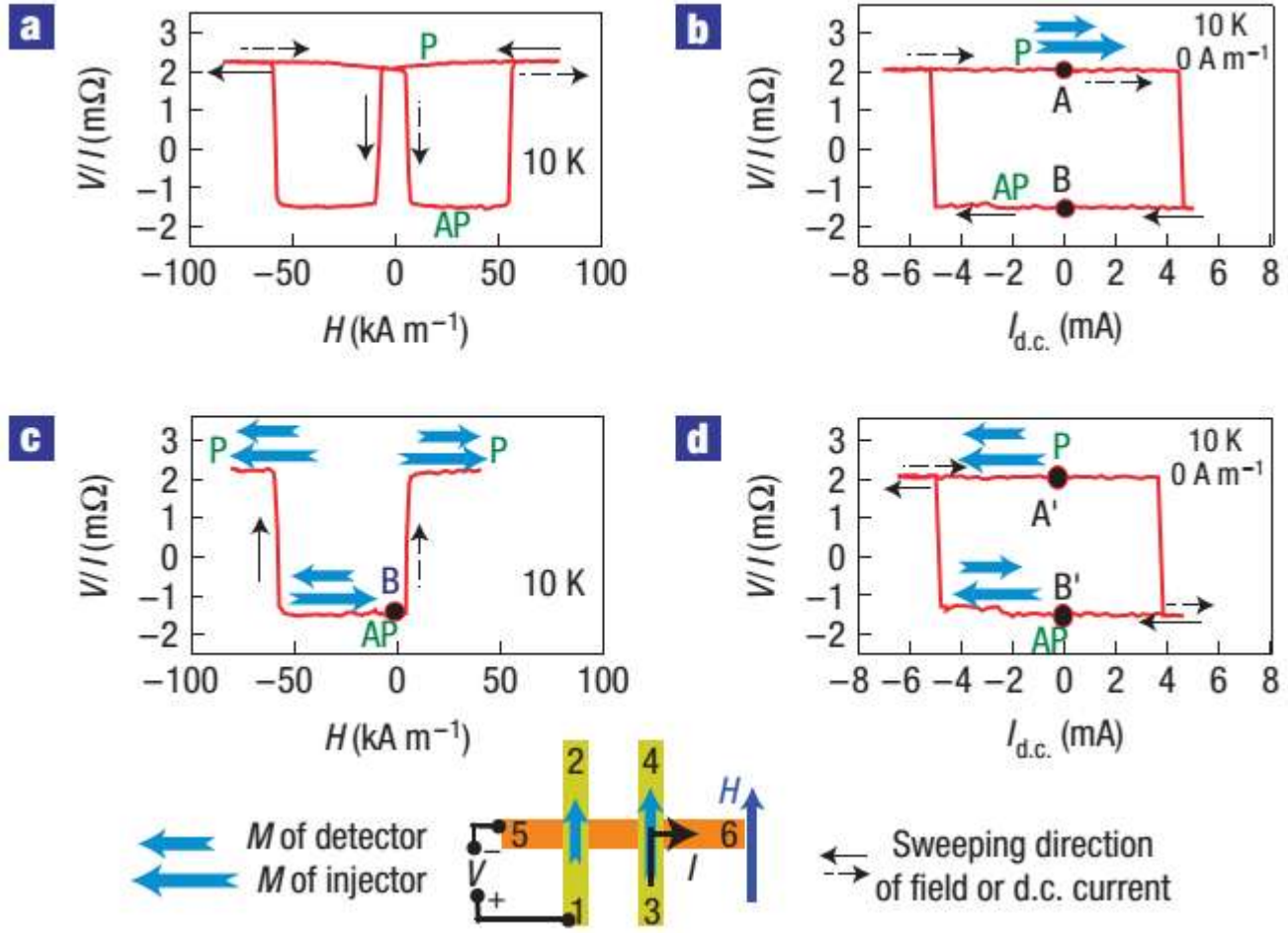


Spin Logic

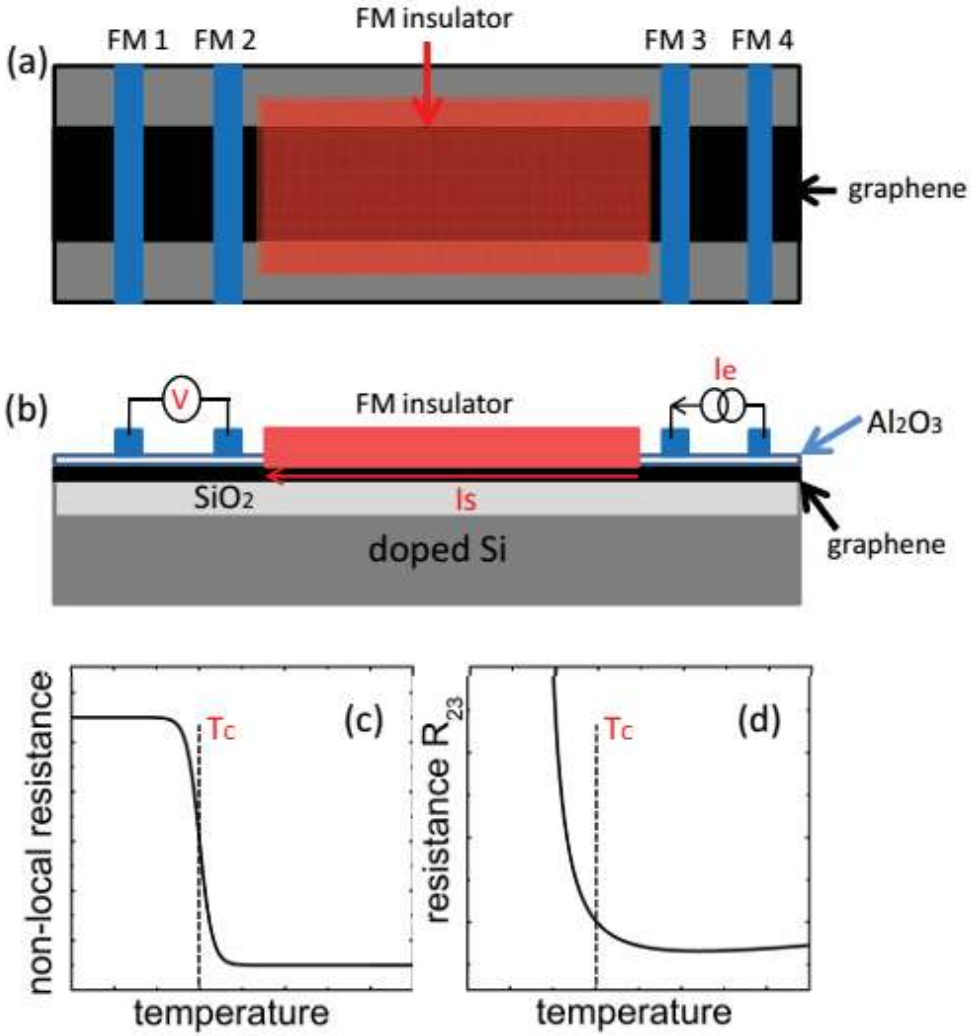


Yang, et al. Nature Nanotech. (2008)

Spin Logic


a
V/I (mΩ)
P
AP
10 K
H (kA m⁻¹)
b
10 K
0 A m⁻¹
A
B
I d.c. (mA)
c
B
d
A'
B'
M of detector
M of injector
Sweeping direction
of field or d.c. current

Spin Superconductor

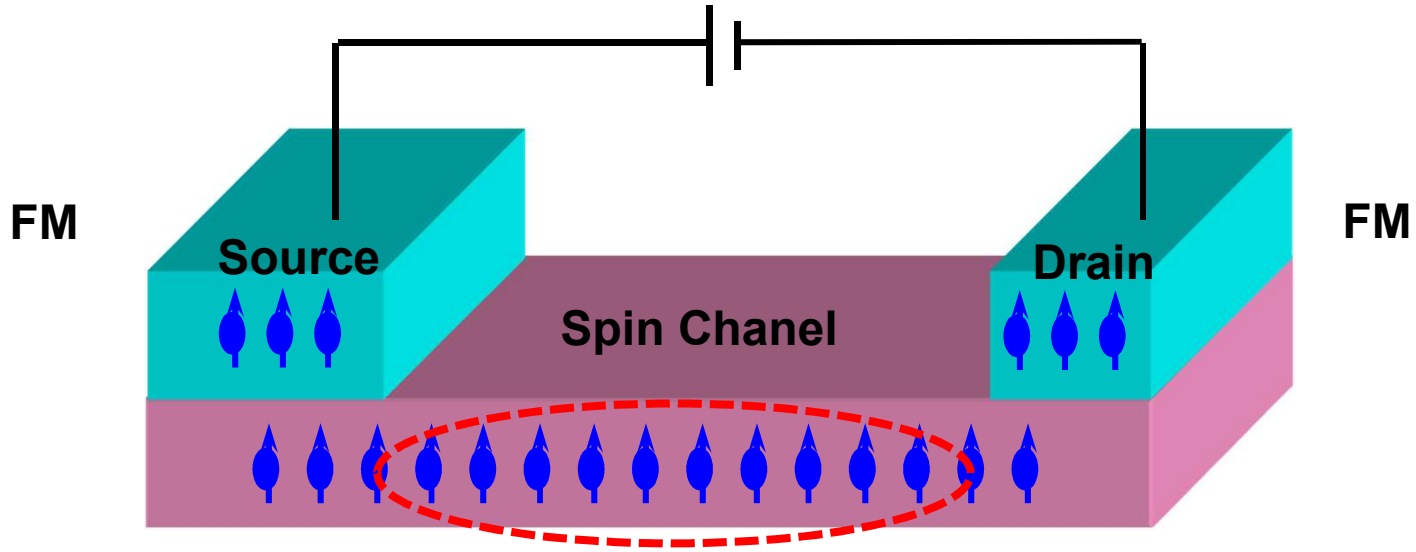


ICQM: Sun & Xie, PRB (2011), Nature Comm (2013)

Summary

Vertical Spin valves

Lateral Spin valves



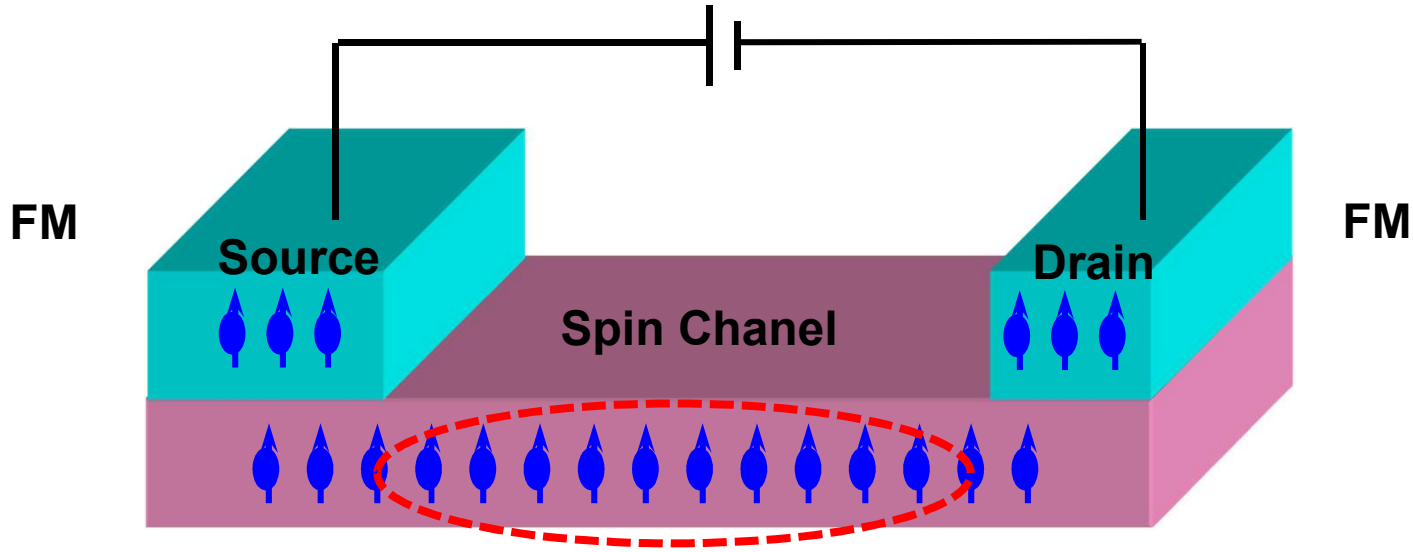
Spin manipulation

休息10分钟

Summary

Vertical Spin valves

Lateral Spin valves



Spin manipulation

Outline

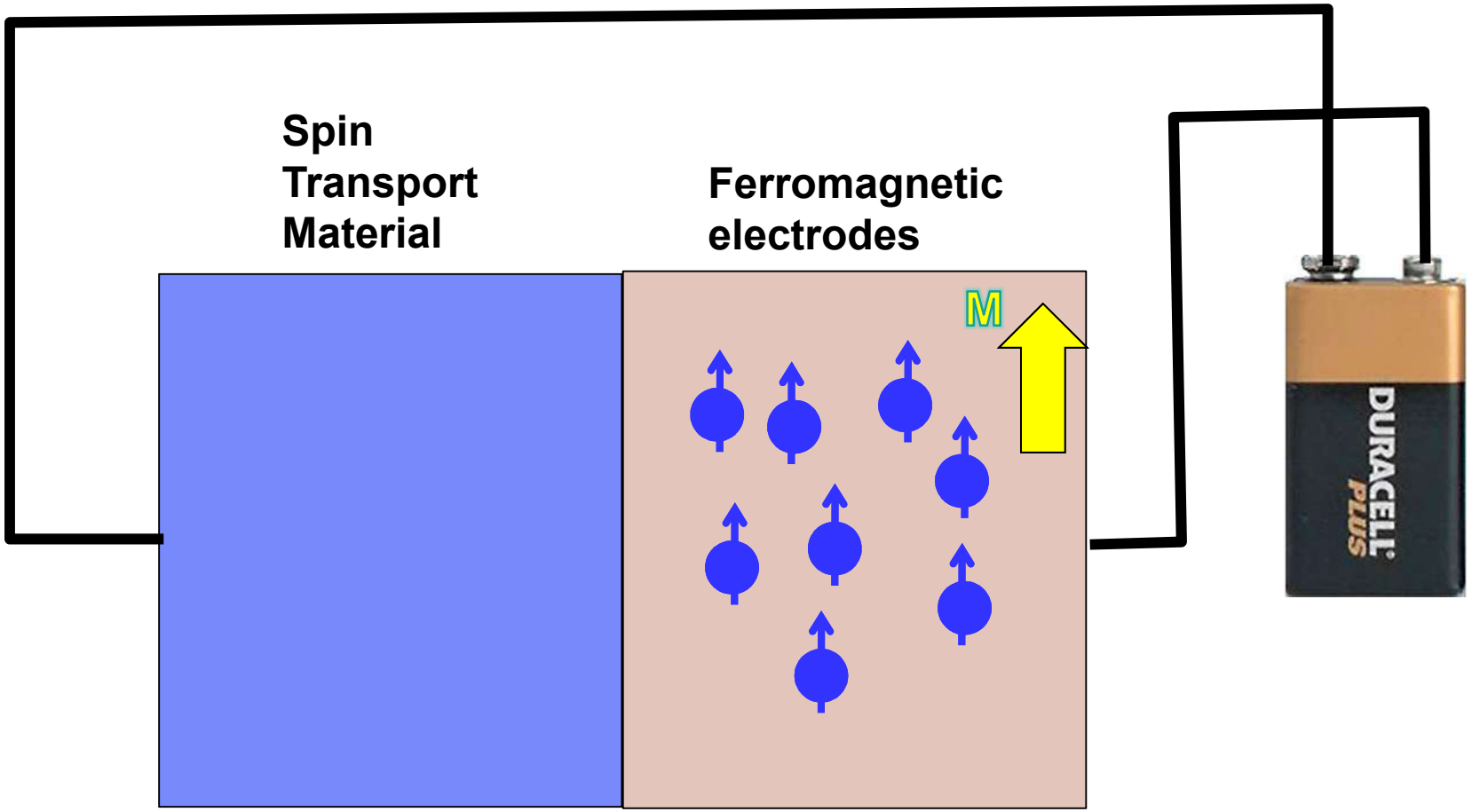
3. Spin injection

- ❑ **Electrical**
- ❑ **Optical**
- ❑ **Dynamic**
- ❑ **Thermal**

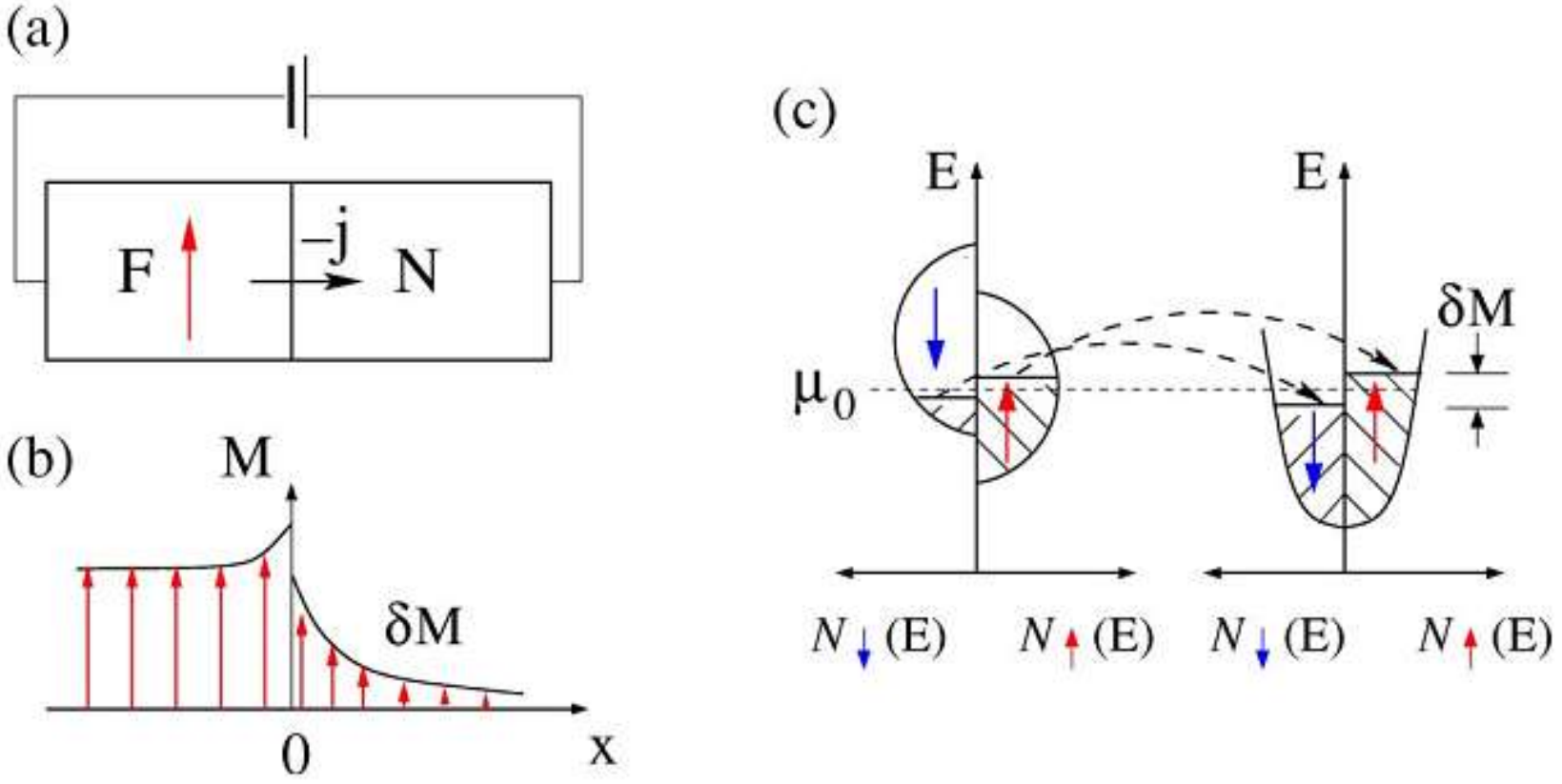
3. Spin injection

- **Electrical**

Electrical Spin injection



Electrical Spin injection



Zutic, et al, Rev. Mod. Phys. (2004)

Electrical Spin injection

Charge current:

$$\boldsymbol{j = \sigma \nabla \mu}$$

Einstein relation

$$\boldsymbol{\sigma = q^2 N D}$$

Spin current:

$$\boldsymbol{j_{\uparrow} = \sigma_{\uparrow} \nabla \mu_{\uparrow}} \qquad \boldsymbol{\sigma_{\uparrow} = q^2 N_{\uparrow} D_{\uparrow}}$$

$$\boldsymbol{j_{\downarrow} = \sigma_{\downarrow} \nabla \mu_{\downarrow}} \qquad \boldsymbol{\sigma_{\downarrow} = q^2 N_{\downarrow} D_{\downarrow}}$$

Electrical Spin injection

Spin dependent chemical potential:

$$\mu_{\uparrow} = \left(\frac{qD_{\uparrow}}{\sigma_{\uparrow}}\right)\delta n_{\uparrow} - \emptyset$$

$$\mu_{\downarrow} = \left(\frac{qD_{\downarrow}}{\sigma_{\downarrow}}\right)\delta n_{\downarrow} - \emptyset$$

$$\delta n_{\uparrow} = n_{\uparrow} - n_{\uparrow 0}$$

D: diffusion coefficient

σ: conductivity

∅: electrical potential

Electrical Spin injection

Continuity:

$$\nabla j_{\uparrow} = +q\left[\frac{\delta n_{\uparrow}}{\tau_{\uparrow\downarrow}} - \frac{\delta n_{\downarrow}}{\tau_{\downarrow\uparrow}}\right]$$

$$\nabla j_{\downarrow} = -q\left[\frac{\delta n_{\downarrow}}{\tau_{\downarrow\uparrow}} - \frac{\delta n_{\downarrow}}{\tau_{\downarrow\uparrow}}\right]$$

Electrical Spin injection

Charge vs. Spin

$$\boldsymbol{\sigma = \sigma_{\uparrow} + \sigma_{\downarrow}}$$

$$\boldsymbol{N = N_{\uparrow} + N_{\downarrow}}$$

At the balance:

$$\boldsymbol{\frac{N_{\uparrow}}{\tau_{\uparrow\downarrow}} - \frac{N_{\downarrow}}{\tau_{\downarrow\uparrow}} = 0}$$

Electrical Spin injection

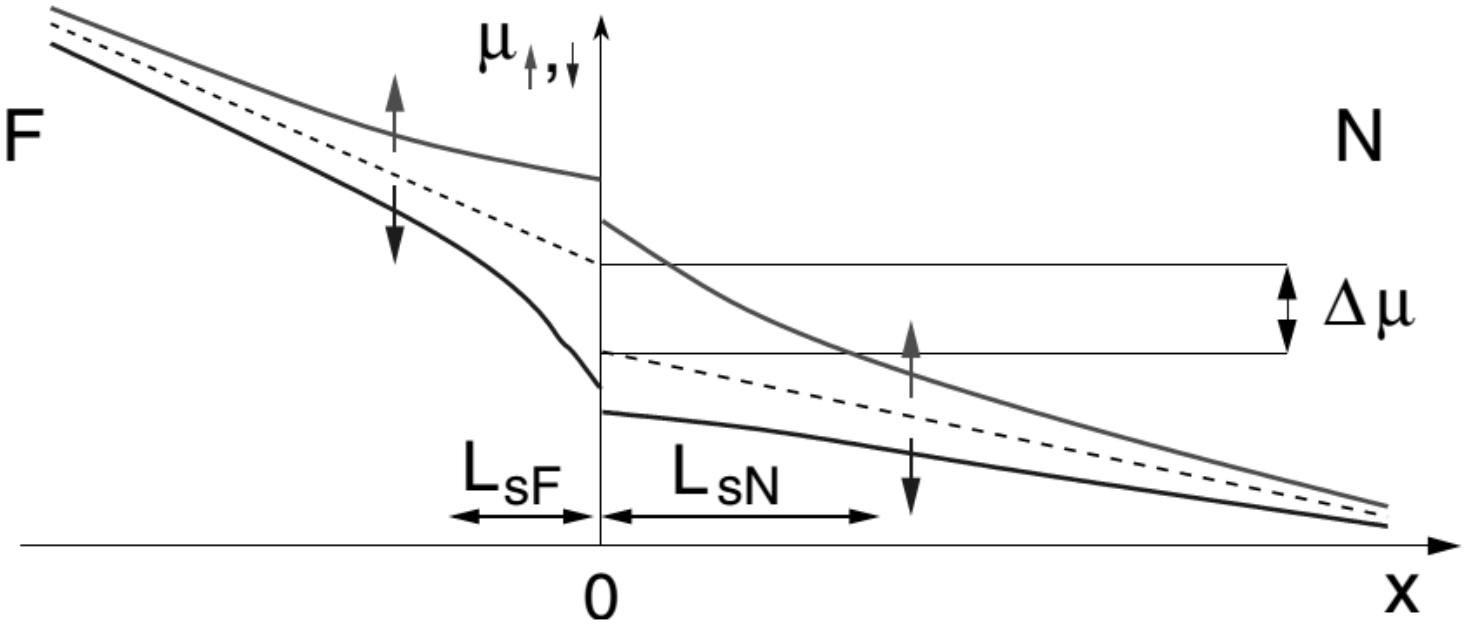
Interfacial Spin accumulation

$$\mu_S = \mu_{\uparrow} - \mu_{\downarrow}$$

$$\delta S = \delta n_{\uparrow} - \delta n_{\downarrow}$$

$$\mu_S = \frac{1}{2q}\frac{N_{\uparrow} + N_{\downarrow}}{N_{\uparrow} N_{\downarrow}}(\delta n_{\uparrow} - \delta n_{\downarrow})$$

Electrical Spin injection



Zutic, et al, Rev. Mod. Phys. (2004)

Electrical Spin injection

Spin diffusion length

$$L_{SF} = \sqrt{D_{SF}\tau_{sF}}$$

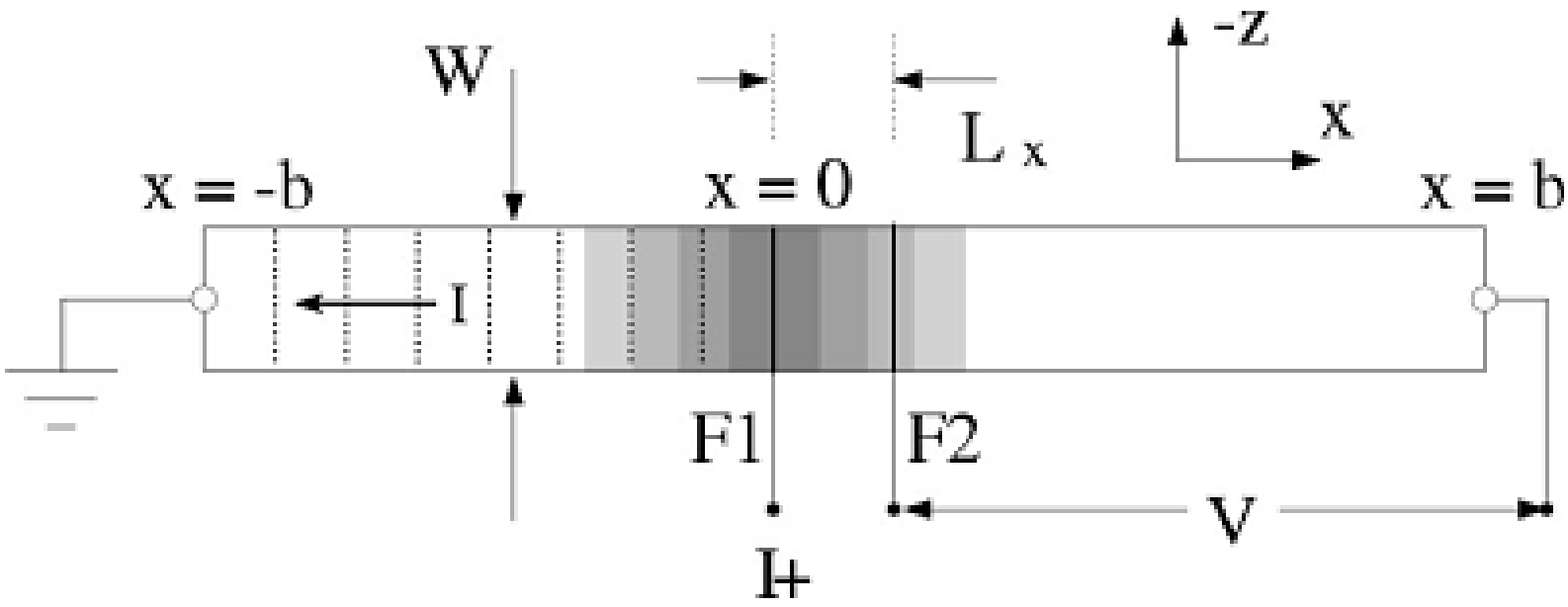
$$L_{SN} = \sqrt{D_{SN}\tau_{sN}}$$

Diffusion equation:

$$\nabla^2\mu_{SF} = \mu_{SF}/LSF^2$$

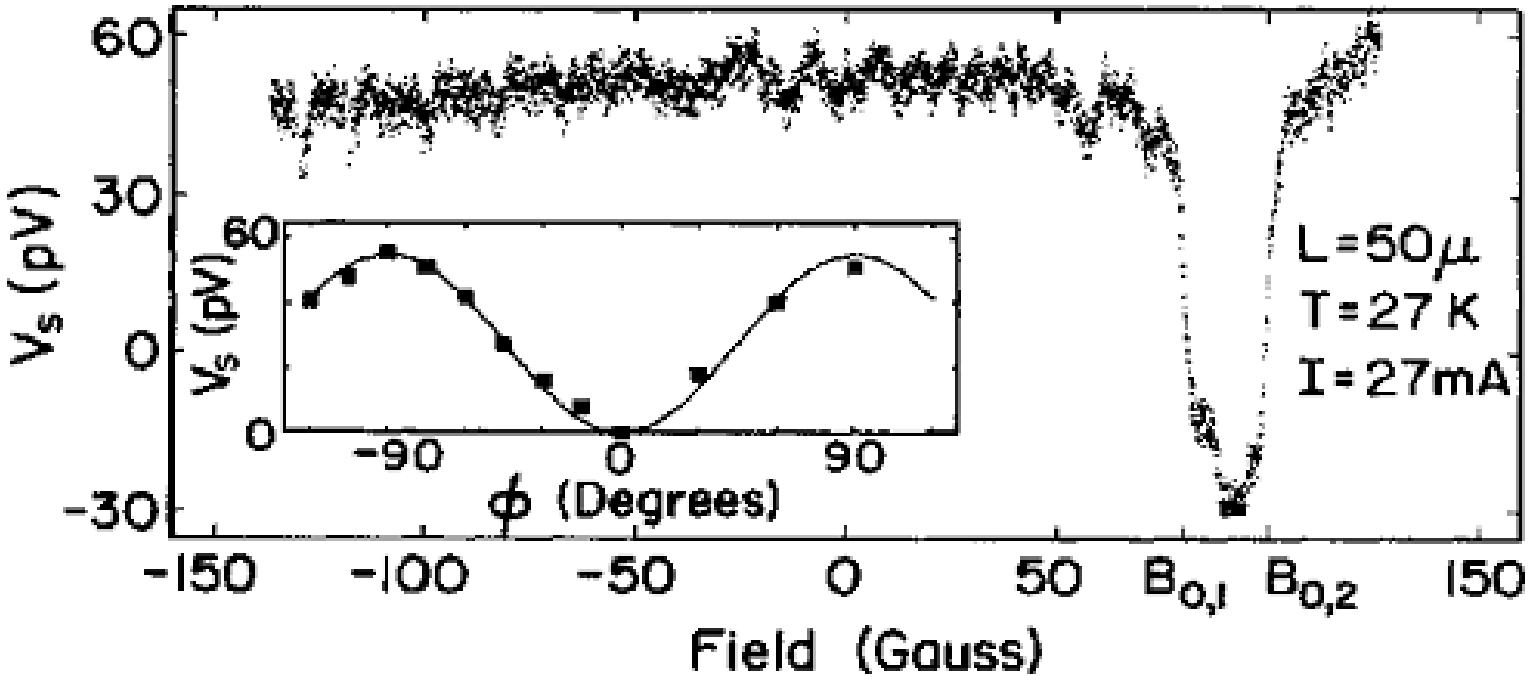
$$\nabla^2\mu_{SN} = \mu_{SN}/LSN^2$$

Electrical Spin injection



Johnson & Silsbee, PRL (1985)

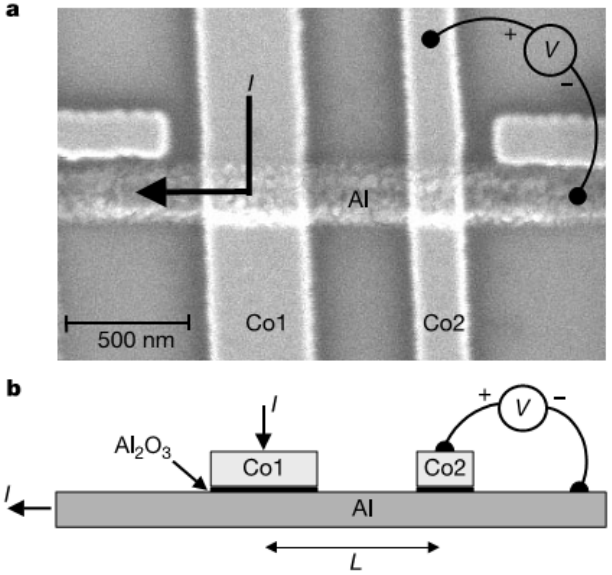
Electrical Spin injection



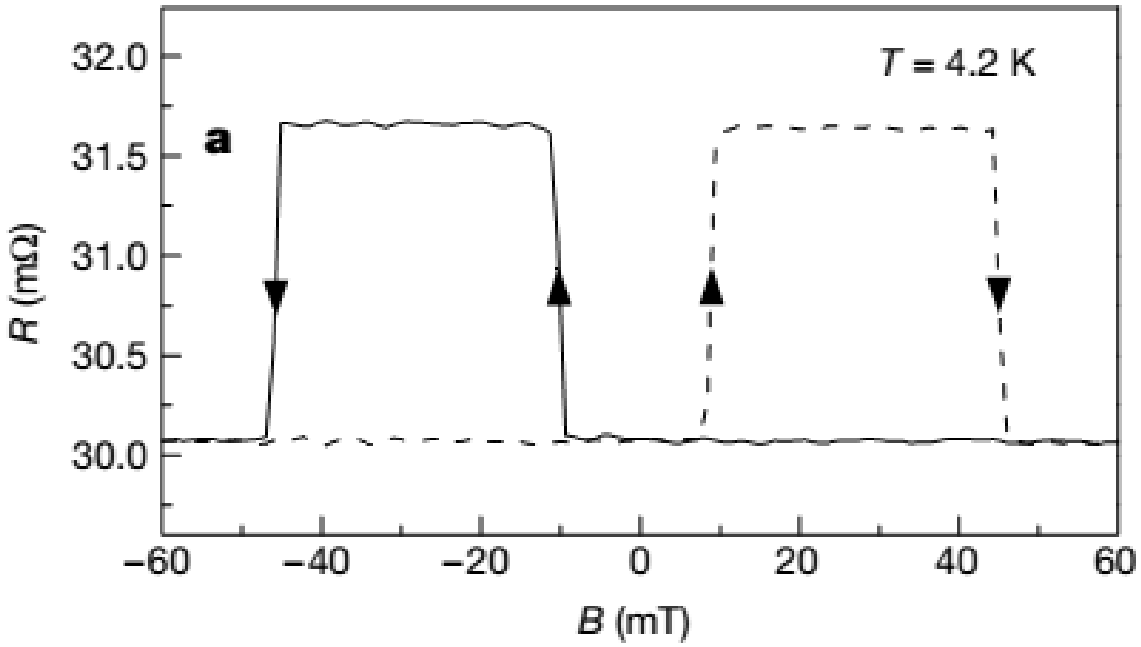
Johnson & Silsbee, PRL (1985)

Electrical Spin injection

Electron beam lithography



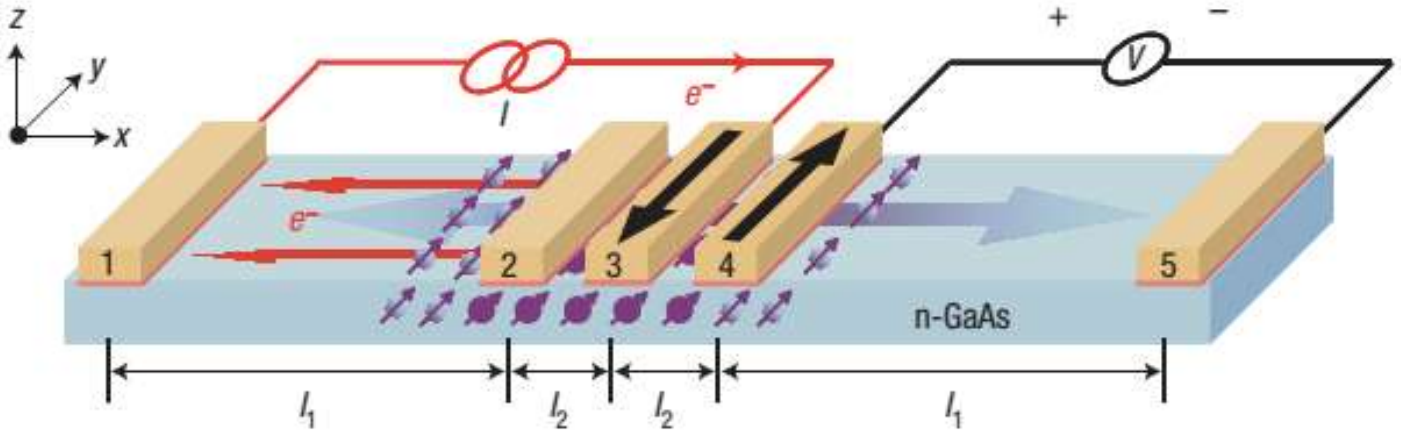
Nano Devices: spin diffusion length ~ μm

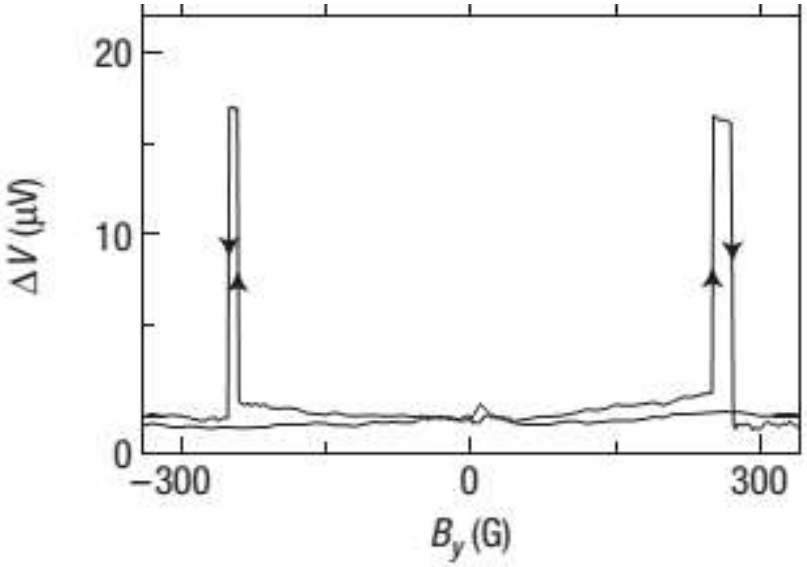


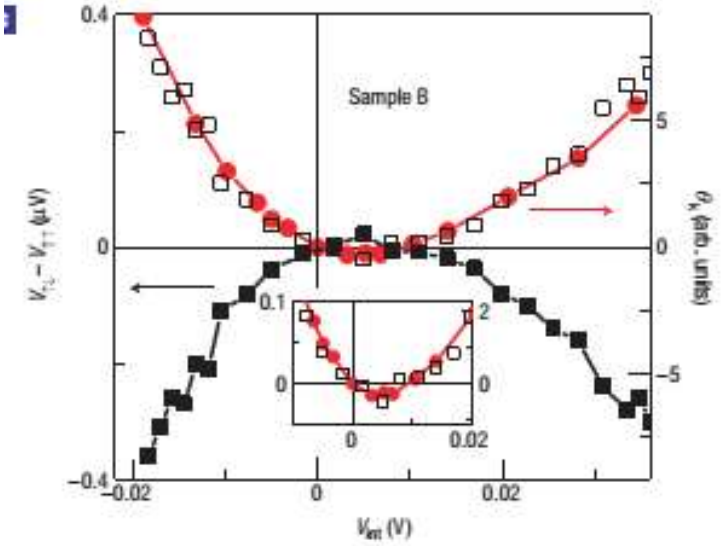
Jedema, et al, Nature (2001)
Jedema, et al, Nature (2002)

Electrical Spin injection

GaAs: a semiconducting channel

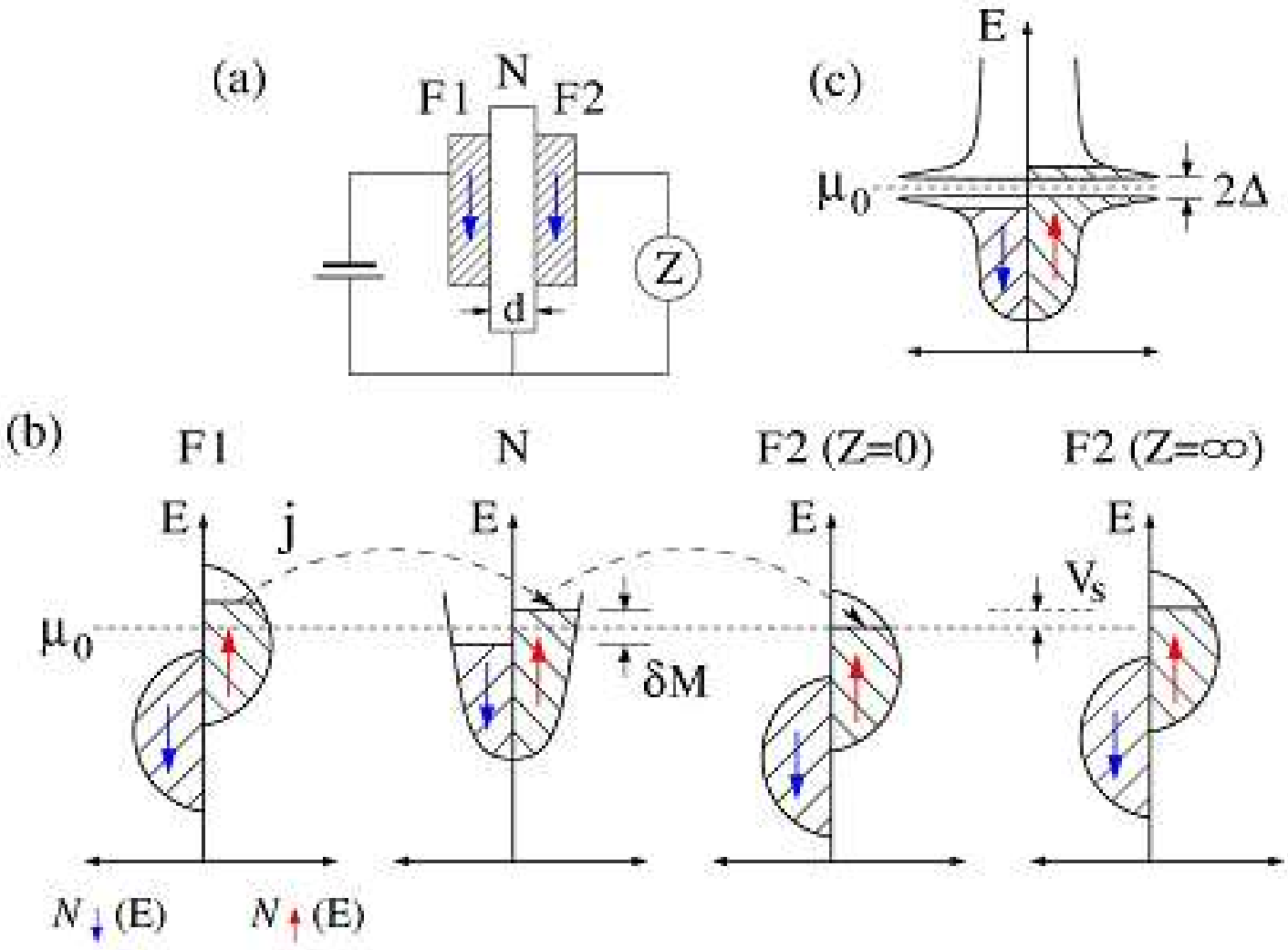




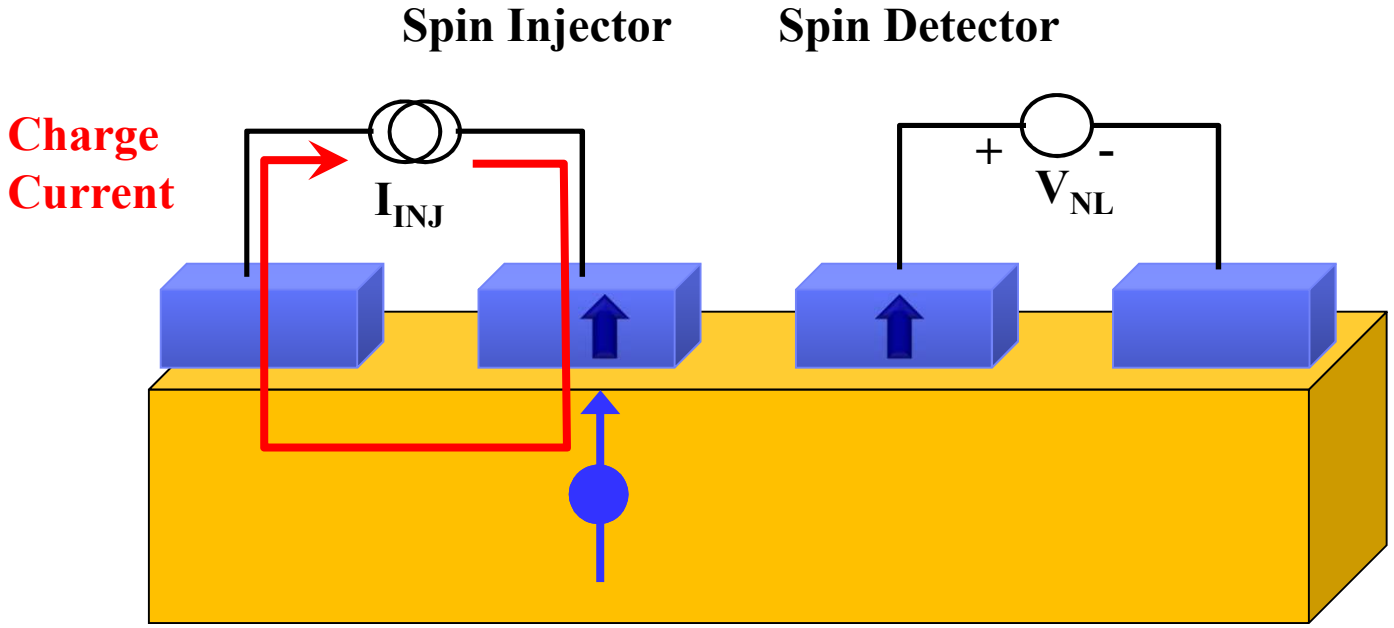


Lou, et al, Nature Physics (2007)

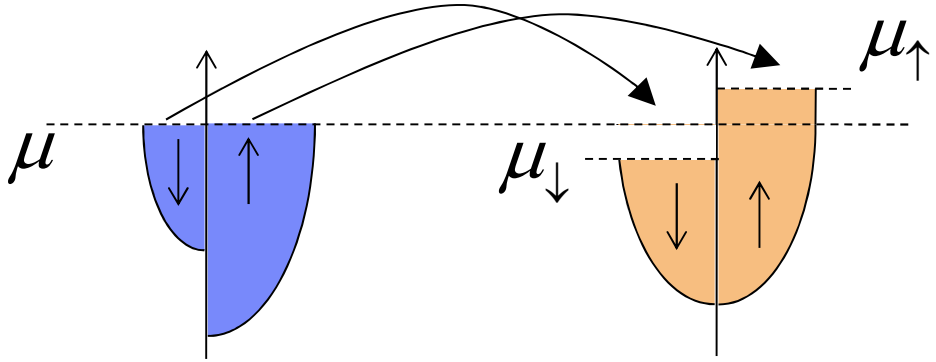
Electrical Spin detection



Nonlocal Spin valve

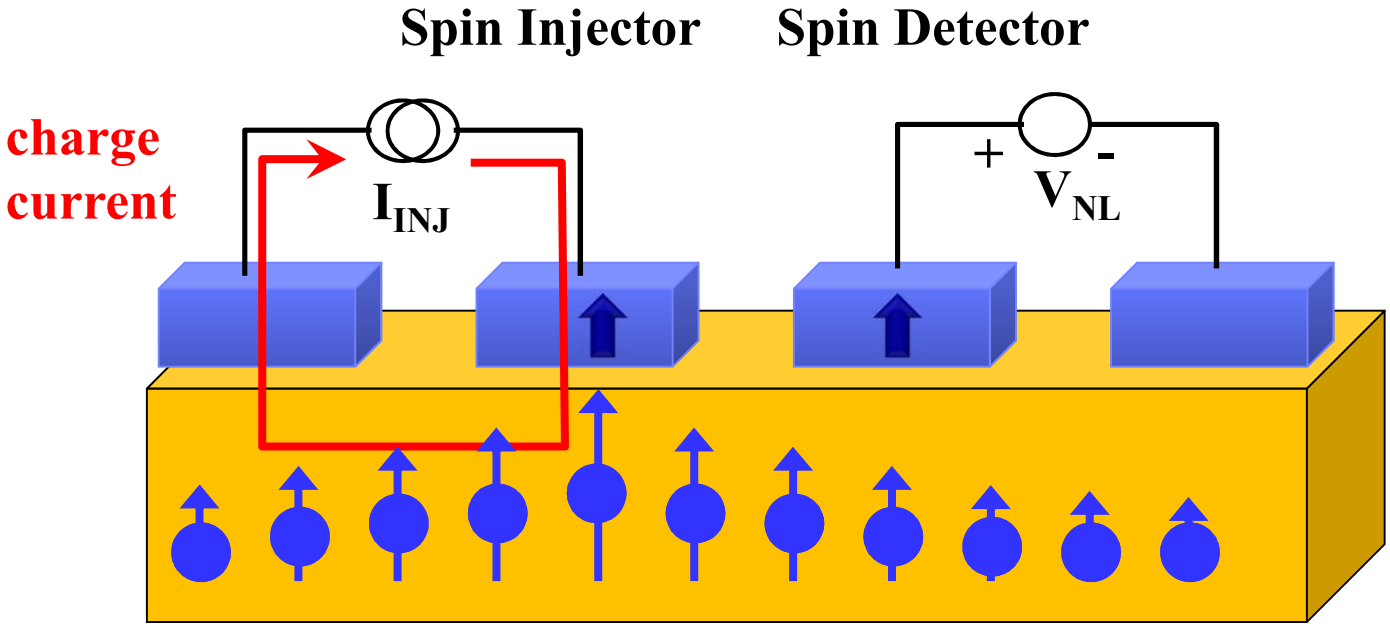


Chemical Potential (Fermi level)

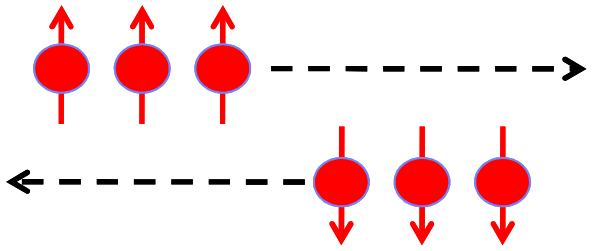


Johnson and Silsbee, PRL (1985)

Nonlocal Spin valve

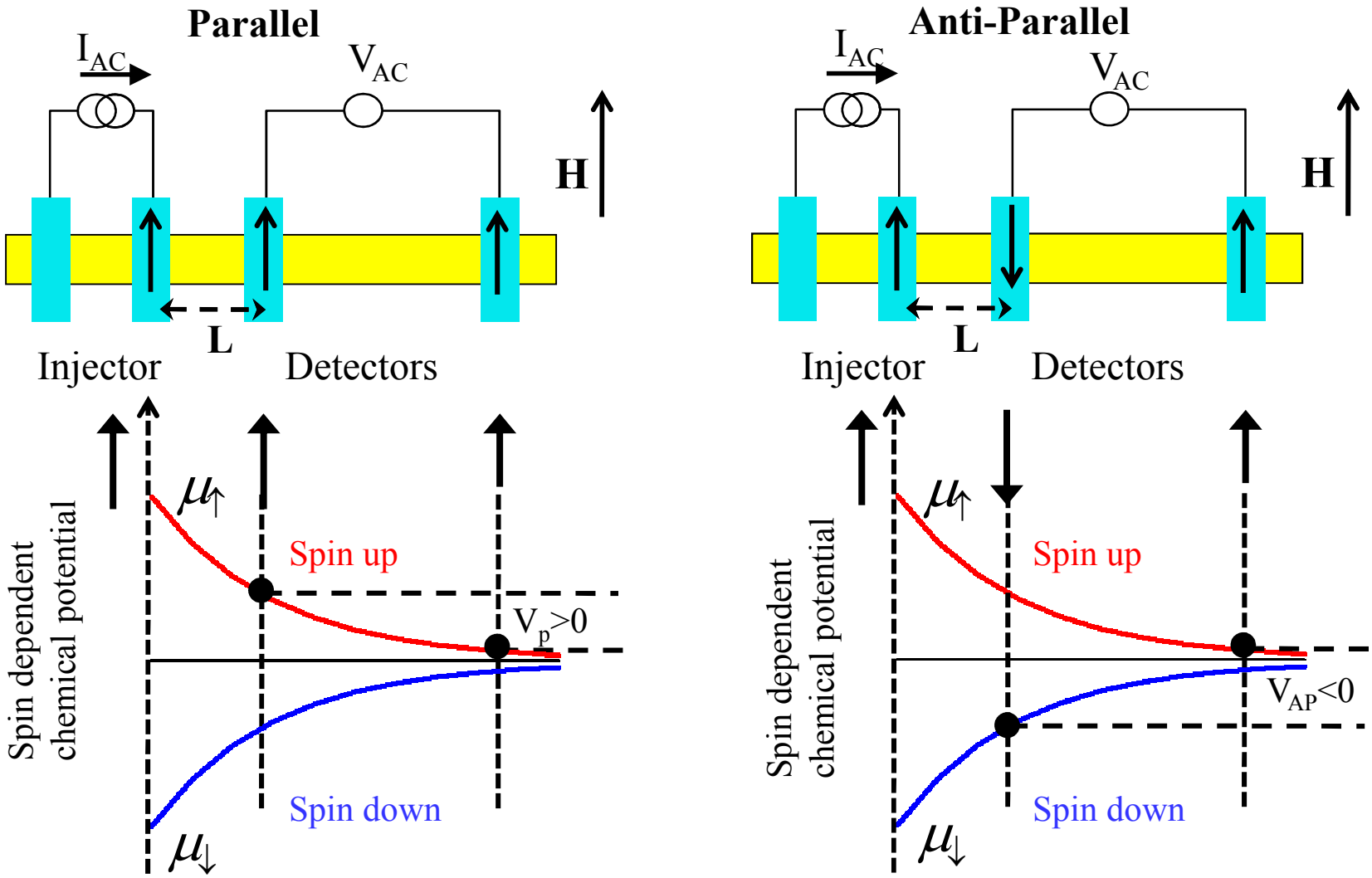


Pure spin current: Flow of spin without net flow of charge



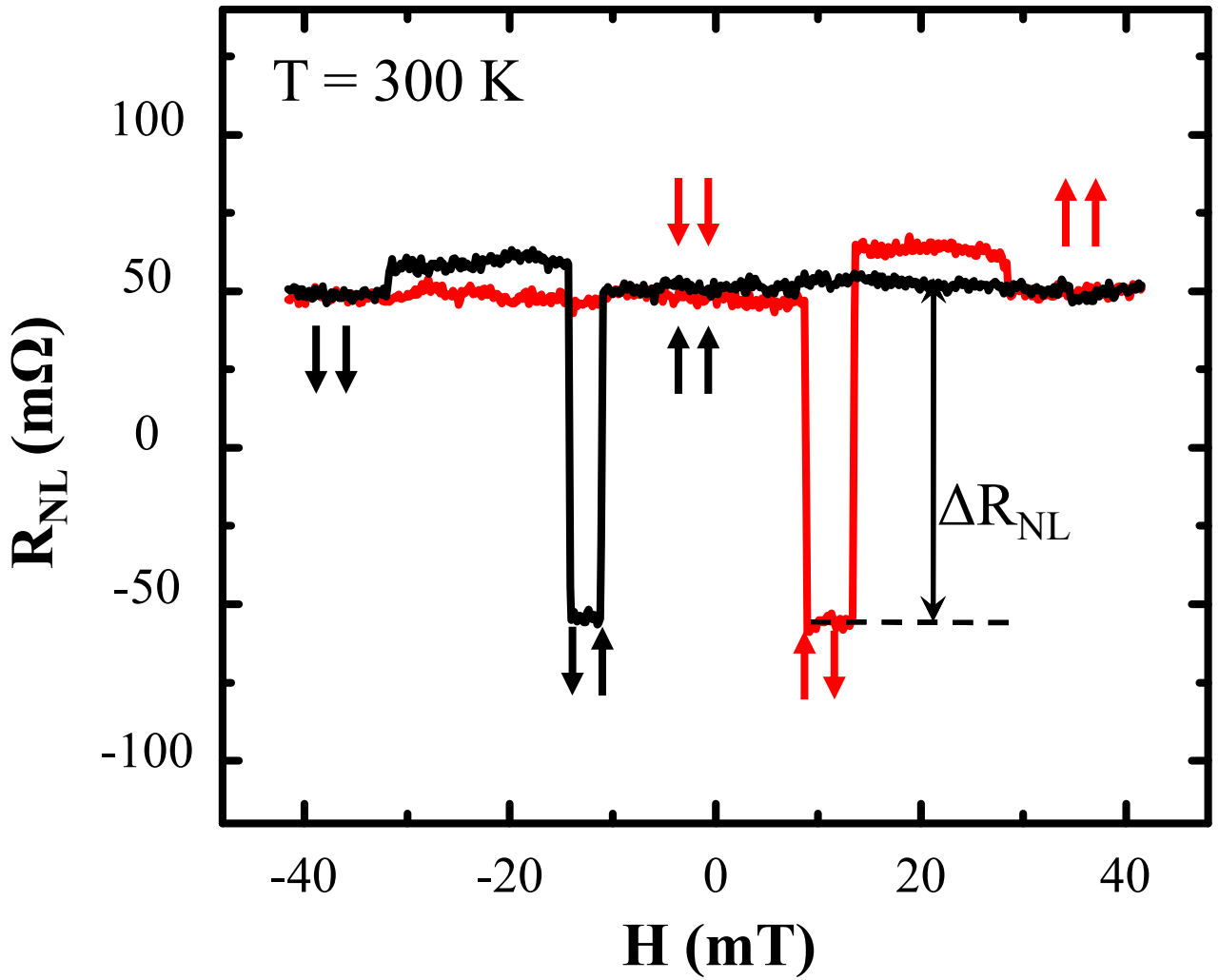
Johnson and Silsbee, PRL (1985)

Nonlocal Spin valve



Nonlocal MR = $(V_P - V_{AP})/I_{INJ}$

Nonlocal Spin valve



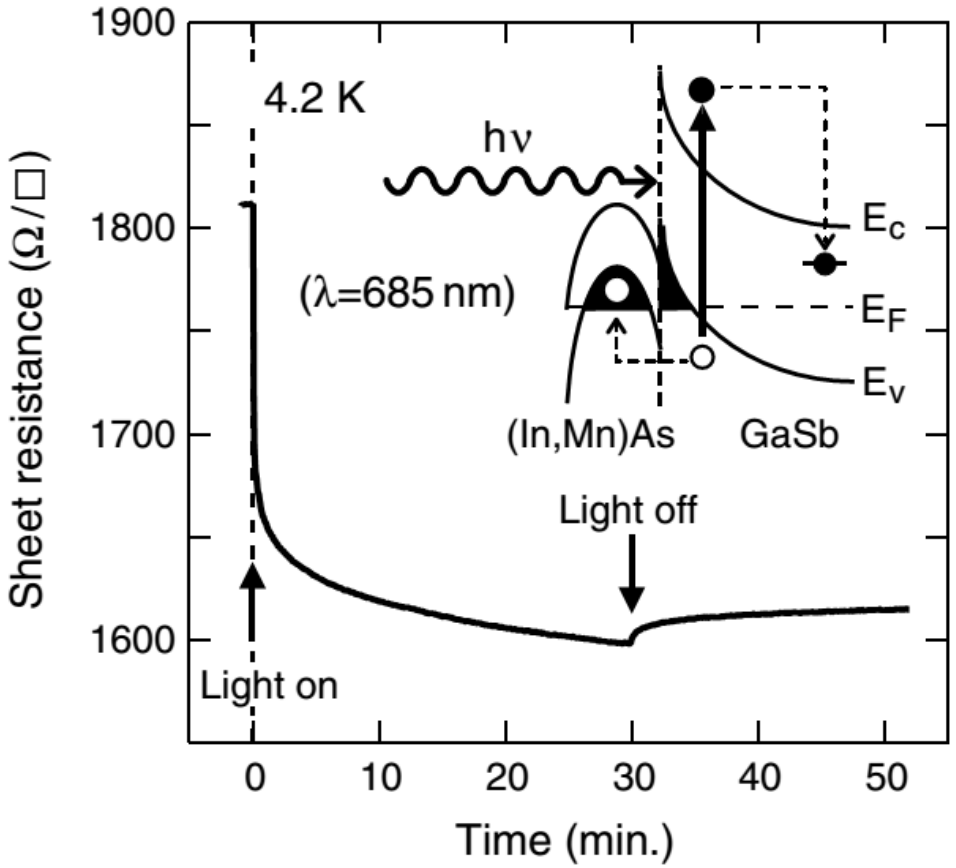
Han, et al, APL (2009)

3. Spin injection

- **Optical**

Optical spin injection

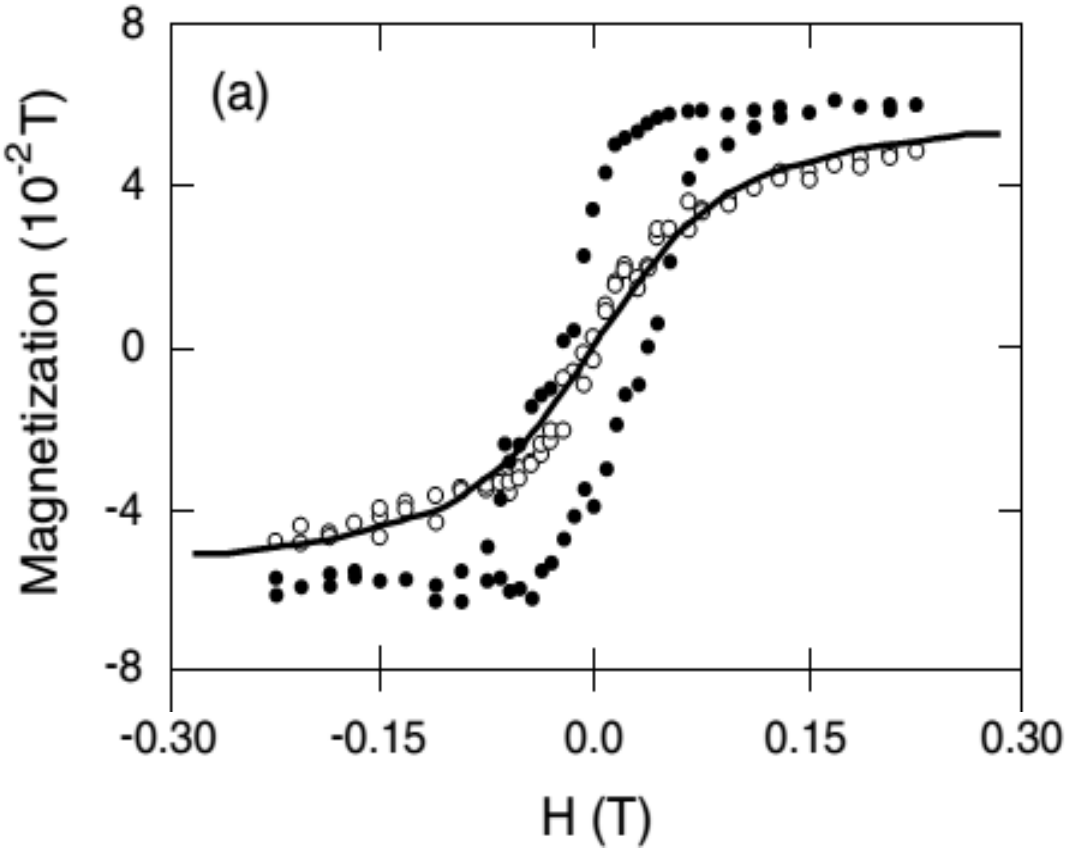
GaMnAs

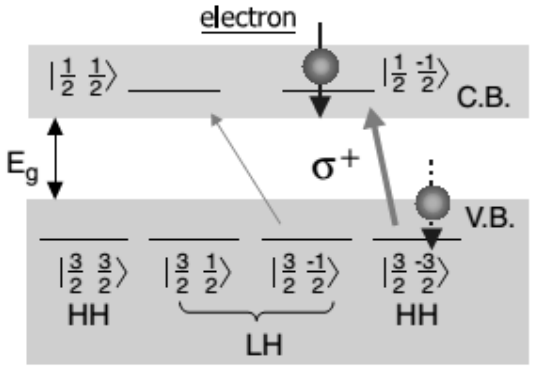


Maekawa, Book Concepts in Spin electronics (2006)

Optical spin injection

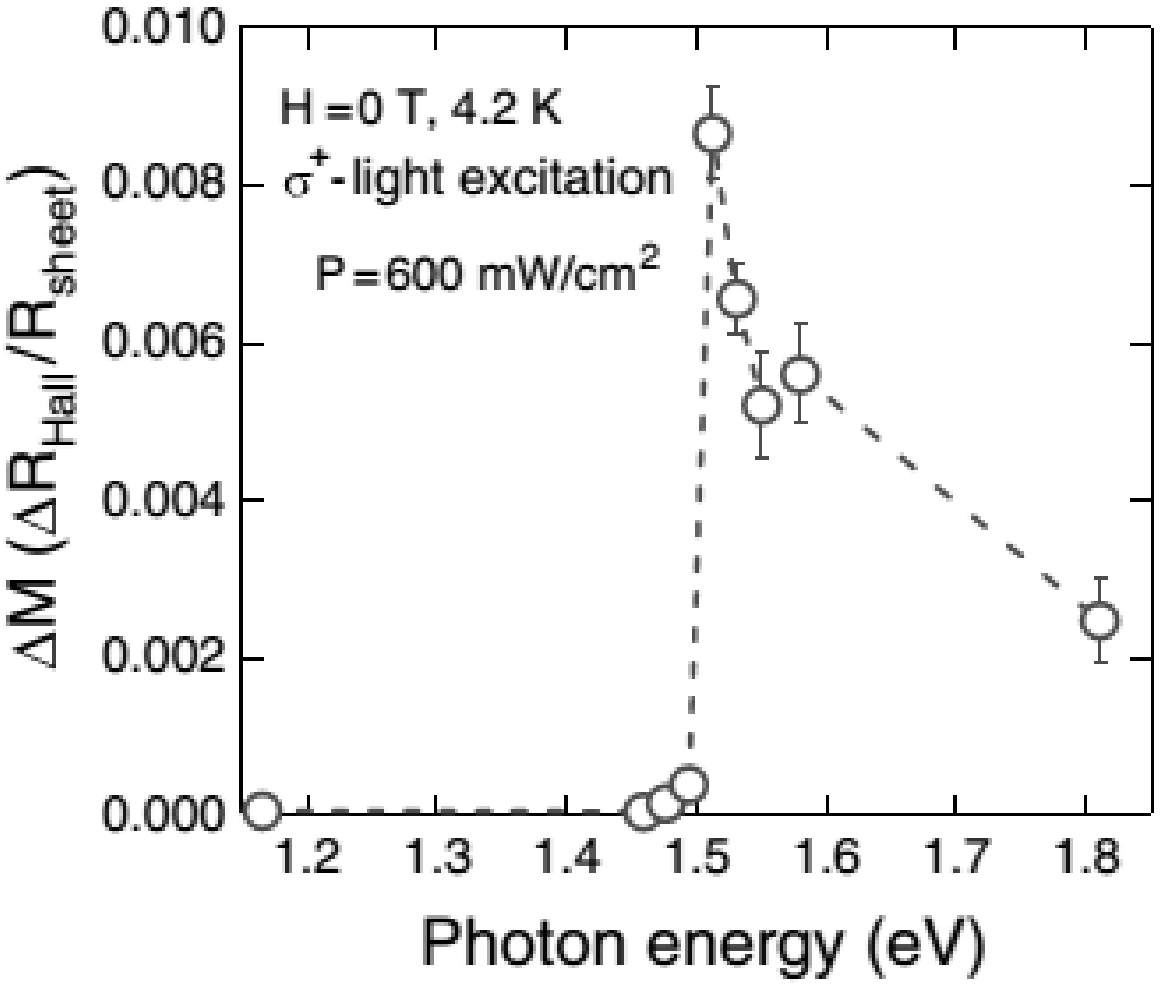
GaMnAs



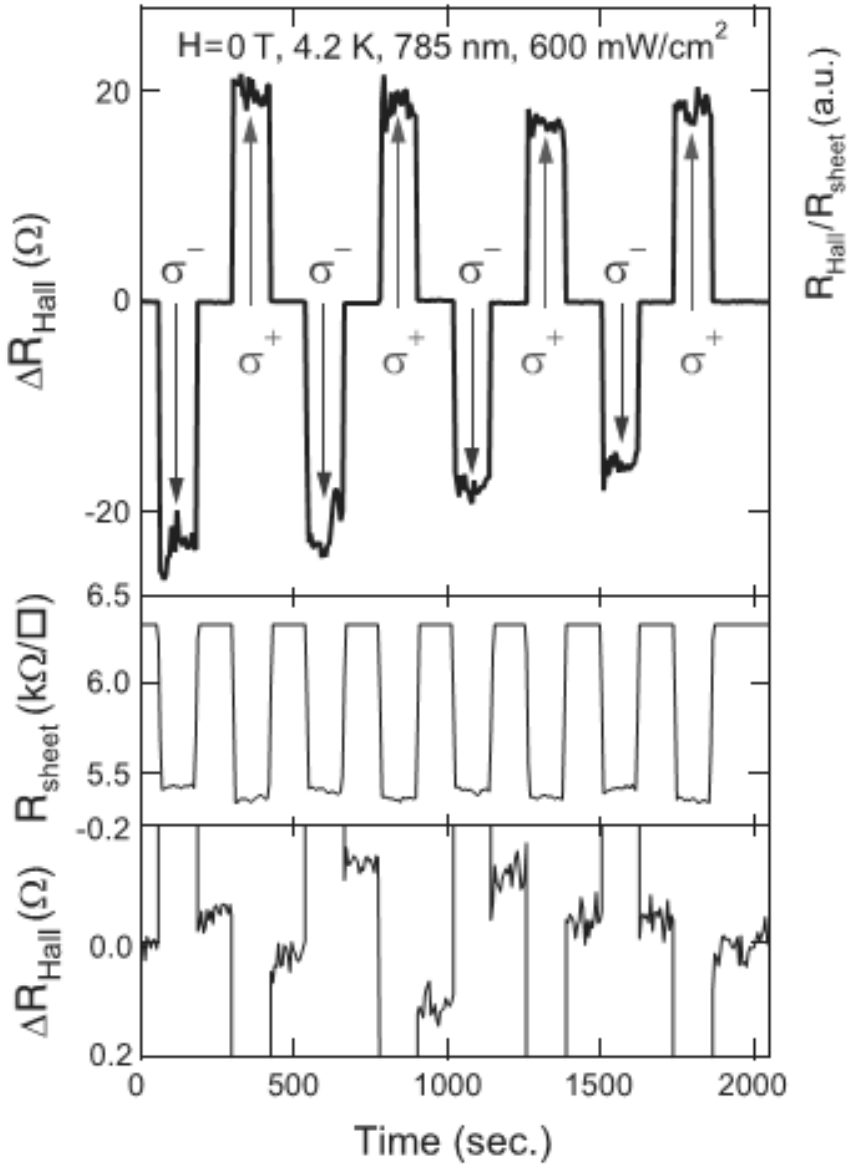


Optical spin injection

GaMnAs



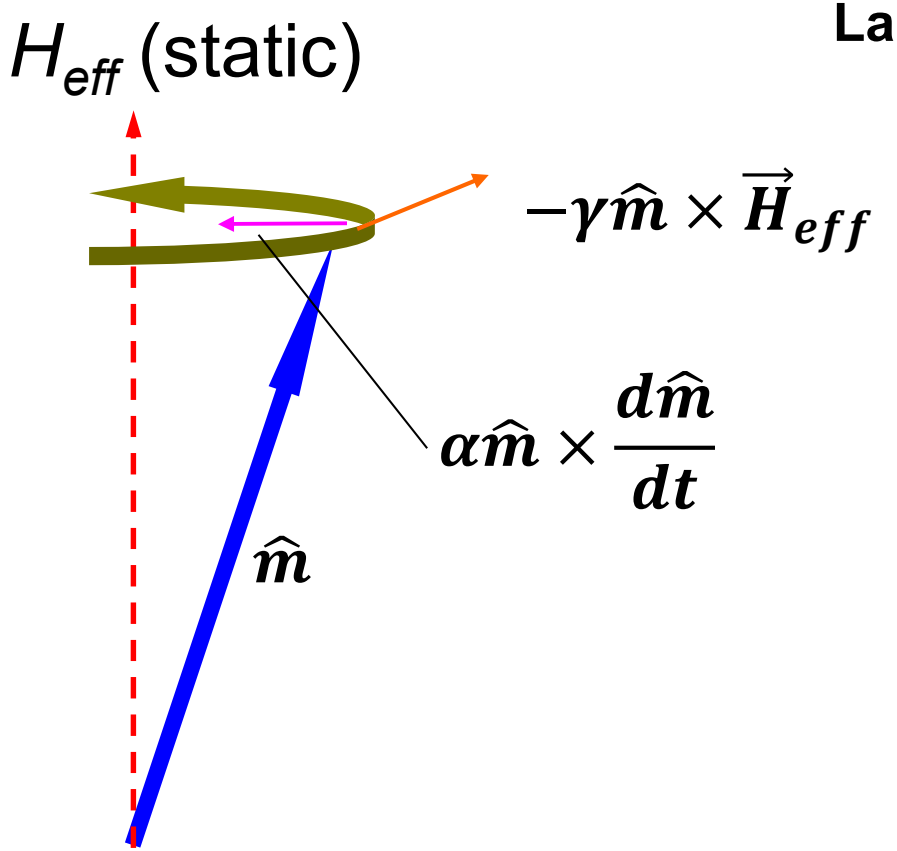
Optical spin injection



3. Spin injection

- **Dynamical**

Magnetic resonance



Landau-Lifshitz-Gilbert equation

$$\frac{d\hat{m}}{dt} = -\gamma\hat{m} \times \vec{H}_{eff} + \alpha\hat{m} \times \frac{d\hat{m}}{dt}$$

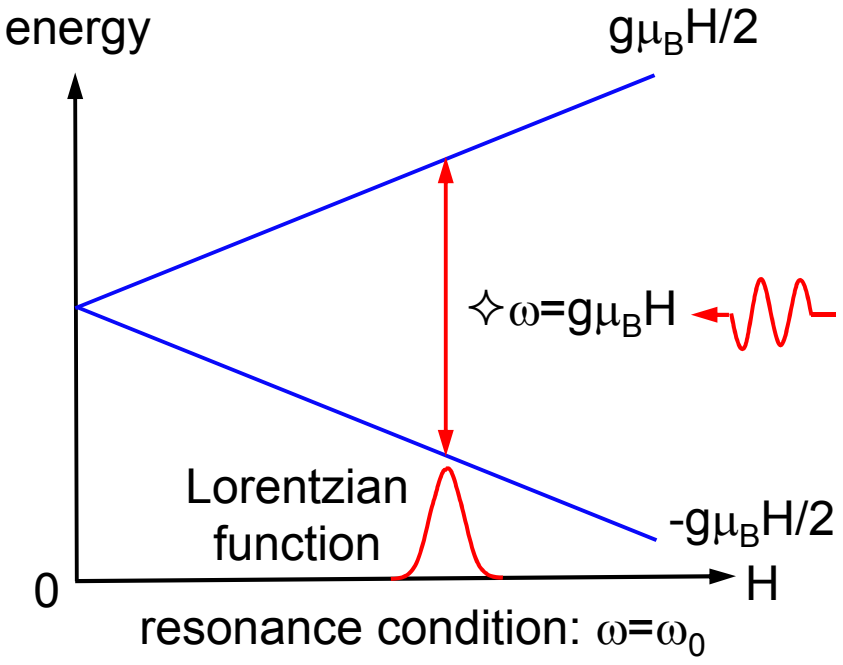
$\gamma = \frac{g\,e}{2\,m_e c}$ is gyromagnetic ratio

α is the Gilbert damping

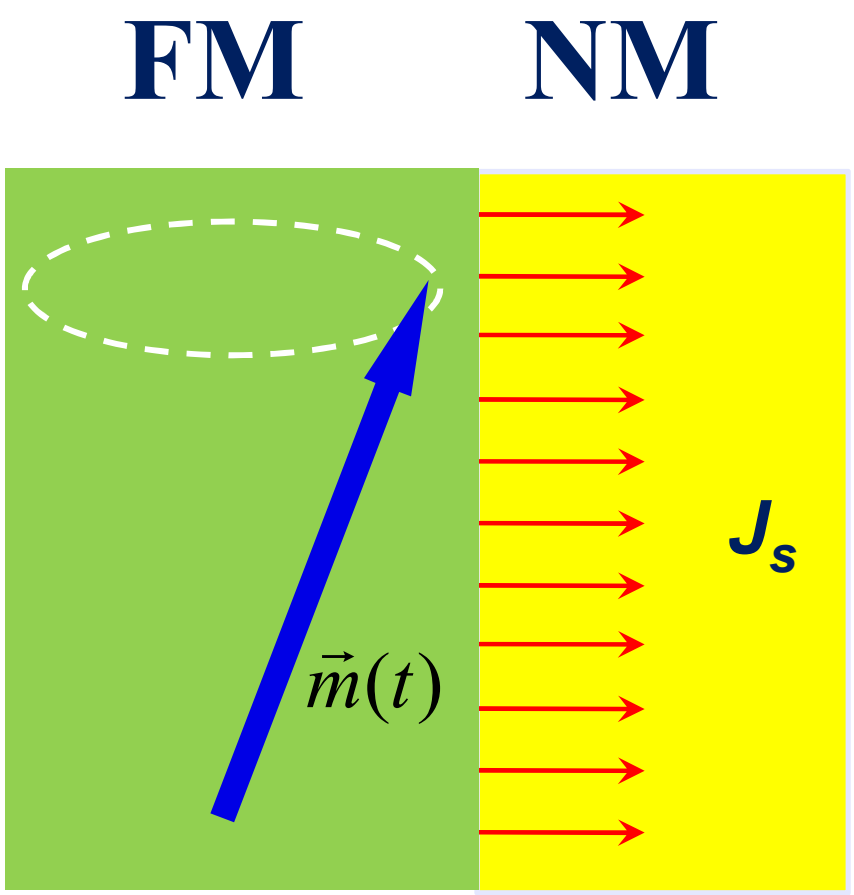
$H_x\, e^{i\omega t}$ (rf): small perturbation

Magnetic resonance

FMR



Dynamical Spin injection



$$\vec{J}_S = \frac{\hbar g_r^{\uparrow\downarrow}}{4\pi M^2}\left(\vec{M} \times \frac{\partial \vec{M}}{\partial t}\right)$$

Precessing magnetization in FM layer pump spin current into NM layer (Angular momentum conservatoin)

Dynamical Spin injection

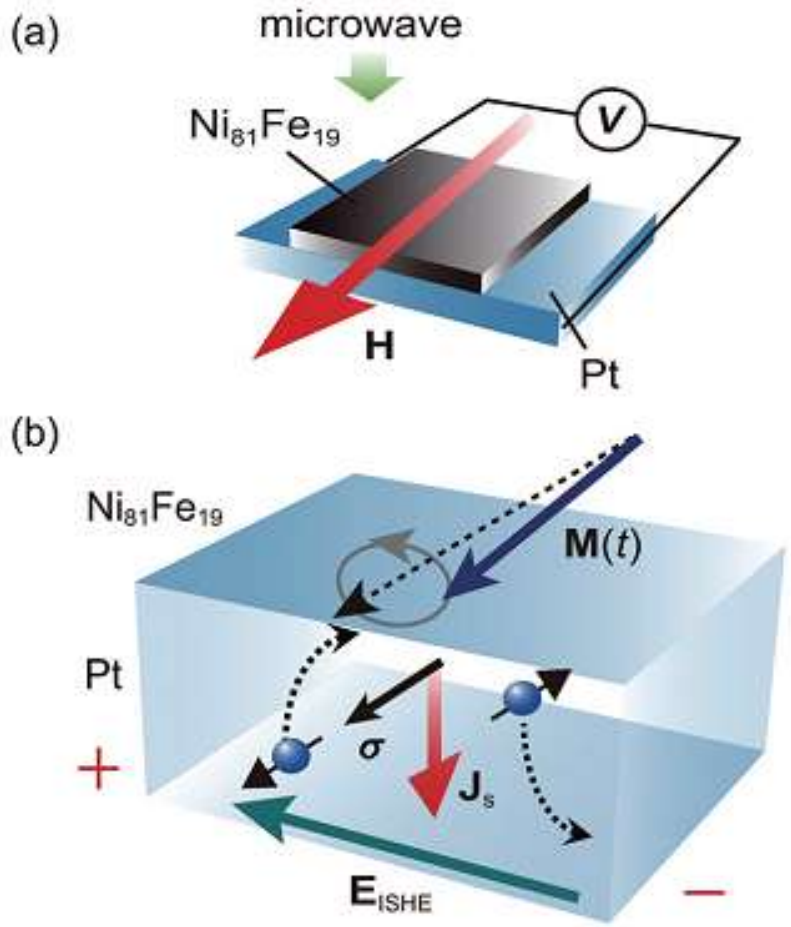
$$\frac{d\mathbf{M}(t)}{dt} = -\gamma \mathbf{M}(t) \times \mathbf{H}_{\text{eff}} + \frac{\alpha}{M_s} \mathbf{M}(t) \times \frac{d\mathbf{M}(t)}{dt}.$$

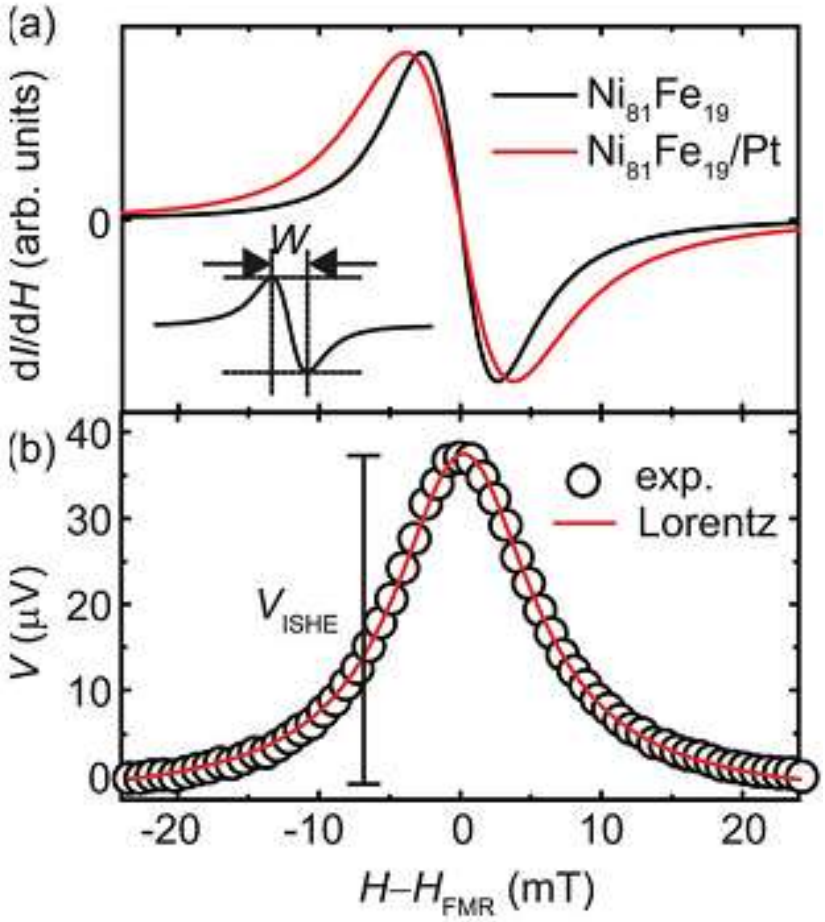
$$\boldsymbol{\tau} = -\,\mathbf{m} \times \mathbf{I}_s \times \mathbf{m}.$$

$$\mathbf{I}_{s,R}^{\text{pump}} = \frac{\hbar}{4\pi}\left(\mathcal{A}_r^{\uparrow\downarrow} \mathbf{m} \times \frac{d\mathbf{m}}{dt} + \mathcal{A}_i^{\uparrow\downarrow} \frac{d\mathbf{m}}{dt} \right)$$

Tserkovnyak, et al, RMP (2005)

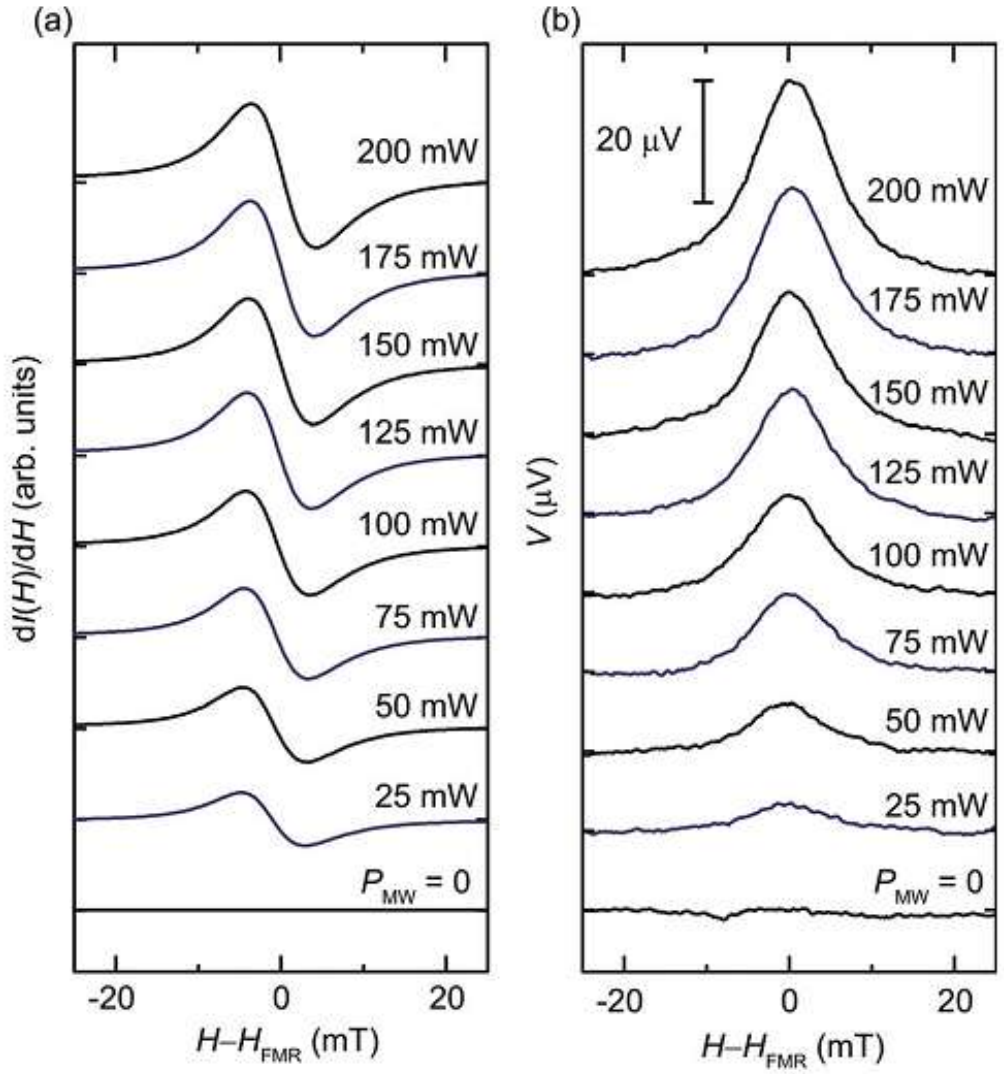
Dynamical Spin injection

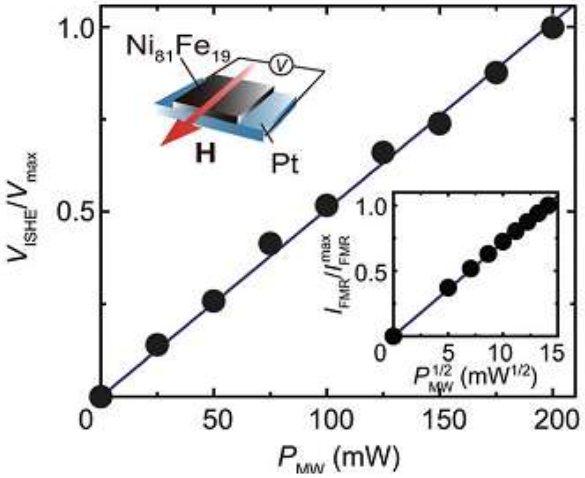




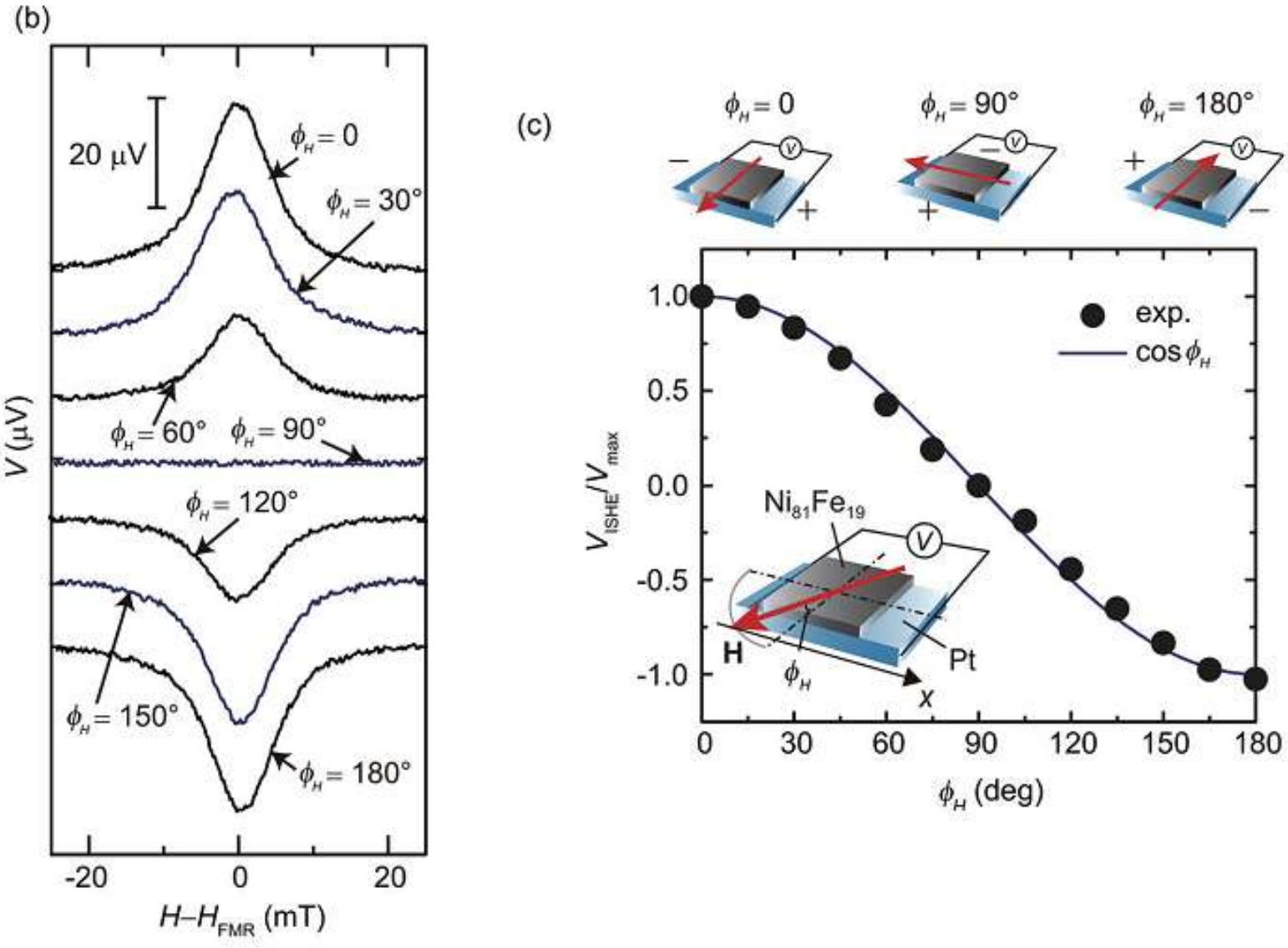
Ando, et al, JAP (2011)

Dynamical Spin injection

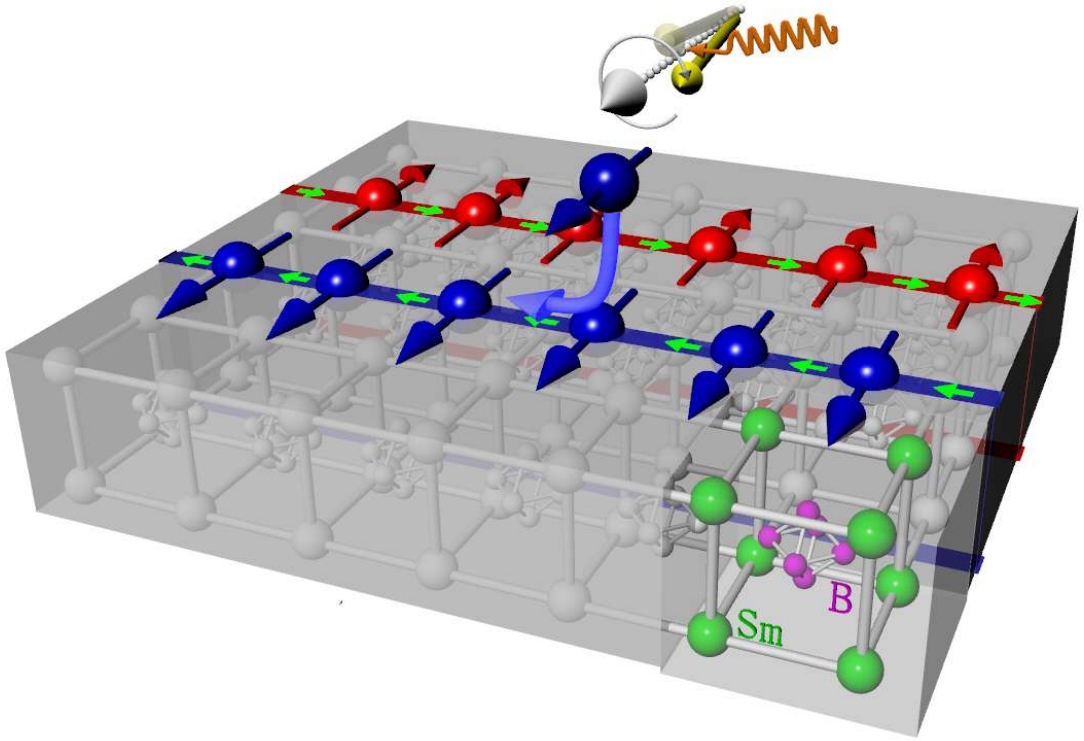


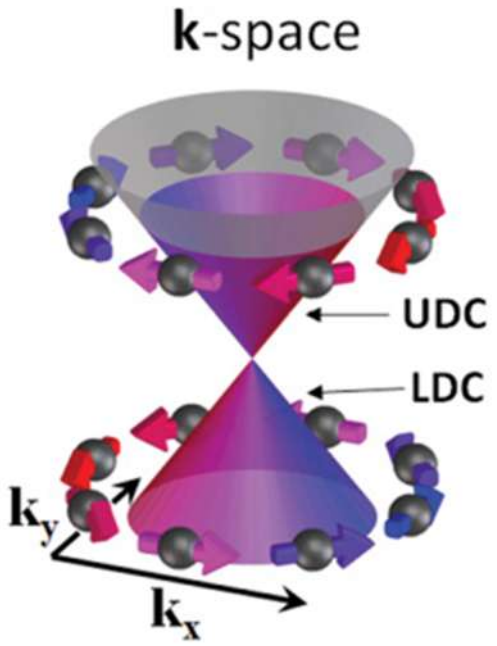


Dynamical Spin injection



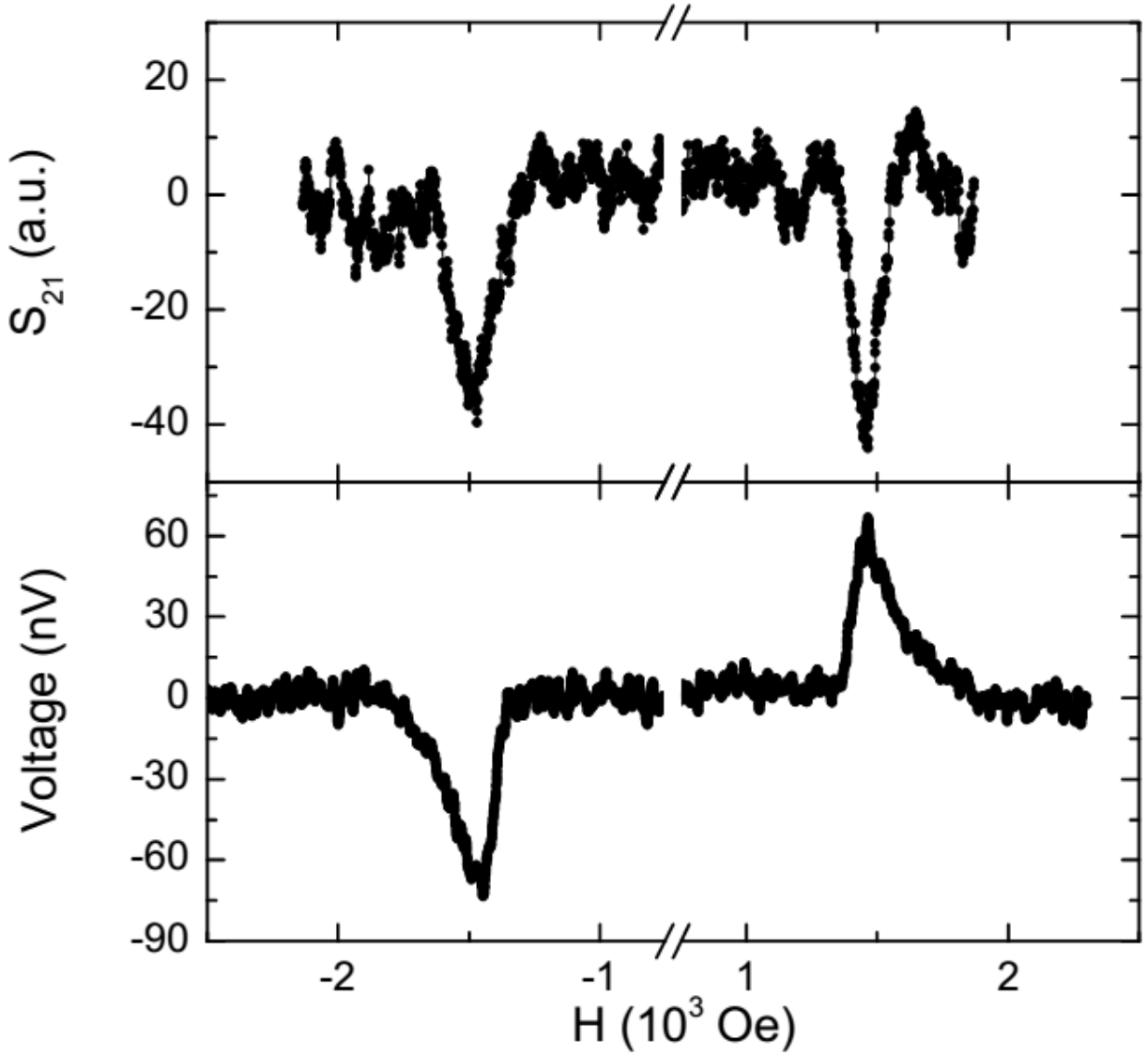
Dynamical Spin injection



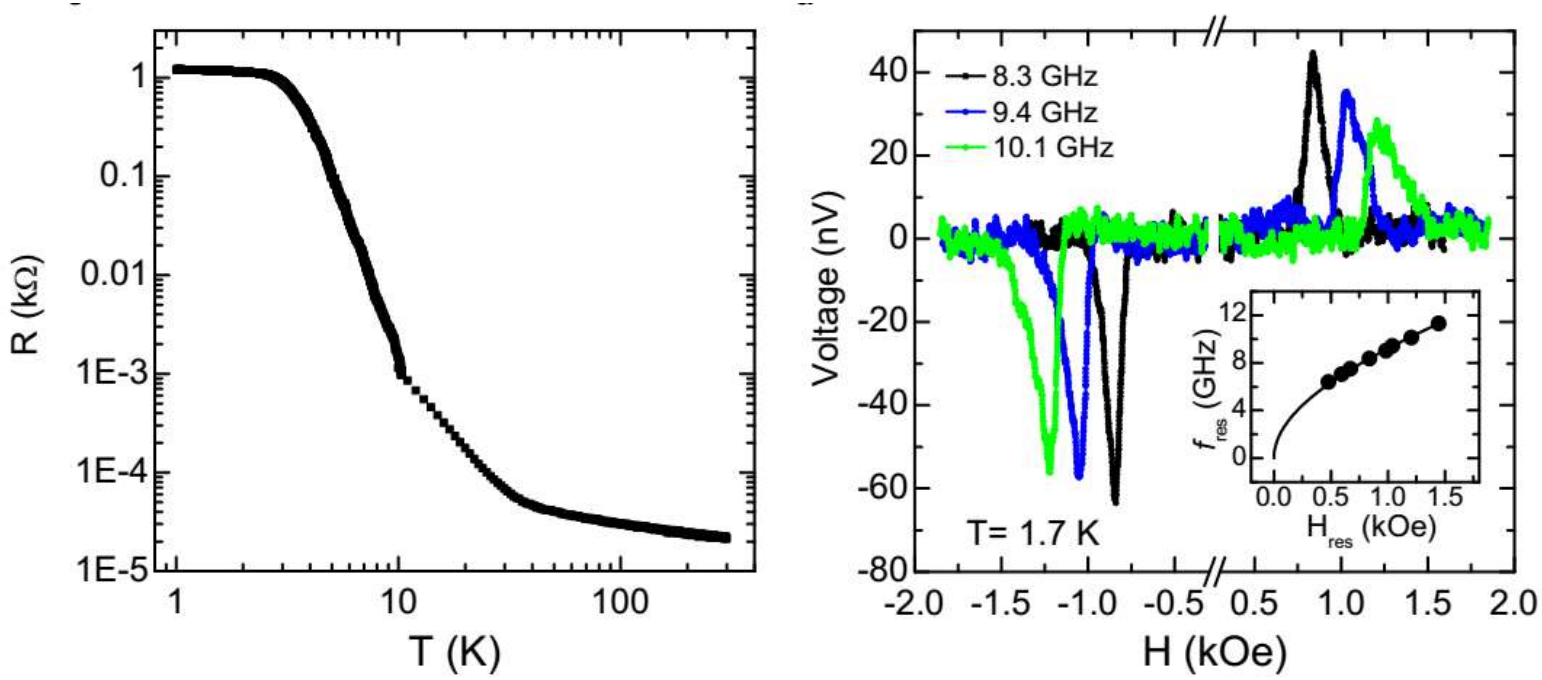


Spin-Momentum Locking

Dynamical Spin injection

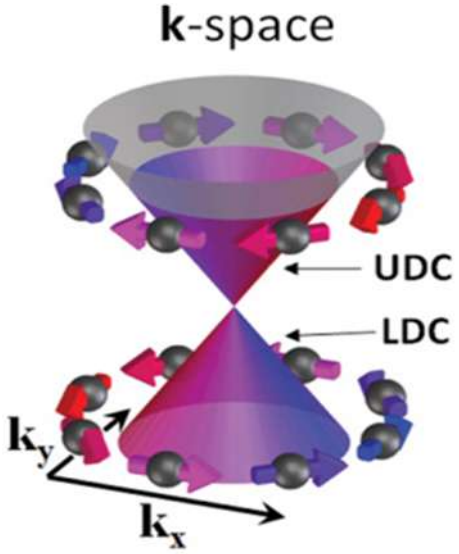


Dynamical Spin injection

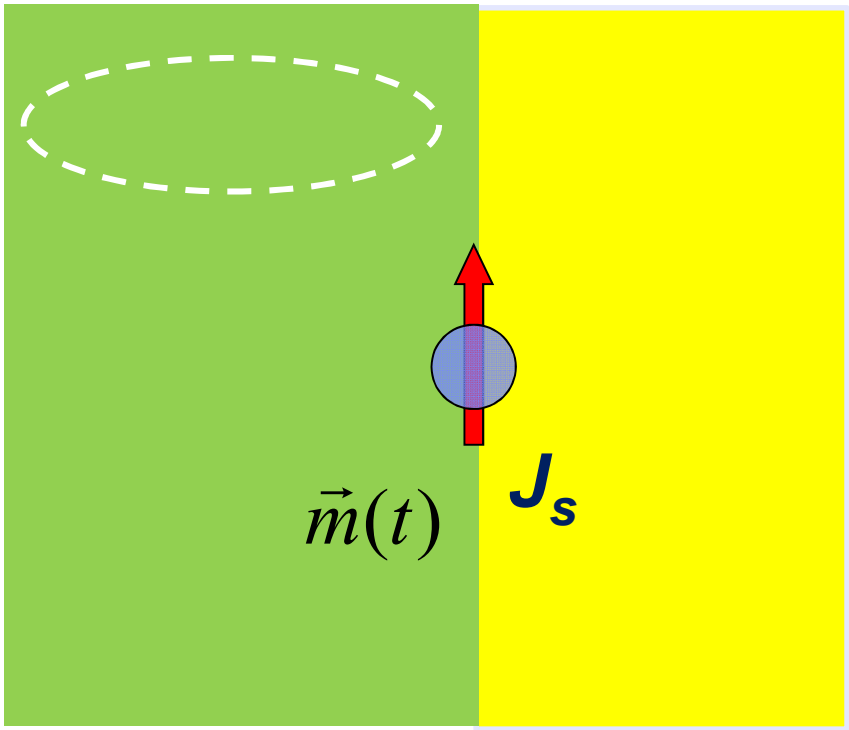


Song, et al, Nature Communications (2016)

Spin pumping efficiency

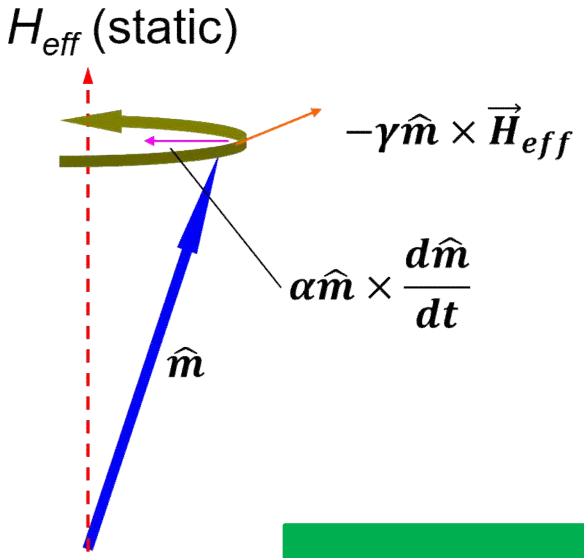


$$\vec{J}_S = \frac{\hbar g_r^{\uparrow\downarrow}}{4\pi M^2}\left(\vec{M}\times\frac{\partial\vec{M}}{\partial t}\right)$$



Enhanced Gilbert Damping

Spin pumping efficiency



α : Gilbert Damping

Film Quality

Capping Layer

Gilbert Damping

Surface Roughness

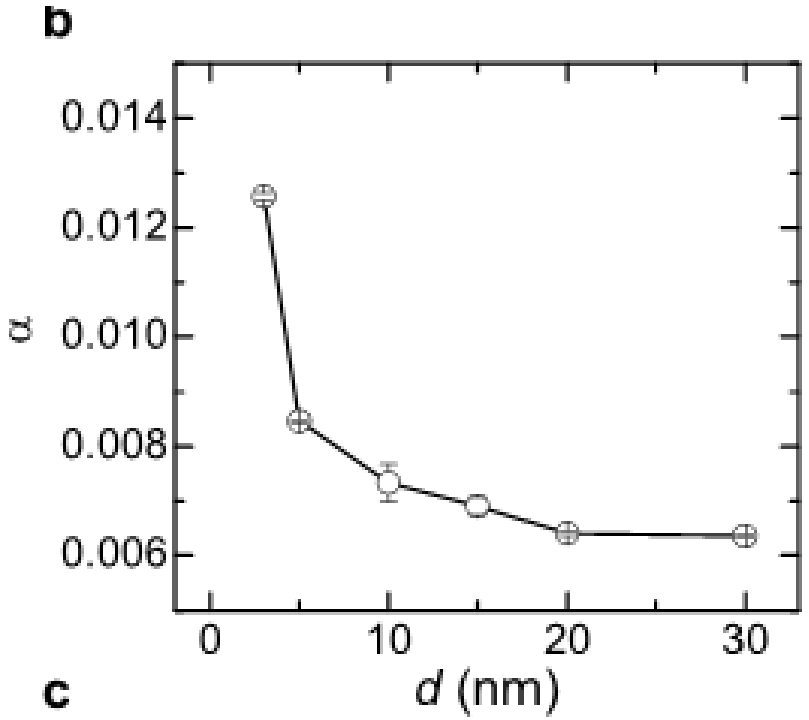
Spin Pumping

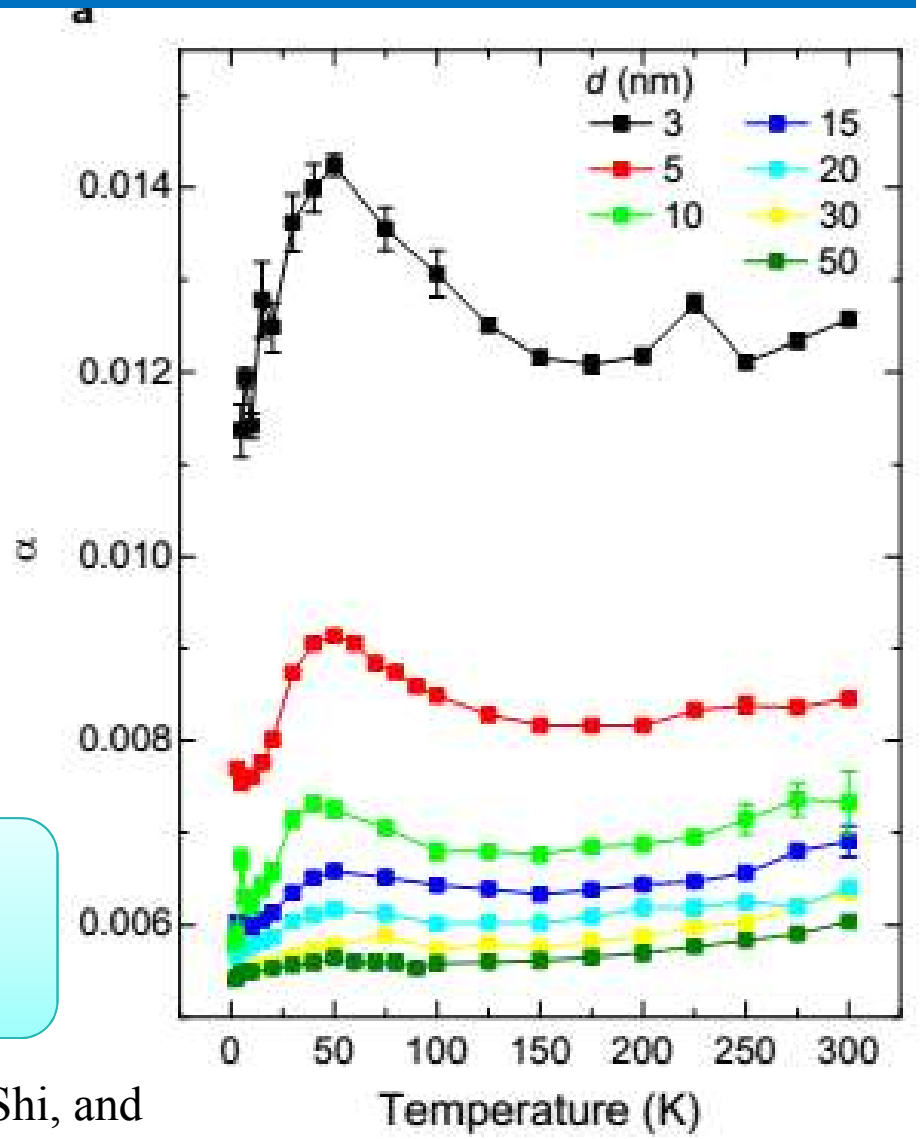
Substrate

Thickness

Spin pumping efficiency

Si-SiO_2/Py/TaN or Al_2O_3



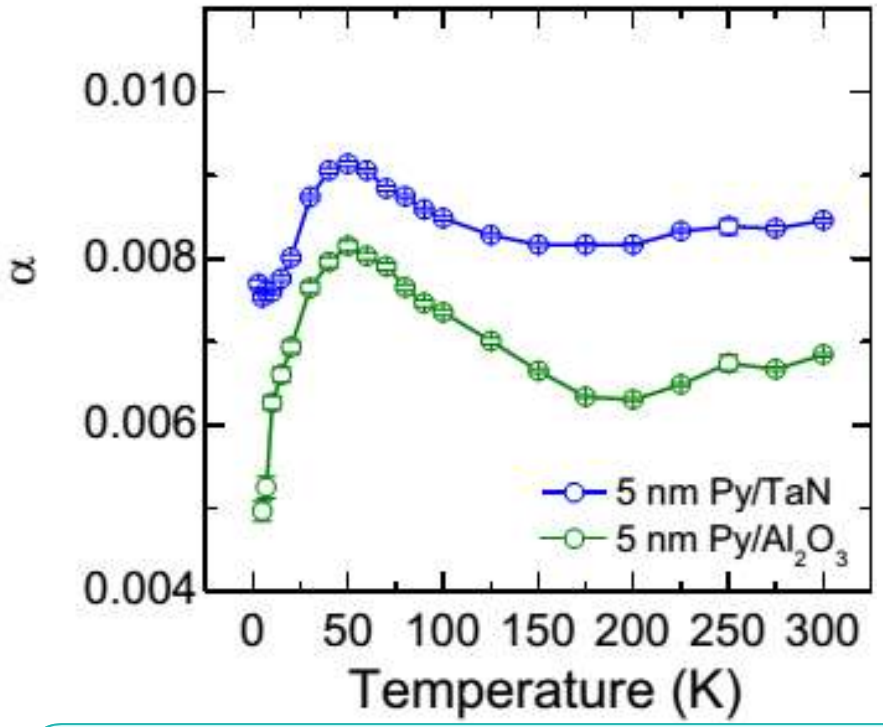


Damping affected by interface, thickness, roughness, etc

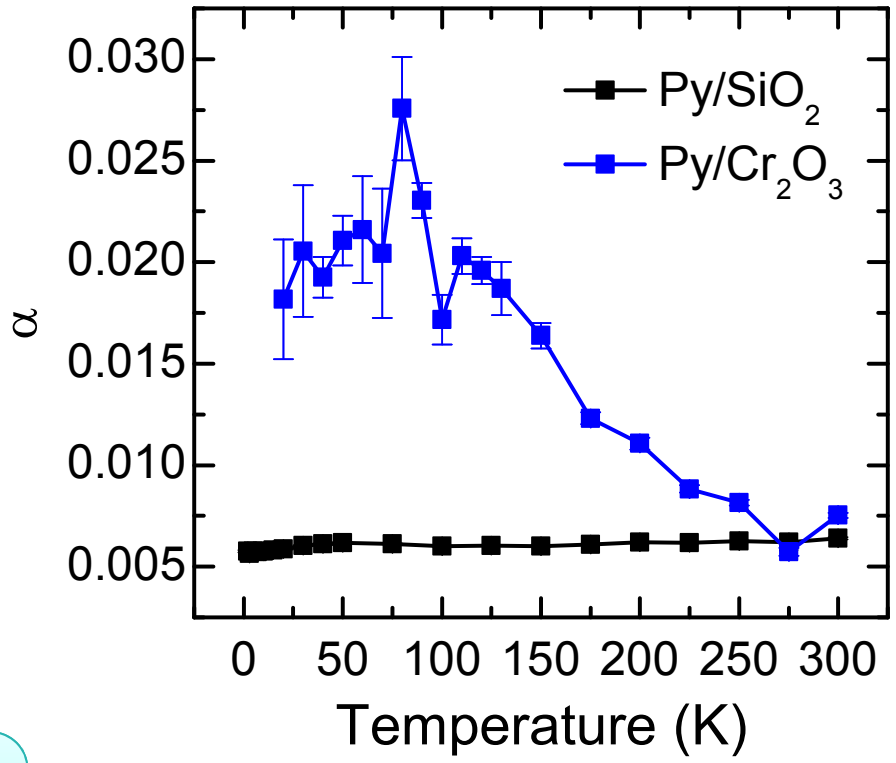
Zhao*, Song*, Yang, Su, Yuan, Parkin, Shi, and W. Han, Scientific Reports, 6:22890 (2016)

Spin pumping efficiency

Capping layer



Substrates

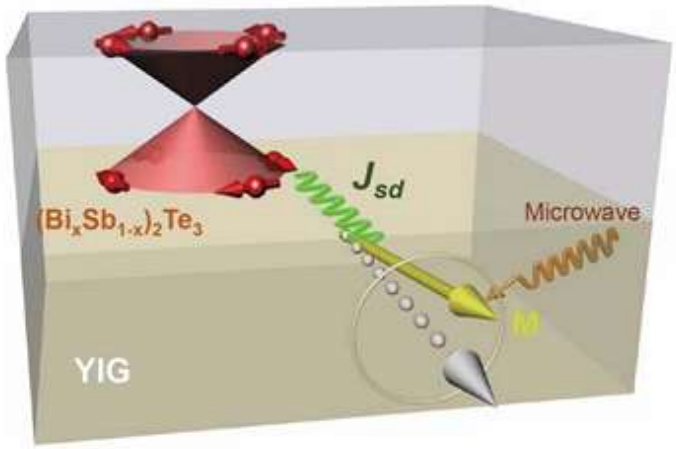


Damping affected by interface, thickness, roughness, etc

Song, et al, unpublished

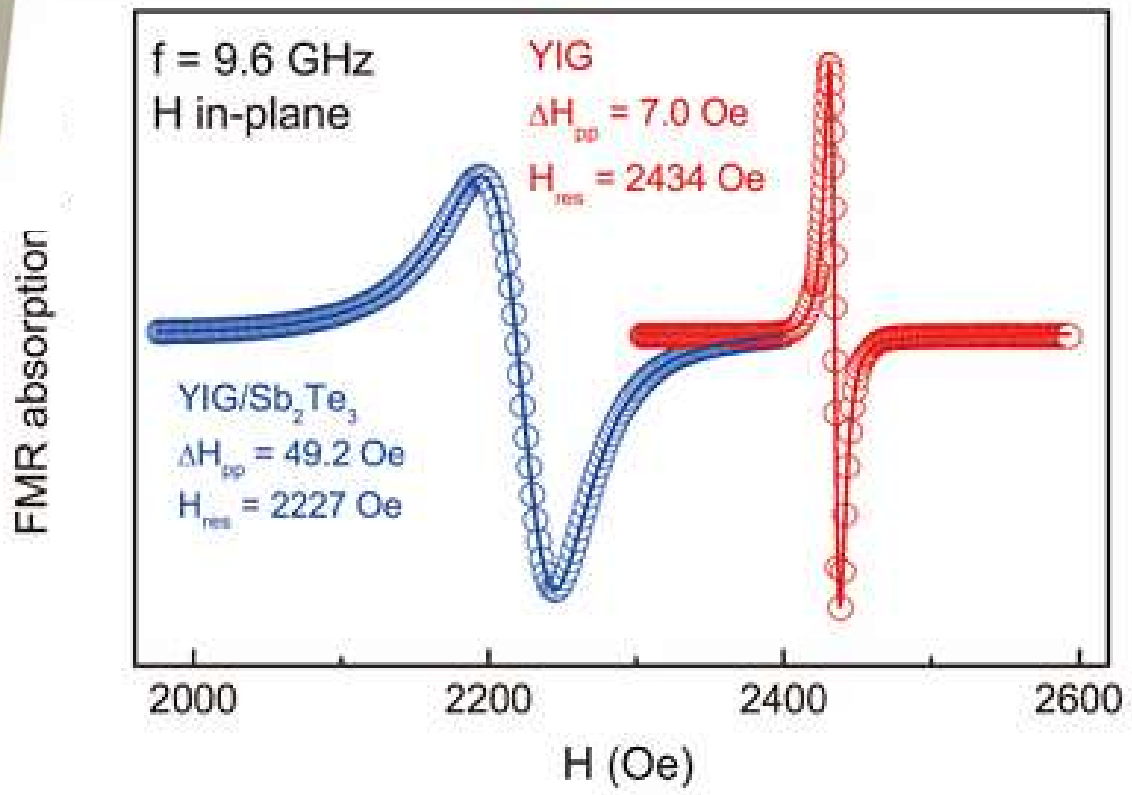
Zhao*, Song*, Yang, Su, Yuan, Parkin, Shi, and W. Han, Scientific Reports, 6:22890 (2016)

Spin pumping efficiency



$$H_{sd} = J_{sd} \sum_{i \in FM/NM\ interface} \vec{\sigma}_i \cdot \vec{s}_i$$

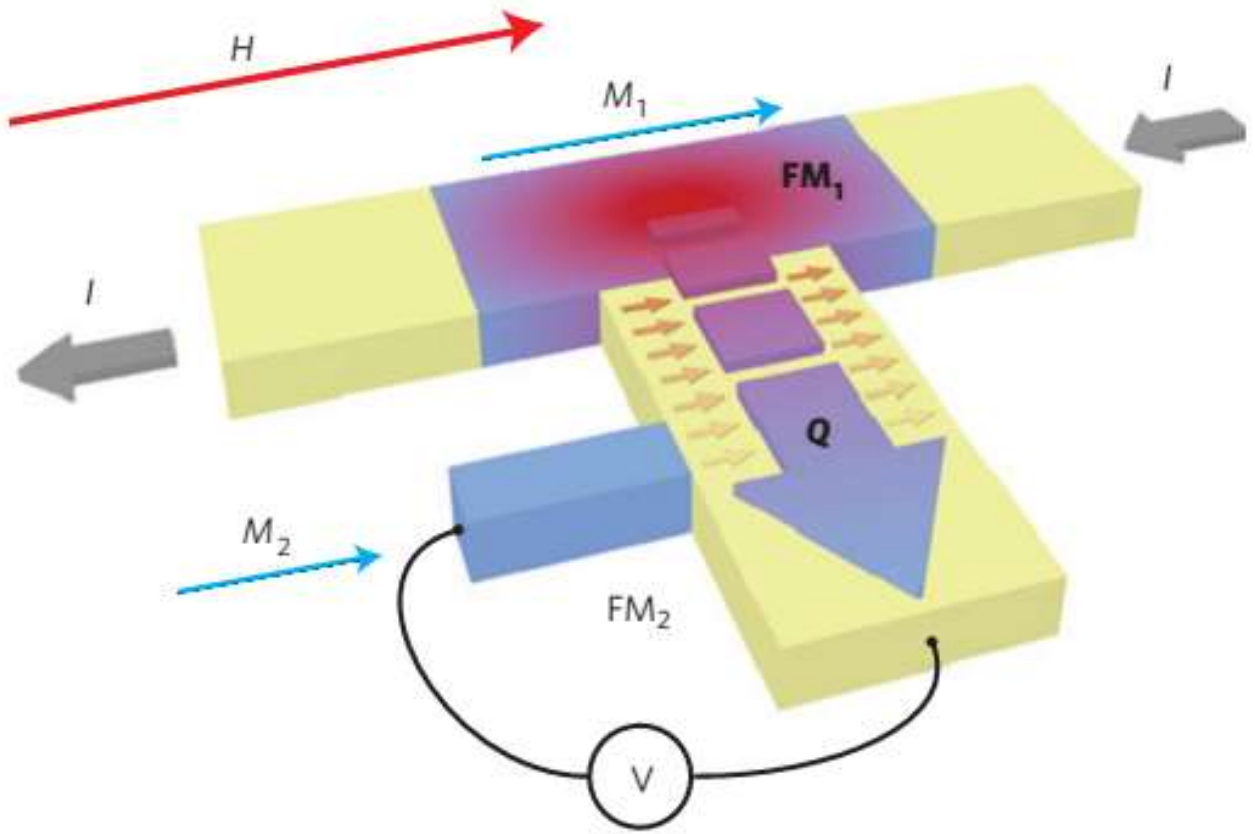
Enhanced Gilbert damping



3. Spin injection

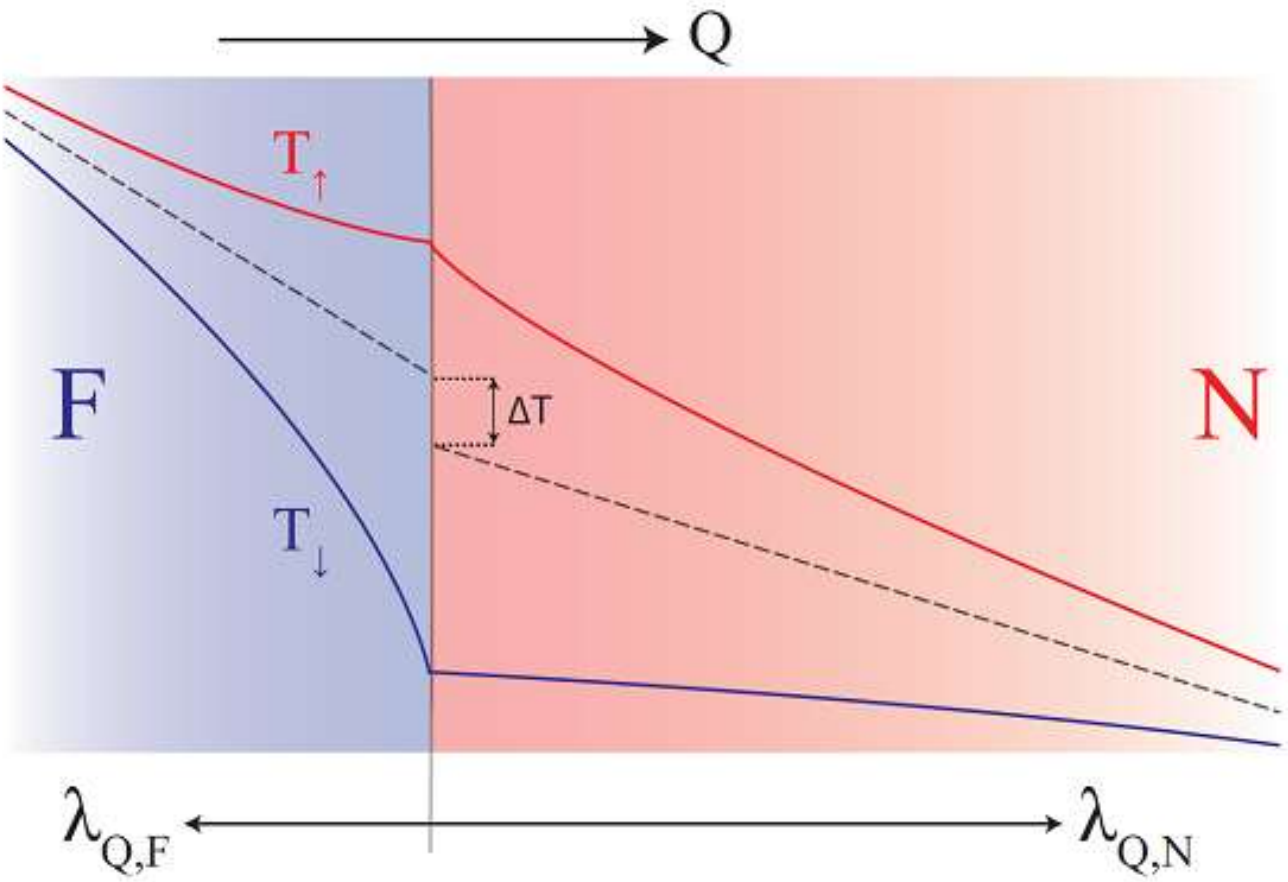
- **Thermal**

Thermal Spin Injection



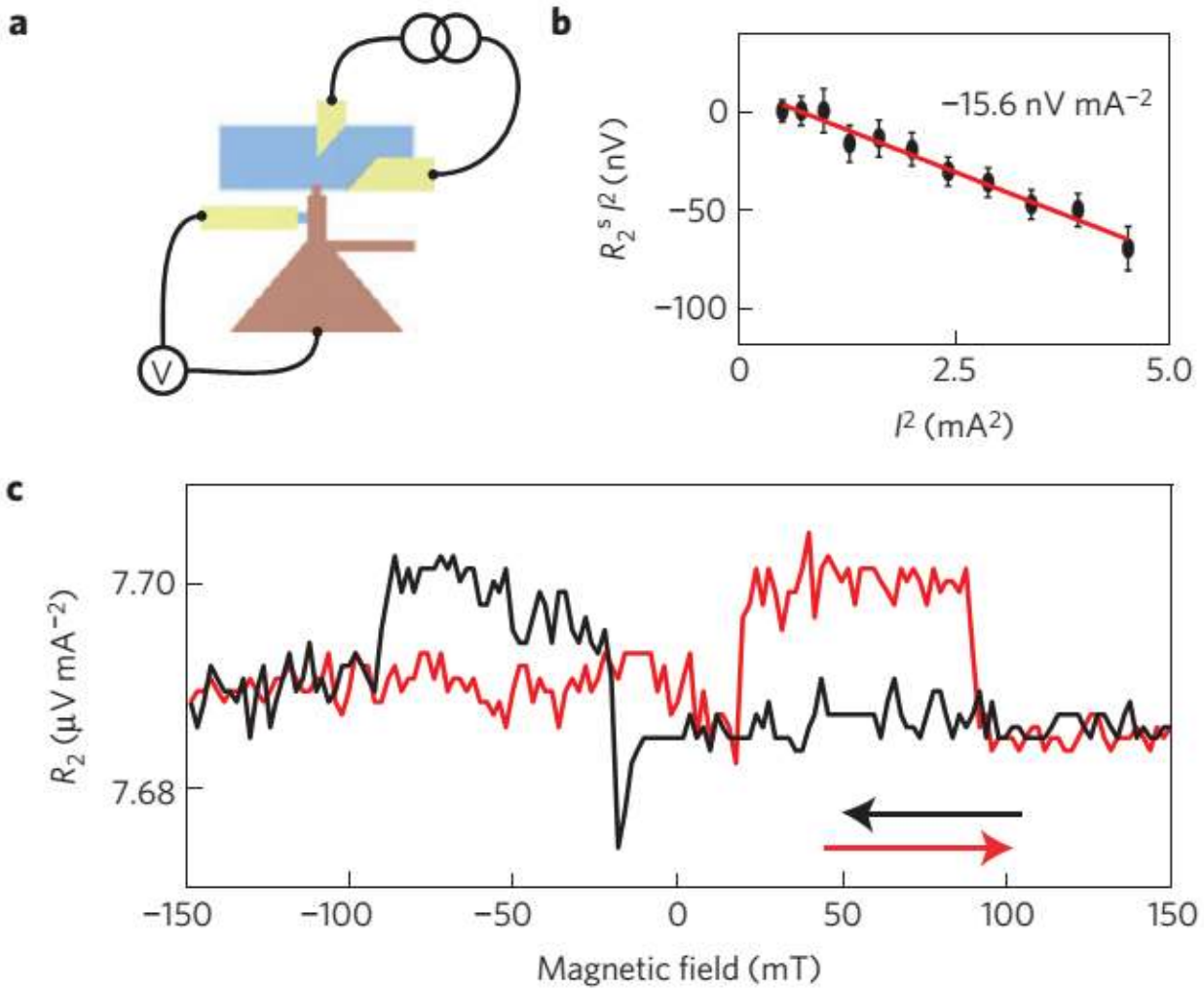
Slachter, et al, Nature Physics (2010)

Thermal Spin Injection



Thermal Spin Injection

Metal



学习了解一些自旋电子学研究进展

本课程共八章

一、自旋电子学简介

二、磁性和磁性材料

三、磁阻效应

四、自旋阀

五、自旋转移力矩

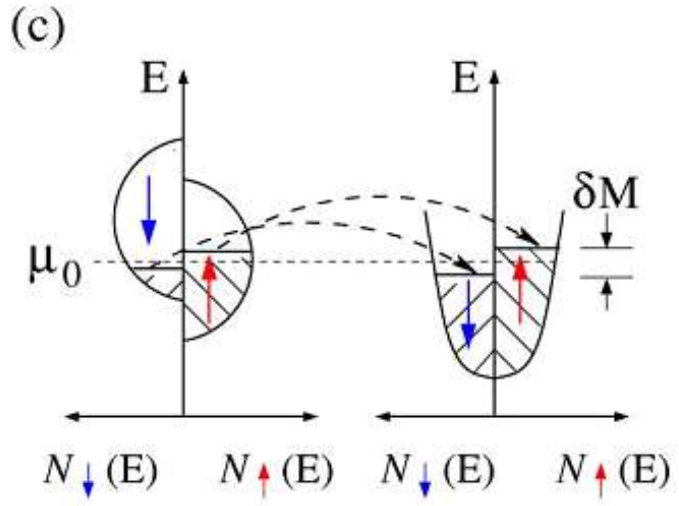
六、热自旋电子学

七、拓扑自旋流

八、反铁磁自旋电子学

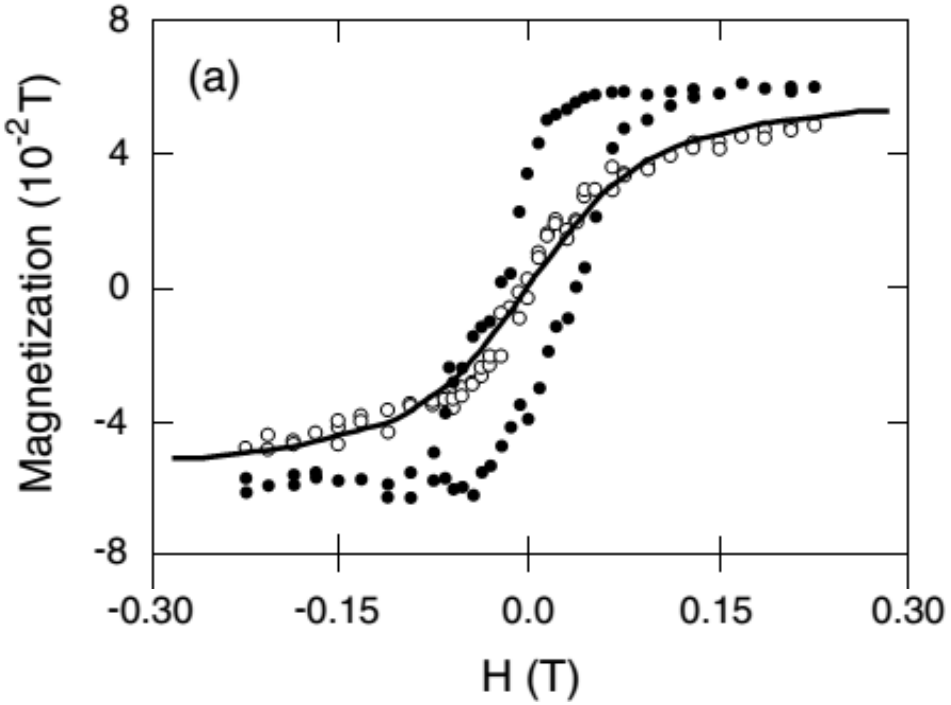
3. Spin injection

- **Electrical**



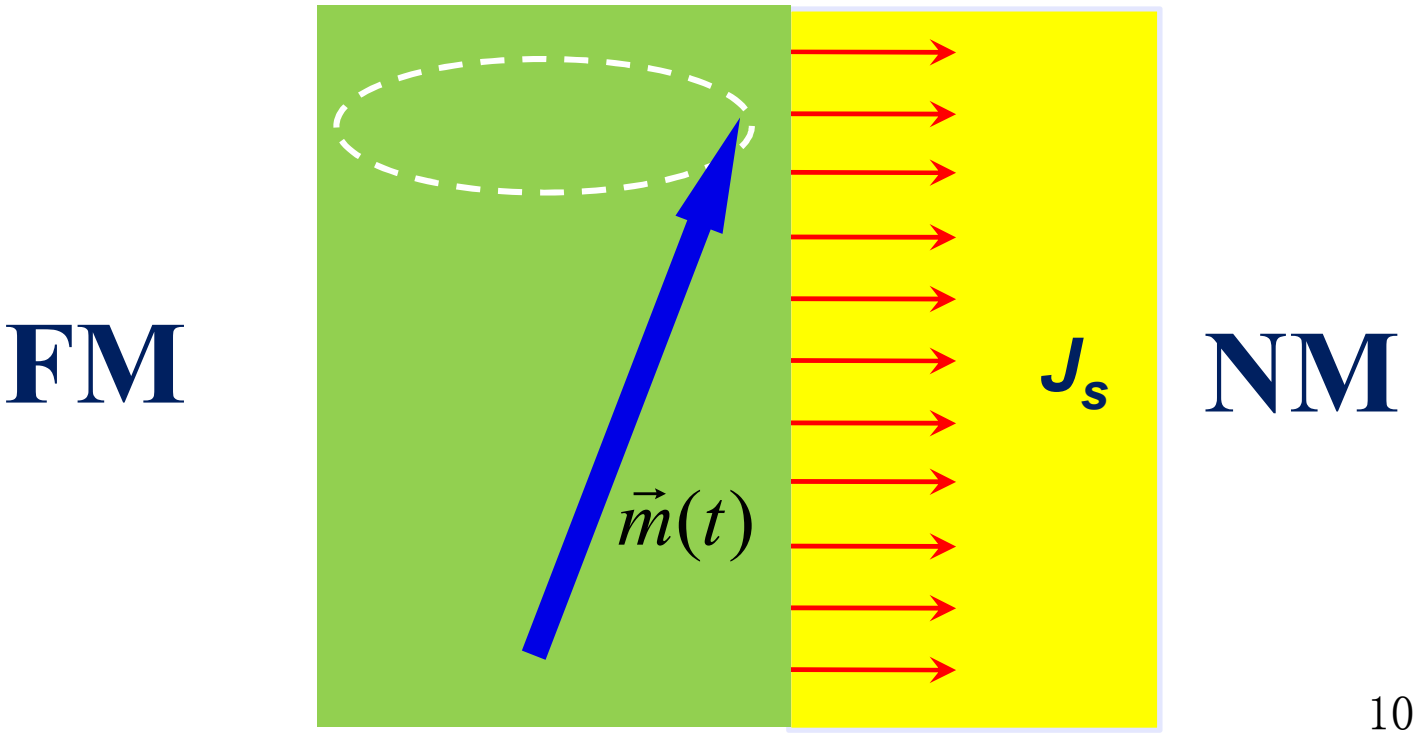
3. Spin injection

❑ Optical



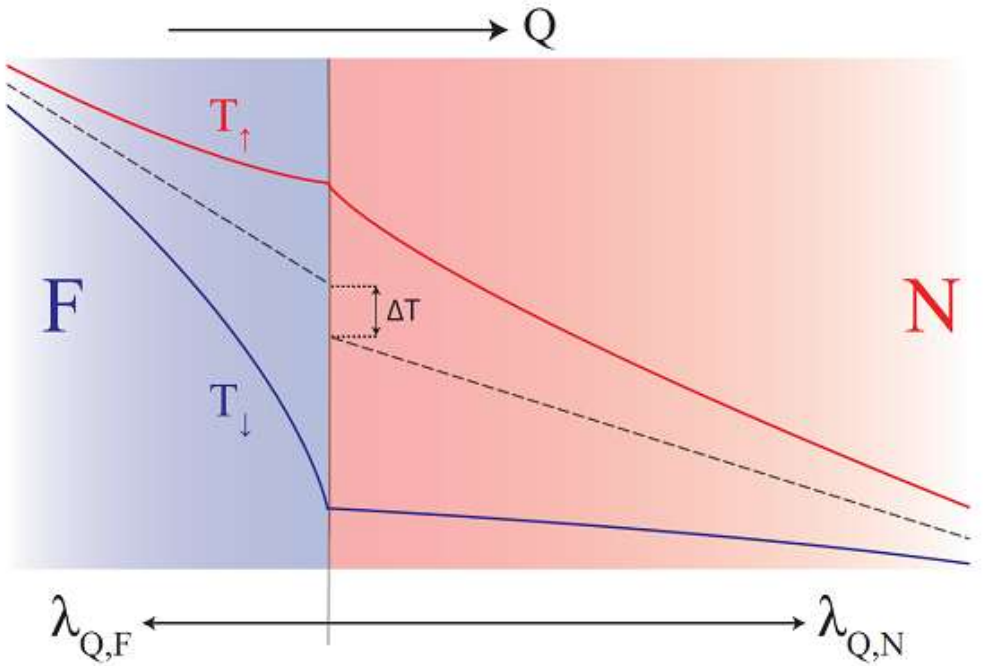
3. Spin injection

- **Dynamical**



3. Spin injection

- **Thermal**



下一节课: Nov. 2nd

Chapter 4: Spin Valves

2. Spin valves based on Metal and Superconductor

课件下载：
http://www.phy.pku.edu.cn/~LabSpin/teaching.html